

TEST REPORT

FCC LTE B25 Test for SM-S931B/DS
Certification

APPLICANT
SAMSUNG Electronics Co., Ltd.

REPORT NO.
HCT-RF-2410-FC055

DATE OF ISSUE
October 29, 2024

Tested by
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TEST REPORT

REPORT NO.

HCT-RF-2410-FC055

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Additional Model

SM-S931B

Applicant**SAMSUNG Electronics Co., Ltd.**

129, Samsung-ro, Yeongtong-gu, Suwon-si, Gyeonggi-do, 16677, Rep. of
Korea

Product Name

Mobile Phone

Model Name

SM-S931B/DS

Date of Test

August 21, 2024 ~ October 28, 2024

FCC ID

A3LSMS931B

Location of Test☒ Permanent Testing Lab ☐ On Site Testing

(Address: 74, Seoicheon-ro 578beon-gil, Majang-myeon, Icheon-si, Gyeonggi-do,
17383 Republic of Korea)

FCC Classification:

PCS Licensed Transmitter Held to Ear (PCE)

Test Standard Used

FCC Rule Part : § 24

Test Results

PASS

REVISION HISTORY

The revision history for this test report is shown in table.

Revision No.	Date of Issue	Description
0	October 29, 2024	Initial Release

Notice

Content

The measurements shown in this report were made in accordance with the procedures specified in CFR47 section § 2.947. I assume full responsibility for the accuracy and completeness of these measurements, and for the qualifications of all persons taking them.

HCT CO., LTD. Certifies that no party to this application has subject to a denial of Federal benefits that includes FCC benefits pursuant to section 5301 of the Anti-Drug Abuse Act of 1998, 21 U.S.C. 853(a)

The results shown in this test report only apply to the sample(s), as received, provided by the applicant, unless otherwise stated.

The test results have only been applied with the test methods required by the standard(s).

The laboratory is not accredited for the test results marked *.

Information provided by the applicant is marked **.

Test results provided by external providers are marked ***.

When confirmation of authenticity of this test report is required, please contact www.hct.co.kr

The test results in this test report are not associated with the ((KS Q) ISO/IEC 17025) accreditation by KOLAS (Korea Laboratory Accreditation Scheme) / A2LA (American Association for Laboratory Accreditation) that are under the ILAC (International Laboratory Accreditation Cooperation) Mutual Recognition Agreement (MRA).

CONTENTS

1. GENERAL INFORMATION	5
1.1. MAXIMUM OUTPUT POWER.....	6
2. INTRODUCTION	8
2.1. DESCRIPTION OF EUT	8
2.2. MEASURING INSTRUMENT CALIBRATION.....	8
2.3. TEST FACILITY	8
3. DESCRIPTION OF TESTS.....	9
3.1 TEST PROCEDURE.....	9
3.2 RADIATED POWER	10
3.3 RADIATED SPURIOUS EMISSIONS	11
3.4 PEAK- TO- AVERAGE RATIO.....	12
3.5 OCCUPIED BANDWIDTH.	14
3.6 SPURIOUS AND HARMONIC EMISSIONS AT ANTENNA TERMINAL	15
3.7 BAND EDGE	16
3.8 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE.....	18
3.9 WORST CASE(RADIATED TEST).....	19
3.10 WORST CASE(CONDUCTED TEST)	20
4. LIST OF TEST EQUIPMENT	21
5. MEASUREMENT UNCERTAINTY	22
6. SUMMARY OF TEST RESULTS.....	23
7. SAMPLE CALCULATION	24
8. TEST DATA(Main1).....	26
8.1 EQUIVALENT ISOTROPIC RADIATED POWER	26
8.2 RADIATED SPURIOUS EMISSIONS	29
8.3 PEAK-TO-AVERAGE RATIO.....	30
8.4 OCCUPIED BANDWIDTH	31
8.5 CONDUCTED SPURIOUS EMISSIONS.....	32
8.6 BAND EDGE	32
8.7 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE.....	33
9. TEST DATA(Sub1)	51
9.1 EQUIVALENT ISOTROPIC RADIATED POWER	51
9.2 RADIATED SPURIOUS EMISSIONS	54
9.3 PEAK-TO-AVERAGE RATIO.....	55
9.4 OCCUPIED BANDWIDTH	56
9.5 CONDUCTED SPURIOUS EMISSIONS.....	57
9.6 BAND EDGE	57
9.7 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE.....	58
10. TEST PLOTS(Main1)	76
11. TEST PLOTS(Sub1)	197
12. ANNEX A_ TEST SETUP PHOTO	318

MEASUREMENT REPORT

1. GENERAL INFORMATION

Applicant Name:	SAMSUNG Electronics Co., Ltd.
Address:	129, Samsung-ro, Yeongtong-gu, Suwon-si, Gyeonggi-do, 16677, Rep. of Korea
FCC ID:	A3LSMS931B
Application Type:	Certification
FCC Classification:	PCS Licensed Transmitter Held to Ear (PCE)
FCC Rule Part(s):	§ 24
EUT Type:	Mobile phone
Model(s):	SM-S931B/DS
Additional Model(s)	SM-S931B
Tx Frequency:	1850.7 MHz – 1914.3 MHz (LTE – Band25 (1.4 MHz)) 1851.5 MHz – 1913.5 MHz (LTE – Band25 (3 MHz)) 1852.5 MHz – 1912.5 MHz (LTE – Band25 (5 MHz)) 1855.0 MHz – 1910.0 MHz (LTE – Band25 (10 MHz)) 1857.5 MHz – 1907.5 MHz (LTE – Band25 (15 MHz)) 1860.0 MHz – 1905.0 MHz (LTE – Band25 (20 MHz))
Date(s) of Tests:	August 21, 2024 ~ October 28, 2024
Serial number:	Radiated : R3CX80V3NKP(Main1), R3CX80V3NKP(Sub1) Conducted : R3CX80PTCEN(Main1), R3CX80PTCEN(Sub1)

1.1. MAXIMUM OUTPUT POWER

Main1

Mode (MHz)	Tx Frequency (MHz)	Emission Designator	Modulation	EIRP	
				Max. Power (W)	Max. Power (dBm)
LTE – Band25 (1.4)	1850.7 - 1914.3	1M10G7D	QPSK	0.259	24.14
		1M10W7D	16QAM	0.220	23.42
		1M10W7D	64QAM	0.169	22.29
		1M10W7D	256QAM	0.085	19.29
LTE – Band25 (3)	1851.5 - 1913.5	2M72G7D	QPSK	0.253	24.03
		2M72W7D	16QAM	0.210	23.23
		2M72W7D	64QAM	0.165	22.17
		2M71W7D	256QAM	0.080	19.03
LTE – Band25 (5)	1852.5 - 1912.5	4M51G7D	QPSK	0.257	24.10
		4M50W7D	16QAM	0.217	23.37
		4M52W7D	64QAM	0.168	22.25
		4M51W7D	256QAM	0.083	19.17
LTE – Band25 (10)	1855.0 - 1910.0	8M99G7D	QPSK	0.259	24.13
		9M00W7D	16QAM	0.214	23.31
		9M01W7D	64QAM	0.169	22.28
		9M02W7D	256QAM	0.084	19.23
LTE – Band25 (15)	1857.5 - 1907.5	13M5G7D	QPSK	0.268	24.28
		13M5W7D	16QAM	0.218	23.39
		13M5W7D	64QAM	0.169	22.27
		13M5W7D	256QAM	0.084	19.22
LTE – Band25 (20)	1860.0 - 1905.0	18M0G7D	QPSK	0.265	24.23
		18M0W7D	16QAM	0.215	23.33
		18M0W7D	64QAM	0.171	22.33
		18M0W7D	256QAM	0.083	19.19

Sub1

Mode (MHz)	Tx Frequency (MHz)	Emission Designator	Modulation	EIRP	
				Max. Power (W)	Max. Power (dBm)
LTE – Band25 (1.4)	1850.7 - 1914.3	1M10G7D	QPSK	0.169	22.27
		1M10W7D	16QAM	0.145	21.61
		1M10W7D	64QAM	0.113	20.53
		1M10W7D	256QAM	0.055	17.43
LTE – Band25 (3)	1851.5 - 1913.5	2M72G7D	QPSK	0.171	22.33
		2M72W7D	16QAM	0.147	21.66
		2M72W7D	64QAM	0.115	20.60
		2M71W7D	256QAM	0.056	17.50
LTE – Band25 (5)	1852.5 - 1912.5	4M51G7D	QPSK	0.177	22.47
		4M51W7D	16QAM	0.150	21.76
		4M52W7D	64QAM	0.115	20.61
		4M51W7D	256QAM	0.056	17.46
LTE – Band25 (10)	1855.0 - 1910.0	9M01G7D	QPSK	0.173	22.37
		9M00W7D	16QAM	0.143	21.56
		9M00W7D	64QAM	0.112	20.49
		8M99W7D	256QAM	0.056	17.45
LTE – Band25 (15)	1857.5 - 1907.5	13M5G7D	QPSK	0.176	22.46
		13M5W7D	16QAM	0.144	21.58
		13M5W7D	64QAM	0.113	20.53
		13M5W7D	256QAM	0.056	17.48
LTE – Band25 (20)	1860.0 - 1905.0	17M9G7D	QPSK	0.175	22.42
		18M0W7D	16QAM	0.143	21.56
		18M0W7D	64QAM	0.113	20.53
		18M0W7D	256QAM	0.055	17.38

2. INTRODUCTION

2.1. DESCRIPTION OF EUT

The EUT was a Mobile Phone with GSM/GPRS/EGPRS/UMTS and LTE, Sub 6.
It also supports IEEE 802.11 a/b/g/n/ac/ax/be (20/40/80/160/320 MHz), Bluetooth(iPA, ePA), BT LE(iPA, ePA), NFC, WPT, WIFI 6E

2.2. MEASURING INSTRUMENT CALIBRATION

The measuring equipment, which was utilized in performing the tests documented herein, has been calibrated in accordance with the manufacturer's recommendations for utilizing calibration equipment, which is traceable to recognized national standards.

2.3. TEST FACILITY

The Fully-anechoic chamber and conducted measurement facility used to collect the radiated data are located at the **74, Seoicheon-ro 578beon-gil, Majang-myeon, Icheon-si, Gyeonggi-do, Republic of Korea**

3. DESCRIPTION OF TESTS

3.1 TEST PROCEDURE

Test Description	Test Procedure Used
Occupied Bandwidth	- KDB 971168 D01 v03r01 – Section 4.3 - ANSI C63.26-2015 – Section 5.4.4
Band Edge	- KDB 971168 D01 v03r01 – Section 6.0 - ANSI C63.26-2015 – Section 5.7
Spurious and Harmonic Emissions at Antenna Terminal	- KDB 971168 D01 v03r01 – Section 6.0 - ANSI C63.26-2015 – Section 5.7
Conducted Output Power	- N/A (See SAR Report)
Peak- to- Average Ratio	- KDB 971168 D01 v03r01 – Section 5.7 - ANSI C63.26-2015 – Section 5.2.3.4
Frequency stability	- ANSI C63.26-2015 – Section 5.6
Effective Radiated Power/ Effective Isotropic Radiated Power	- KDB 971168 D01 v03r01 – Section 5.2 & 5.8 - ANSI/TIA-603-E-2016 – Section 2.2.17
Radiated Spurious and Harmonic Emissions	- KDB 971168 D01 v03r01 – Section 6.2 - ANSI/TIA-603-E-2016 – Section 2.2.12

3.2 RADIATED POWER

Test Overview

Radiated tests are performed in the Fully-anechoic chamber.

The equipment under test is placed on a non-conductive table 3-meters away from the receive antenna in accordance with ANSI/TIA-603-E-2016 Clause 2.2.17.

Test Settings

1. Radiated power measurements are performed using the signal analyzer's "channel power" measurement capability for signals with continuous operation.
2. RBW = 1 – 5 % of the expected OBW, not to exceed 1 MHz
3. VBW $\geq$ 3 x RBW
4. Span = 1.5 times the OBW
5. No. of sweep points $>$ 2 x span / RBW
6. Detector = RMS
7. Trigger is set to "free run" for signals with continuous operation with the sweep times set to "auto".
8. The integration bandwidth was roughly set equal to the measured OBW of the signal for signals with continuous operation.
9. Trace mode = trace averaging (RMS) over 100 sweeps
10. The trace was allowed to stabilize

Test Note

1. The turntable is rotated through 360 degrees, and the receiving antenna scans in order to determine the level of the maximized emission.
2. A half wave dipole is then substituted in place of the EUT. For emissions above 1 GHz, a horn antenna is substituted in place of the EUT. The substitute antenna is driven by a signal generator and the previously recorded signal was duplicated.

The power is calculated by the following formula;

$$P_d \text{ (dBm)} = P_g \text{ (dBm)} - \text{cable loss (dB)} + \text{antenna gain (dB)}$$

Where: P_d is the dipole equivalent power and P_g is the generator output power into the substitution antenna.

3. The maximum value is calculated by adding the forward power to the calibrated source plus its appropriate gain value.
These steps are repeated with the receiving antenna in both vertical and horizontal polarization. the difference between the gain of the horn and an isotropic antenna are taken into consideration
4. The EUT was tested in three orthogonal planes(X, Y, Z) and in all possible test configurations and positioning.
5. All measurements are performed as RMS average measurements while the EUT is operating at its maximum duty cycle, at maximum power, and at the appropriate frequencies.

3.3 RADIATED SPURIOUS EMISSIONS

Test Overview

Radiated tests are performed in the Fully-anechoic chamber.

Radiated Spurious Emission Measurements at 3 meters by Substitution Method according to ANSI/TIA-603-E-2016.

Test Settings

1. RBW = 100 kHz for emissions below 1 GHz and 1 MHz for emissions above 1 GHz
2. VBW $\geq 3 \times$ RBW
3. Span = 1.5 times the OBW
4. No. of sweep points $> 2 \times$ span / RBW
5. Detector = Peak
6. Trace mode = Max Hold
7. The trace was allowed to stabilize
8. Test channel : Low/ Middle/ High
9. Frequency range : We are performed all frequency to 10th harmonics from 9 kHz.

Test Note

1. Measurements value show only up to 3 maximum emissions noted, or would be lesser if no specific emissions from the EUT are recorded (ie: margin > 20 dB from the applicable limit) and considered that's already beyond the background noise floor.
2. The EUT was tested in three orthogonal planes(X, Y, Z) and in all possible test configurations and positioning.
The worst case emissions are reported with the EUT positioning, modulations, RB sizes and offsets, and channel bandwidth configurations shown in the test data
3. For spurious emissions above 1 GHz, a horn antenna is substituted in place of the EUT. The substitute antenna is driven by a signal generator and the previously recorded signal was duplicated.

The spurious emissions is calculated by the following formula;

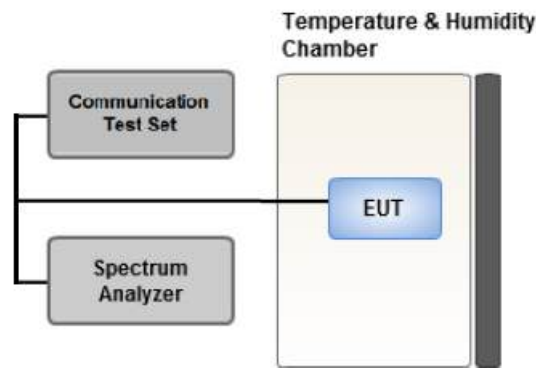
$$\text{Result}_{(\text{dBm})} = P_g_{(\text{dBm})} - \text{cable loss}_{(\text{dB})} + \text{antenna gain}_{(\text{dBi})}$$

Where: P_g is the generator output power into the substitution antenna.

If the fundamental frequency is below 1 GHz, RF output power has been converted to EIRP.

$$\text{EIRP}_{(\text{dBm})} = \text{ERP}_{(\text{dBm})} + 2.15$$

3.4 PEAK- TO- AVERAGE RATIO



Test setup

① CCDF Procedure for PAPR

Test Settings

1. Set resolution/measurement bandwidth $\geq$ signal's occupied bandwidth;
2. Set the number of counts to a value that stabilizes the measured CCDF curve;
3. Set the measurement interval as follows:
 - .- for continuous transmissions, set to 1 ms,
 - .- or burst transmissions, employ an external trigger that is synchronized with the EUT burst timing sequence, or use the internal burst trigger with a trigger level that allows the burst to stabilize and set the measurement interval to a time that is less than or equal to the burst duration.
4. Record the maximum PAPR level associated with a probability of 0.1 %.

② Alternate Procedure for PAPR

Use one of the procedures presented in 5.2(ANSI C63.26-2015) to measure the total peak power and record as P_{Pk} .

Use one of the applicable procedures presented 5.2(ANSI C63.26-2015) to measure the total average power and record as P_{Avg} . Determine the P.A.R. from:

$$P.A.R. (dB) = P_{Pk} (dBm) - P_{Avg} (dBm) \quad (P_{Avg} = \text{Average Power} + \text{Duty cycle Factor})$$

Test Settings(Peak Power)

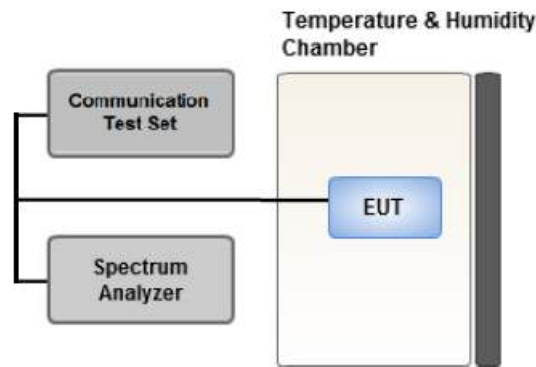
The measurement instrument must have a RBW that is greater than or equal to the OBW of the signal to be measured and a VBW $\geq 3 \times$ RBW.

1. Set the RBW $\geq$ OBW.
2. Set VBW $\geq 3 \times$ RBW.
3. Set span $\geq 2 \times$ OBW.
4. Sweep time $\geq 10 \times$ (number of points in sweep) $\times$ (transmission symbol period).
5. Detector = peak.
6. Trace mode = max hold.
7. Allow trace to fully stabilize.
8. Use the peak marker function to determine the peak amplitude level.

Test Settings(Average Power)

1. Set span to $2 \times$ to $3 \times$ the OBW.
2. Set RBW $\geq$ OBW.
3. Set VBW $\geq 3 \times$ RBW.
4. Set number of measurement points in sweep $\geq 2 \times$ span / RBW.
5. Sweep time:
Set $\geq [10 \times (\text{number of points in sweep}) \times (\text{transmission period})]$ for single sweep (automation-compatible) measurement. The transmission period is the (on + off) time.
6. Detector = power averaging (rms).
7. Set sweep trigger to "free run."
8. Trace average at least 100 traces in power averaging (rms) mode if sweep is set to auto-couple. (To accurately determine the average power over the on and off period of the transmitter, it can be necessary to increase the number of traces to be averaged above 100 or, if using a manually configured sweep time, increase the sweep time.)
9. Use the peak marker function to determine the maximum amplitude level.
10. Add $[10 \log (1/\text{duty cycle})]$ to the measured maximum power level to compute the average power during continuous transmission. For example, add $[10 \log (1/0.25)] = 6 \text{ dB}$ if the duty cycle is a constant 25 %.

3.5 OCCUPIED BANDWIDTH.



Test setup

The width of a frequency band such that, below the lower and above the upper frequency limits, the mean powers emitted are each equal to a specified percentage 0.5 % of the total mean power of a given emission.

The EUT makes a call to the communication simulator.

The conducted occupied bandwidth used the power splitter via EUT RF power connector between simulation base station and spectrum analyzer.

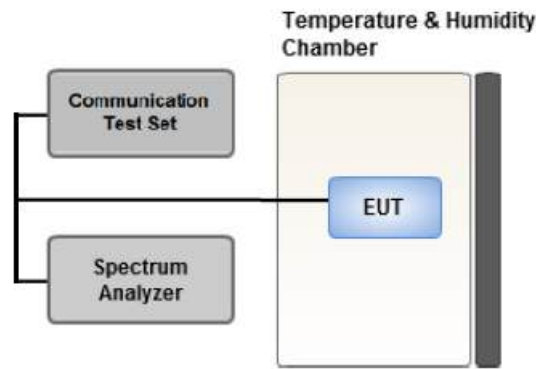
The communication simulator station system controlled a EUT to export maximum output power under transmission mode and specific channel frequency.

Use OBW measurement function of Spectrum analyzer to measure 99 % occupied bandwidth

Test Settings

1. The signal analyzer's automatic bandwidth measurement capability was used to perform the 99 % occupied bandwidth and the 26 dB bandwidth. The bandwidth measurement was not influenced by any intermediate power nulls in the fundamental emission.
2. RBW = 1 – 5 % of the expected OBW
3. VBW $\geq$ 3 x RBW
4. Detector = Peak
5. Trace mode = max hold
6. Sweep = auto couple
7. The trace was allowed to stabilize
8. If necessary, steps 2 – 7 were repeated after changing the RBW such that it would be within 1 – 5 % of the 99 % occupied bandwidth observed in Step 7

3.6 SPURIOUS AND HARMONIC EMISSIONS AT ANTENNA TERMINAL



Test setup

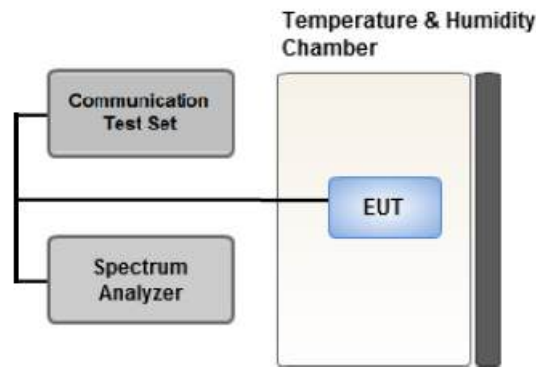
Test Overview

The level of the carrier and the various conducted spurious and harmonic frequencies is measured by means of a calibrated spectrum analyzer. The spectrum is scanned from the lowest frequency generated in the equipment up to a frequency including its 10th harmonic. All out of band emissions are measured with a spectrum analyzer connected to the antenna terminal of the EUT while the EUT is operating at its maximum duty cycle, at maximum power, and at the appropriate frequencies. All data rates were investigated to determine the worst case configuration. All modes of operation were investigated and the worst case configuration results are reported in this section.

Test Settings

1. RBW = 1 MHz
2. VBW $\geq$ 3 MHz
3. Detector = RMS
4. Trace Mode = trace average
5. Sweep time = auto
6. Number of points in sweep $\geq$ 2 x Span / RBW

3.7 BAND EDGE



Test setup

Test Overview

All out of band emissions are measured with a spectrum analyzer connected to the antenna terminal of the EUT while the EUT is operating at its maximum duty cycle, at maximum power, and at the appropriate frequencies. All data rates were investigated to determine the worst case configuration. All modes of operation were investigated and the worst case configuration results are reported in this section.

Test Settings

1. Start and stop frequency were set such that the band edge would be placed in the center of the plot
2. Span was set large enough so as to capture all out of band emissions near the band edge
3. RBW > 1 % of the emission bandwidth
4. VBW > 3 x RBW
5. Detector = RMS
6. Number of sweep points $\geq 2 \times \text{Span}/\text{RBW}$
7. Trace mode = trace average
8. Sweep time = auto couple
9. The trace was allowed to stabilize

Test Notes

According to FCC 22.917, 24.238, 27.53 specified that power of any emission outside of The authorized operating frequency ranges must be attenuated below the transmitting power (P) by a factor of at least $43 + 10 \log(P)$ dB. In

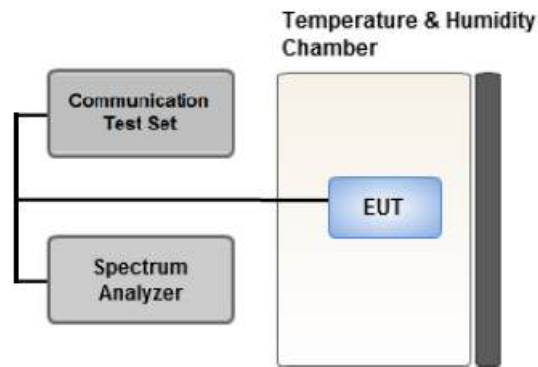
the 1 MHz bands immediately outside and adjacent to the frequency block a resolution bandwidth of at least one percent of the emission bandwidth of the fundamental emission of the transmitter may be employed.

All measurements were done at 2 channels(low and high operational frequency range.)

The band edge measurement used the power splitter via EUT RF power connector between simulation base station and spectrum analyzer.

Where Margin < 1 dB the emission level is either corrected by $10 \log(1 \text{ MHz} / \text{RB})$ or the emission is integrated over a 1 MHz bandwidth to determine the final result. When using the integration method the integration window is either centered on the emission or, for emissions at the band edge, centered by an offset of 500 kHz from the block edge so that the integration window is the 1 MHz adjacent to the block edge.

3.8 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE



Test setup

Test Overview

Frequency stability testing is performed in accordance with the guidelines of ANSI C63.26-2015.

The frequency stability of the transmitter is measured by:

1. Temperature:

The temperature is varied from -30 °C to +50 °C in 10 °C increments using an environmental chamber.

2. Primary Supply Voltage:

- Unless otherwise specified, vary primary supply voltage from 85 % to 115 % of the nominal value for other than hand carried battery equipment.
- For hand carried, battery powered equipment, reduce the primary ac or dc supply voltage to the battery operating end point, which shall be specified by the manufacturer.

Test Settings

1. The carrier frequency of the transmitter is measured at room temperature (20 °C to provide a reference).
2. The equipment is turned on in a “standby” condition for fifteen minutes before applying power to the transmitter.
Measurement of the carrier frequency of the transmitter is made within one minute after applying power to the transmitter.
3. Frequency measurements are made at 10 °C intervals ranging from -30 °C to +50 °C. A period of at least one half-hour is provided to allow stabilization of the equipment at each temperature level.

3.9 WORST CASE(RADIATED TEST)

- The EUT was tested in three orthogonal planes(X, Y, Z) and in all possible test configurations and positioning.
- In the case of radiated spurious emissions, all bandwidth of operation were investigated and the worst case bandwidth results are reported. (Worst case : 15 MHz(Main1), 5MHz(Sub2))
- The worst case is reported with the EUT positioning, modulations, and paging service configurations shown in the test data.
- Please refer to the table below.
- All modes of operation were investigated and the worst case configuration results are reported.
Mode : Stand alone, Stand alone + External accessories (Earphone, AC adapter, etc)
Worst case : Stand alone
- All simultaneous transmission scenarios of operation were investigated, and the test results showed no additional significant emissions relative to the least restrictive limit were observed.
Therefore, only the worst case(stand-alone) results were reported.
- SM-S931B/DS & additional models were tested and the worst case results are reported.
(Worst case : SM-S931B/DS)

[Main1 Worst case]

Test Description	Modulation	RB size	RB offset	Axis
Effective Isotropic Radiated Power	QPSK, 16QAM, 64QAM, 256QAM	See Section 8.1		Z
Radiated Spurious and Harmonic Emissions	QPSK	See Section 8.2		Y

[Sub1 Worst case]

Test Description	Modulation	RB size	RB offset	Axis
Effective Isotropic Radiated Power	QPSK, 16QAM, 64QAM, 256QAM	See Section 9.1		Z
Radiated Spurious and Harmonic Emissions	QPSK	See Section 9.2		Z

3.10 WORST CASE(CONDUCTED TEST)

- All modes of operation were investigated and the worst case configuration results are reported.
 - SM-S931B/DS & additional models were tested and the worst case results are reported.
- (Worst case : SM-S931B/DS)

[Worst case]

Test Description	Modulation	Bandwidth (MHz)	Frequency	RB size	RB offset
Occupied Bandwidth	QPSK, 16QAM, 64QAM, 256QAM	1.4, 3, 5, 10, 15, 20	Mid	Full RB	0
Peak-To-Average Ratio	QPSK, 16QAM, 64QAM, 256QAM	1.4, 3, 5, 10, 15, 20	Mid	Full RB	0
Band Edge	QPSK	1.4	Low	1	0
			High	1	5
		3	Low	1	0
			High	1	14
		5	Low	1	0
			High	1	24
		10	Low	1	0
			High	1	49
		15	Low	1	0
			High	1	74
		20	Low	1	0
			High	1	99
		1.4, 3, 5, 10, 15, 20	Low, High	Full RB	0
Spurious and Harmonic Emissions at Antenna Terminal	QPSK	1.4, 3, 5, 10, 15, 20	Low, Mid, High	1	0

4. LIST OF TEST EQUIPMENT

Equipment	Model	Manufacture	Serial No.	Due to Calibration	Calibration Interval
RF Switching System	Switch box(1.2 G HPF+LNA)	HCT CO., LTD.,	F1L1	08/21/2025	Annual
RF Switching System	Switch box(3.3 G HPF+LNA)	HCT CO., LTD.,	F1L2	08/21/2025	Annual
RF Switching System	Switch box(LNA)	HCT CO., LTD.,	F1L4	08/21/2025	Annual
RF Switching System	Switch box(6 G HPF+LNA)	HCT CO., LTD.,	F1L7	08/21/2025	Annual
Power Splitter(DC ~ 26.5 GHz)	11667B	Hewlett Packard	5001	04/17/2025	Annual
DC Power Supply	E3632A	Agilent	MY40010147	08/06/2025	Annual
Dipole Antenna	UHAP	Schwarzbeck	01274	03/10/2026	Biennial
Dipole Antenna	UHAP	Schwarzbeck	01288	08/07/2026	Biennial
Chamber	SU-642	ESPEC	93008124	02/19/2025	Annual
Horn Antenna(1 ~ 18 GHz)	BBHA 9120D	Schwarzbeck	147	08/17/2025	Biennial
Horn Antenna(1 ~ 18 GHz)	BBHA 9120D	Schwarzbeck	9120D-1298	09/11/2025	Biennial
Horn Antenna(15 ~ 40 GHz)	BBHA 9170	Schwarzbeck	BBHA9170342	09/20/2026	Biennial
Horn Antenna(15 ~ 40 GHz)	BBHA 9170	Schwarzbeck	BBHA9170124	03/28/2025	Biennial
Signal Analyzer(10 Hz ~ 26.5 GHz)	N9020A	Agilent	MY52090906	04/19/2025	Annual
ATTENUATOR(20 dB)	8493C	Hewlett Packard	17280	04/17/2025	Annual
Spectrum Analyzer(10 Hz ~ 40 GHz)	FSV40	REOHDE & SCHWARZ	100931	08/06/2025	Annual
Base Station	8960 (E5515C)	Agilent	MY48360800	08/05/2025	Annual
Loop Antenna(9 kHz ~ 30 MHz)	FMZB1513	Schwarzbeck	1513-333	03/07/2026	Biennial
Trilog Broadband Antenna	VULB9168	Schwarzbeck	895	08/28/2026	Biennial
Trilog Broadband Antenna	VULB9168	Schwarzbeck	1135	08/19/2026	Biennial
Wideband Radio Communication Tester	MT8821C	Anritsu Corp.	6262094331	11/17/2024	Annual
Wideband Radio Communication Tester	MT8820C	Anritsu Corp.	6201026545	12/11/2024	Annual
SIGNAL GENERATOR (100 kHz ~ 40 GHz)	SMB100A	REOHDE & SCHWARZ	177633	07/26/2025	Annual
Signal Analyzer(5 Hz ~ 40.0 GHz)	N9030B	KEYSIGHT	MY55480167	05/17/2025	Annual
FCC LTE Mobile Conducted RF Automation Test Software	-	HCT CO., LTD.,	-	-	-

Note:

- Equipment listed above that has a calibration due date during the testing period, the testing is completed before equipment expiration date.
- Especially, all antenna for measurement is calibrated in accordance with the requirements of C63.5 (Version : 2017).

5. MEASUREMENT UNCERTAINTY

The measurement uncertainties shown below were calculated in accordance with the requirements of ANSI C63.4:2014.

All measurement uncertainty values are shown with a coverage factor of $k=2$ to indicate a 95 % level of confidence. The measurement data shown herein meets or exceeds the U_{CISPR} measurement uncertainty values specified in CISPR 16-4-2 and, thus, can be compared directly to specified limits to determine compliance.

Parameter	Expanded Uncertainty ($\pm$ dB)
Conducted Disturbance (150 kHz ~ 30 MHz)	1.98 (Confidence level about 95 %, $k=2$)
Radiated Disturbance (9 kHz ~ 30 MHz)	4.36 (Confidence level about 95 %, $k=2$)
Radiated Disturbance (30 MHz ~ 1 GHz)	5.70 (Confidence level about 95 %, $k=2$)
Radiated Disturbance (1 GHz ~ 18 GHz)	5.52 (Confidence level about 95 %, $k=2$)
Radiated Disturbance (18 GHz ~ 40 GHz)	5.66 (Confidence level about 95 %, $k=2$)
Radiated Disturbance (Above 40 GHz)	5.58 (Confidence level about 95 %, $k=2$)

6. SUMMARY OF TEST RESULTS

6.1 Test Condition: Conducted Test

Test Description	FCC Part Section(s)	Test Limit	Test Result
Occupied Bandwidth	§ 2.1049	N/A	PASS
Band Edge / Spurious and Harmonic Emissions at Antenna Terminal.	§ 2.1051, § 24.238(a)	$< 43 + 10\log_{10}(P[\text{Watts}])$ at Band Edge and for all out-of-band emissions	PASS
Conducted Output Power	§ 2.1046	N/A	<u>See Note1</u>
Peak- to- Average Ratio	§ 24.232(d)	< 13 dB	PASS
Frequency stability / variation of ambient temperature	§ 24.235	Emission must remain in band	PASS

Note:

1. See SAR Report

6.2 Test Condition: Radiated Test

Test Description	FCC Part Section(s)	Test Limit	Test Result
Equivalent Isotropic Radiated Power	§ 24.232(c)	< 2 Watts max. EIRP	PASS
Radiated Spurious and Harmonic Emissions	§ 2.1053, § 24.238(a)	$< 43 + 10\log_{10}(P[\text{Watts}])$ for all out-of band emissions	PASS

7. SAMPLE CALCULATION

7.1 ERP Sample Calculation

Ch./ Freq.		Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain (dBd)	C.L	Pol.	ERP	
channel	Freq.(MHz)						W	dBm
128	824.20	-21.37	38.40	-10.61	0.95	H	0.483	26.84

$$\text{ERP} = \text{Substitute LEVEL(dBm)} + \text{Ant. Gain} - \text{CL(Cable Loss)}$$

- 1) The EUT mounted on a non-conductive turntable is 2.5 meter above test site ground level.
- 2) During the test, the turn table is rotated until the maximum signal is found.
- 3) Record the field strength meter's level.
- 4) Replace the EUT with dipole/Horn antenna that is connected to a calibrated signal generator.
- 5) Increase the signal generator output till the field strength meter's level is equal to the item (3).
- 6) The signal generator output level with Ant. Gain and cable loss are the rating of effective radiated power.

7.2 EIRP Sample Calculation

Ch./ Freq.		Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain (dBi)	C.L	Pol.	EIRP	
channel	Freq.(MHz)						W	dBm
20175	1,732.50	-15.75	18.45	9.90	1.76	H	0.456	26.59

$$\text{EIRP} = \text{Substitute LEVEL(dBm)} + \text{Ant. Gain} - \text{CL(Cable Loss)}$$

- 1) The EUT mounted on a non-conductive turntable is 2.5 meter above test site ground level.
- 2) During the test, the turn table is rotated until the maximum signal is found.
- 3) Record the field strength meter's level.
- 4) Replace the EUT with dipole/Horn antenna that is connected to a calibrated signal generator.
- 5) Increase the signal generator output till the field strength meter's level is equal to the item (3).
- 6) The signal generator output level with Ant. Gain and cable loss are the rating of equivalent isotropic radiated power.

7.3. Emission Designator

GSM Emission Designator

Emission Designator = 249KGXW

GSM BW = 249 kHz

G = Phase Modulation

X = Cases not otherwise covered

W = Combination (Audio/Data)

EDGE Emission Designator

Emission Designator = 249KG7W

GSM BW = 249 kHz

G = Phase Modulation

7 = Quantized/Digital Info

W = Combination (Audio/Data)

WCDMA Emission Designator

Emission Designator = 4M17F9W

WCDMA BW = 4.17 MHz

F = Frequency Modulation

9 = Composite Digital Info

W = Combination (Audio/Data)

QPSK Modulation

Emission Designator = 4M48G7D

LTE BW = 4.48 MHz

G = Phase Modulation

7 = Quantized/Digital Info

D = Data transmission; telemetry; telecommand

QAM Modulation

Emission Designator = 4M48W7D

LTE BW = 4.48 MHz

W = Amplitude/Angle Modulated

7 = Quantized/Digital Info

D = Data transmission; telemetry; telecommand

8. TEST DATA(Main1)

8.1 EQUIVALENT ISOTROPIC RADIATED POWER

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
								W	W	dBm	Size	Offset
1850.7	LTE B25 1.4 MHz	QPSK	-18.71	15.81	10.40	2.07	V	< 2.00	0.259	24.14	1	0
		16-QAM	-19.43	15.09	10.40	2.07	V		0.220	23.42		
		64-QAM	-20.56	13.96	10.40	2.07	V		0.169	22.29		
		256-QAM	-23.56	10.96	10.40	2.07	V		0.085	19.29		
1882.5		QPSK	-20.34	14.64	10.40	2.21	V		0.192	22.83	1	0
		16-QAM	-21.04	13.94	10.40	2.21	V		0.163	22.13		
		64-QAM	-22.02	12.96	10.40	2.21	V		0.130	21.15		
		256-QAM	-25.15	9.83	10.40	2.21	V		0.063	18.02		
1914.3		QPSK	-21.66	13.35	10.40	2.17	V		0.144	21.58	1	0
		16-QAM	-22.33	12.68	10.40	2.17	V		0.123	20.91		
		64-QAM	-23.37	11.64	10.40	2.17	V		0.097	19.87		
		256-QAM	-26.49	8.52	10.40	2.17	V		0.047	16.75		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
								W	W	dBm	Size	Offset
1851.5	LTE B25 3 MHz	QPSK	-18.82	15.70	10.40	2.07	V	< 2.00	0.253	24.03	1	0
		16-QAM	-19.62	14.90	10.40	2.07	V		0.210	23.23		
		64-QAM	-20.68	13.84	10.40	2.07	V		0.165	22.17		
		256-QAM	-23.82	10.70	10.40	2.07	V		0.080	19.03		
1882.5		QPSK	-20.27	14.71	10.40	2.21	V		0.195	22.90	1	0
		16-QAM	-21.02	13.96	10.40	2.21	V		0.164	22.15		
		64-QAM	-22.07	12.91	10.40	2.21	V		0.129	21.10		
		256-QAM	-25.18	9.80	10.40	2.21	V		0.063	17.99		
1913.5		QPSK	-21.40	13.61	10.40	2.17	V		0.153	21.84	1	0
		16-QAM	-22.15	12.86	10.40	2.17	V		0.129	21.09		
		64-QAM	-23.26	11.75	10.40	2.17	V		0.100	19.98		
		256-QAM	-26.47	8.54	10.40	2.17	V		0.048	16.77		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
								W	W	dBm	Size	Offset
1852.5	LTE B25 5 MHz	QPSK	-18.79	15.78	10.40	2.08	V	<2.00	0.257	24.10	1	0
		16-QAM	-19.52	15.05	10.40	2.08	V		0.217	23.37		
		64-QAM	-20.64	13.93	10.40	2.08	V		0.168	22.25		
		256-QAM	-23.72	10.85	10.40	2.08	V		0.083	19.17		
1882.5		QPSK	-19.97	15.01	10.40	2.21	V		0.209	23.20	1	0
		16-QAM	-20.72	14.26	10.40	2.21	V		0.176	22.45		
		64-QAM	-21.83	13.15	10.40	2.21	V		0.136	21.34		
		256-QAM	-24.98	10.00	10.40	2.21	V		0.066	18.19		
1912.5		QPSK	-21.03	13.98	10.40	2.17	V		0.166	22.21	1	0
		16-QAM	-21.81	13.20	10.40	2.17	V		0.139	21.43		
		64-QAM	-22.86	12.15	10.40	2.17	V		0.109	20.38		
		256-QAM	-26.14	8.87	10.40	2.17	V		0.051	17.10		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
								W	W	dBm	Size	Offset
1855.0	LTE B25 10 MHz	QPSK	-18.76	15.81	10.40	2.08	V	< 2.00	0.259	24.13	1	0
		16-QAM	-19.58	14.99	10.40	2.08	V		0.214	23.31		
		64-QAM	-20.61	13.96	10.40	2.08	V		0.169	22.28		
		256-QAM	-23.66	10.91	10.40	2.08	V		0.084	19.23		
1882.5		QPSK	-20.06	14.92	10.40	2.21	V		0.205	23.11	1	0
		16-QAM	-20.94	14.04	10.40	2.21	V		0.167	22.23		
		64-QAM	-21.95	13.03	10.40	2.21	V		0.132	21.22		
		256-QAM	-25.02	9.96	10.40	2.21	V		0.065	18.15		
1910.0		QPSK	-20.99	13.95	10.40	2.17	V		0.165	22.18	1	0
		16-QAM	-21.80	13.14	10.40	2.17	V		0.137	21.37		
		64-QAM	-22.88	12.06	10.40	2.17	V		0.107	20.29		
		256-QAM	-26.01	8.93	10.40	2.17	V		0.052	17.16		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
								W	W	dBm	Size	Offset
1857.5	LTE B25 15 MHz	QPSK	-18.66	15.98	10.40	2.10	V	< 2.00	0.268	24.28	1	0
		16-QAM	-19.55	15.09	10.40	2.10	V		0.218	23.39		
		64-QAM	-20.67	13.97	10.40	2.10	V		0.169	22.27		
		256-QAM	-23.72	10.92	10.40	2.10	V		0.084	19.22		
1882.5		QPSK	-19.82	15.16	10.40	2.21	V		0.216	23.35	1	0
		16-QAM	-20.74	14.24	10.40	2.21	V		0.175	22.43		
		64-QAM	-21.77	13.21	10.40	2.21	V		0.138	21.40		
		256-QAM	-24.88	10.10	10.40	2.21	V		0.067	18.29		
1907.5		QPSK	-20.72	14.22	10.40	2.17	V		0.176	22.45	1	0
		16-QAM	-21.59	13.35	10.40	2.17	V		0.144	21.58		
		64-QAM	-22.62	12.32	10.40	2.17	V		0.114	20.55		
		256-QAM	-25.73	9.21	10.40	2.17	V		0.055	17.44		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
								W	W	dBm	Size	Offset
1860.0	LTE B25 20 MHz	QPSK	-18.71	15.93	10.40	2.10	V	< 2.00	0.265	24.23	1	0
		16-QAM	-19.61	15.03	10.40	2.10	V		0.215	23.33		
		64-QAM	-20.61	14.03	10.40	2.10	V		0.171	22.33		
		256-QAM	-23.75	10.89	10.40	2.10	V		0.083	19.19		
1882.5		QPSK	-19.61	15.37	10.40	2.21	V		0.227	23.56	1	0
		16-QAM	-20.48	14.50	10.40	2.21	V		0.186	22.69		
		64-QAM	-21.50	13.48	10.40	2.21	V		0.147	21.67		
		256-QAM	-24.60	10.38	10.40	2.21	V		0.072	18.57		
1905.0		QPSK	-20.51	14.41	10.40	2.19	V		0.183	22.62	1	0
		16-QAM	-21.41	13.51	10.40	2.19	V		0.149	21.72		
		64-QAM	-22.46	12.46	10.40	2.19	V		0.117	20.67		
		256-QAM	-25.61	9.31	10.40	2.19	V		0.056	17.52		

8.2 RADIATED SPURIOUS EMISSIONS

▣ OPERATING FREQUENCY:	<u>1857.5 MHz</u>
▣ MEASURED OUTPUT POWER:	<u>24.28 dBm = 0.268 W</u>
▣ MOD:	<u>LTE B25</u>
▣ MODULATION SIGNAL:	<u>15 MHz QPSK</u>
▣ DISTANCE:	<u>3 meters</u>
▣ LIMIT: $43 + 10 \log_{10}(W) =$	<u>-13 dBm</u>

Ch	Freq (MHz)	Measured Level (dBm)	Ant. Gain (dBi)	Substitute Level (dBm)	C.L	Pol	Result (dBm)	RB	
								Size	Offset
26115 (1857.5)	3 715.00	-48.23	12.30	-60.63	3.11	H	-51.44	1	0
	5 572.50	-52.79	13.50	-58.35	3.89	H	-48.74		
	7 430.00	-51.76	10.80	-47.60	4.56	H	-41.36		
26365 (1882.5)	3 765.00	-49.87	12.33	-62.31	3.11	H	-53.09	1	0
	5 647.50	-51.77	13.10	-57.26	3.96	H	-48.12		
	7 530.00	-51.80	10.86	-47.69	4.60	H	-41.43		
26615 (1907.5)	3 815.00	-49.02	12.40	-60.72	3.20	H	-51.52	1	0
	5 722.50	-52.61	13.05	-57.69	4.00	H	-48.64		
	7 630.00	-51.14	11.22	-47.48	4.66	H	-40.92		

8.3 PEAK-TO-AVERAGE RATIO

Band	Band Width	Frequency (MHz)	Modulation	Resource Block Size	Resource Block Offset	Data (dB)
25	1.4 MHz	1882.5	QPSK	6	0	4.76
			16-QAM	6	0	5.94
			64-QAM	6	0	6.50
			256-QAM	6	0	6.81
	3 MHz		QPSK	15	0	4.71
			16-QAM	15	0	5.99
			64-QAM	15	0	6.50
			256-QAM	15	0	6.80
	5 MHz		QPSK	25	0	4.80
			16-QAM	25	0	5.80
			64-QAM	25	0	6.48
			256-QAM	25	0	6.76
	10 MHz		QPSK	50	0	4.81
			16-QAM	50	0	5.82
			64-QAM	50	0	6.42
			256-QAM	50	0	6.75
	15 MHz		QPSK	75	0	4.79
			16-QAM	75	0	5.91
			64-QAM	75	0	6.48
			256-QAM	75	0	6.74
	20 MHz		QPSK	100	0	4.79
			16-QAM	100	0	5.80
			64-QAM	100	0	6.43
			256-QAM	100	0	6.73

Note:

1. Plots of the EUT's Peak- to- Average Ratio are shown Page 77 ~ 100.

8.4 OCCUPIED BANDWIDTH

Band	Band Width	Frequency (MHz)	Modulation	Resource Block Size	Resource Block Offset	Data (MHz)
25	1.4 MHz	1882.5	QPSK	6	0	1.1036
			16-QAM	6	0	1.0986
			64-QAM	6	0	1.0956
			256-QAM	6	0	1.0979
	3 MHz		QPSK	15	0	2.7196
			16-QAM	15	0	2.7179
			64-QAM	15	0	2.7236
			256-QAM	15	0	2.7100
	5 MHz		QPSK	25	0	4.5094
			16-QAM	25	0	4.5030
			64-QAM	25	0	4.5233
			256-QAM	25	0	4.5113
	10 MHz		QPSK	50	0	8.9930
			16-QAM	50	0	9.0026
			64-QAM	50	0	9.0143
			256-QAM	50	0	9.0188
	15 MHz		QPSK	75	0	13.463
			16-QAM	75	0	13.491
			64-QAM	75	0	13.473
			256-QAM	75	0	13.491
	20 MHz		QPSK	100	0	17.949
			16-QAM	100	0	17.972
			64-QAM	100	0	17.962
			256-QAM	100	0	17.951

Note:

1. Plots of the EUT's Occupied Bandwidth are shown Page 101 ~ 124.

8.5 CONDUCTED SPURIOUS EMISSIONS

Band	Band Width (MHz)	Frequency (MHz)	Frequency of Maximum Harmonic (GHz)	Factor (dB)	Measurement Maximum Data (dBm)	Result (dBm)	Limit (dBm)
25	1.4	1850.7	3.7010	27.976	-77.494	-49.518	-13.00
		1882.5	3.7129	27.976	-77.346	-49.370	
		1914.3	3.7114	27.976	-76.779	-48.803	
	3	1851.5	3.7144	27.976	-77.155	-49.179	
		1882.5	3.1755	27.976	-77.198	-49.222	
		1913.5	3.7005	27.976	-77.092	-49.116	
	5	1852.5	3.1586	27.976	-77.258	-49.282	
		1882.5	3.6775	27.976	-77.178	-49.202	
		1912.5	3.1755	27.976	-77.115	-49.139	
	10	1855.0	3.7034	27.976	-77.354	-49.378	
		1882.5	3.7144	27.976	-77.011	-49.035	
		1910.0	3.6950	27.976	-77.162	-49.186	
	15	1857.5	3.7114	27.976	-77.128	-49.152	
		1882.5	3.7114	27.976	-77.122	-49.146	
		1907.5	3.2005	27.976	-77.235	-49.259	
	20	1860.0	3.6745	27.976	-77.210	-49.234	
		1882.5	3.7010	27.976	-77.211	-49.235	
		1905.0	3.7094	27.976	-77.189	-49.213	

Note:

1. Plots of the EUT's Conducted Spurious Emissions are shown Page 125 ~ 160.
2. Conducted Spurious Emissions was Tested QPSK Modulation, Resource Block Size 1 and Resource Block Offset 0
3. Result (dBm) = Measurement Maximum Data (dBm) + Factor (dB)
4. Factor(dB) = Cable Loss + Ext. Attenuator + Power Splitter

Frequency Range (GHz)	Factor [dB]
0.03 – 1	25.270
1 – 5	27.976
5 – 10	28.591
10 – 15	29.116
15 – 20	29.489
Above 20(26.5)	30.131

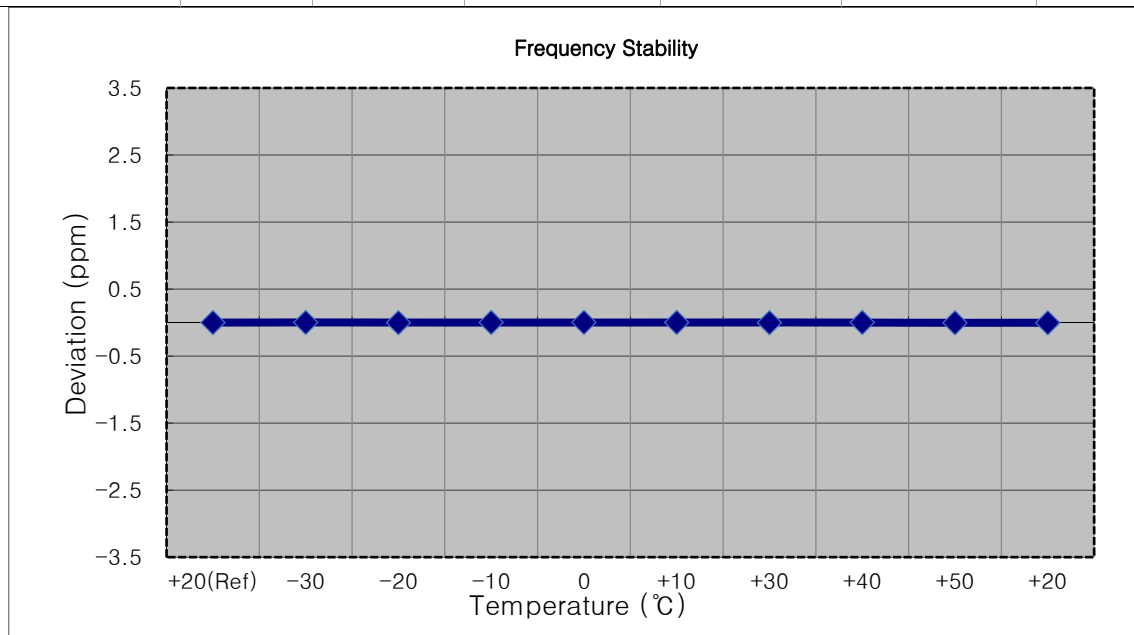
8.6 BAND EDGE

- Plots of the EUT's Band Edge are shown Page 161 ~ 196.

8.7 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE

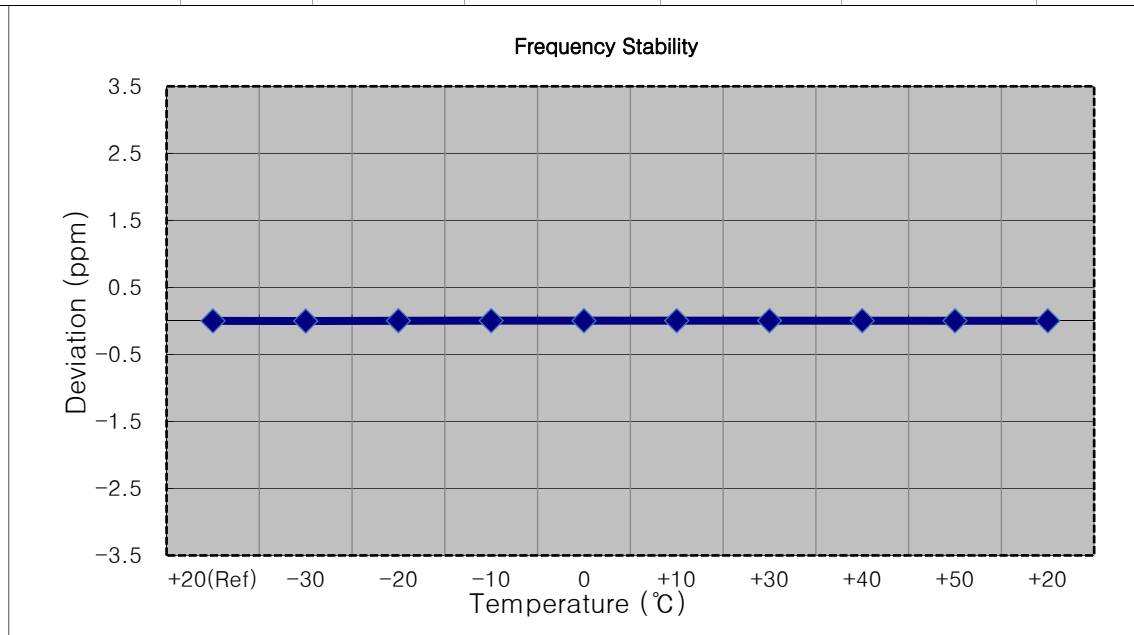
MODE:	<u>LTE B25</u>
OPERATING FREQUENCY:	<u>1850,700,000 Hz</u>
CHANNEL:	<u>26047 (1.4 MHz)</u>
REFERENCE VOLTAGE:	<u>3.880 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1850 700 003	0.0	0.000 000	0.000
100 %		-30	1850 700 006	3.6	0.000 000	0.002
100 %		-20	1850 700 000	-3.1	0.000 000	-0.002
100 %		-10	1850 700 006	3.5	0.000 000	0.002
100 %		0	1850 700 007	3.9	0.000 000	0.002
100 %		+10	1850 700 005	2.6	0.000 000	0.001
100 %		+30	1850 700 000	-2.7	0.000 000	-0.001
100 %		+40	1850 700 005	2.4	0.000 000	0.001
100 %		+50	1850 699 996	-6.4	0.000 000	-0.003
Batt. Endpoint	3.300	+20	1850 699 997	-5.7	0.000 000	-0.003



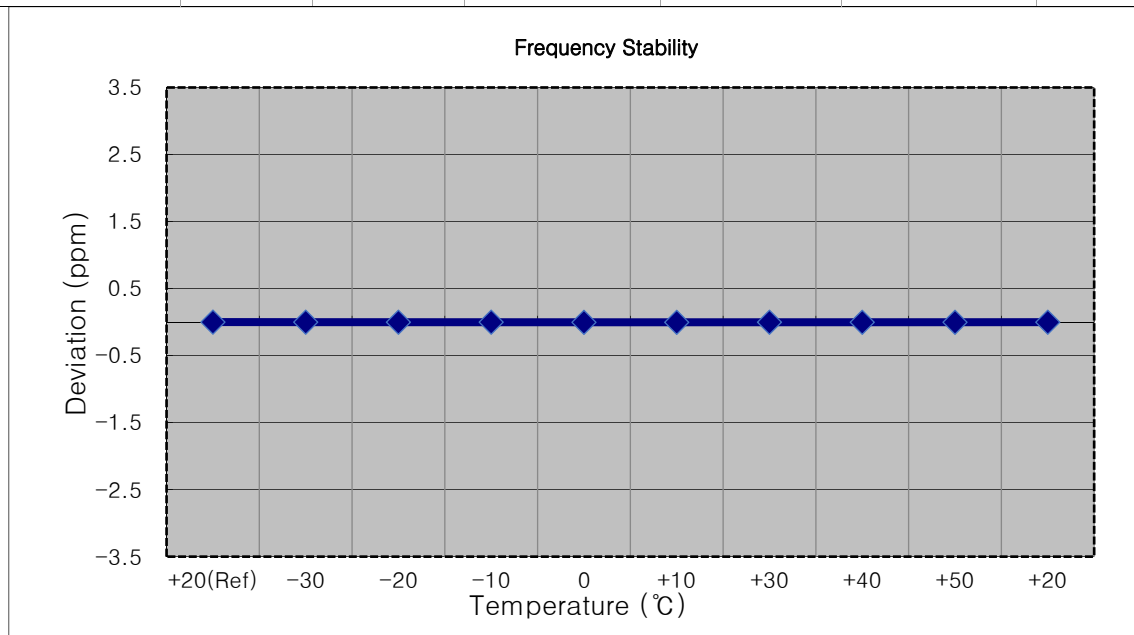
- MODE: LTE B25
- OPERATING FREQUENCY: 1851,500,000 Hz
- CHANNEL: 26055 (3 MHz)
- REFERENCE VOLTAGE: 3.880 VDC
- DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1851 500 009	0.0	0.000 000	0.000
100 %		-30	1851 500 005	-3.6	0.000 000	-0.002
100 %		-20	1851 500 015	5.8	0.000 000	0.003
100 %		-10	1851 500 015	6.3	0.000 000	0.003
100 %		0	1851 500 014	5.7	0.000 000	0.003
100 %		+10	1851 500 014	5.2	0.000 000	0.003
100 %		+30	1851 500 015	6.6	0.000 000	0.004
100 %		+40	1851 500 016	7.3	0.000 000	0.004
100 %		+50	1851 500 012	2.8	0.000 000	0.002
Batt. Endpoint	3.300	+20	1851 500 012	3.3	0.000 000	0.002



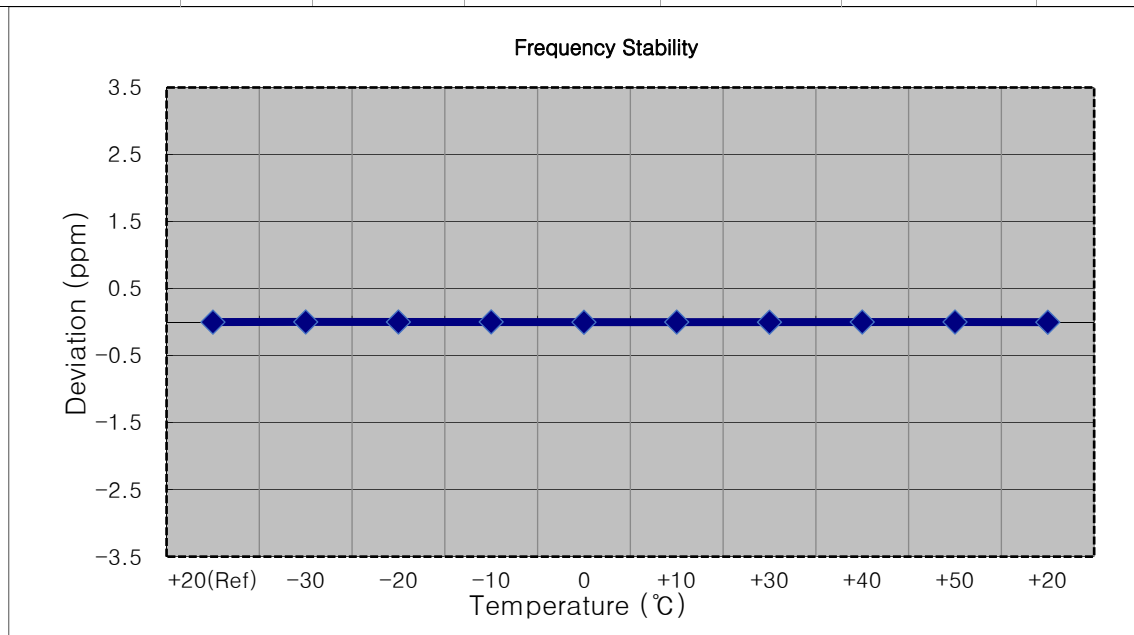
■ MODE: LTE B25
 ■ OPERATING FREQUENCY: 1852,500,000 Hz
 ■ CHANNEL: 26065 (5 MHz)
 ■ REFERENCE VOLTAGE: 3.880 VDC
 ■ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1852 499 996	0.0	0.000 000	0.000
100 %		-30	1852 499 993	-2.5	0.000 000	-0.001
100 %		-20	1852 499 992	-4.0	0.000 000	-0.002
100 %		-10	1852 499 994	-2.1	0.000 000	-0.001
100 %		0	1852 499 989	-6.6	0.000 000	-0.004
100 %		+10	1852 499 990	-5.8	0.000 000	-0.003
100 %		+30	1852 499 992	-3.9	0.000 000	-0.002
100 %		+40	1852 499 991	-5.0	0.000 000	-0.003
100 %		+50	1852 499 991	-4.4	0.000 000	-0.002
Batt. Endpoint	3.300	+20	1852 499 993	-3.1	0.000 000	-0.002



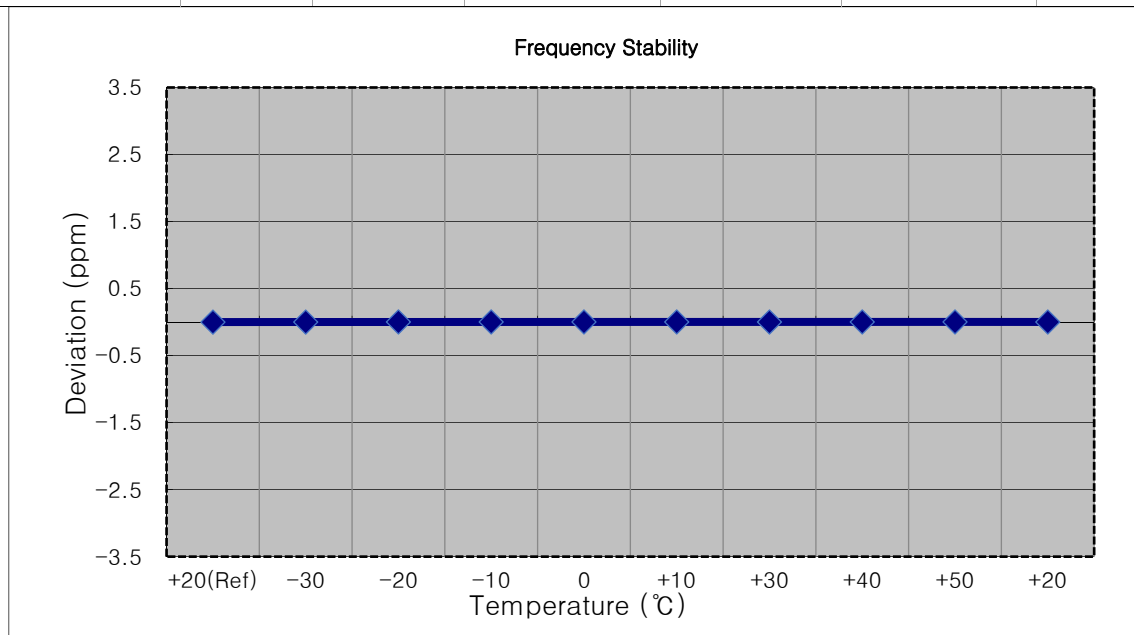
■ MODE: LTE B25
 ■ OPERATING FREQUENCY: 1855,000,000 Hz
 ■ CHANNEL: 26090 (10 MHz)
 ■ REFERENCE VOLTAGE: 3.880 VDC
 ■ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1855 000 003	0.0	0.000 000	0.000
100 %		-30	1855 000 007	4.0	0.000 000	0.002
100 %		-20	1855 000 005	2.5	0.000 000	0.001
100 %		-10	1855 000 008	5.0	0.000 000	0.003
100 %		0	1854 999 998	-4.2	0.000 000	-0.002
100 %		+10	1855 000 003	0.8	0.000 000	0.000
100 %		+30	1854 999 999	-3.6	0.000 000	-0.002
100 %		+40	1855 000 005	2.1	0.000 000	0.001
100 %		+50	1855 000 005	2.1	0.000 000	0.001
Batt. Endpoint	3.300	+20	1855 000 000	-3.0	0.000 000	-0.002



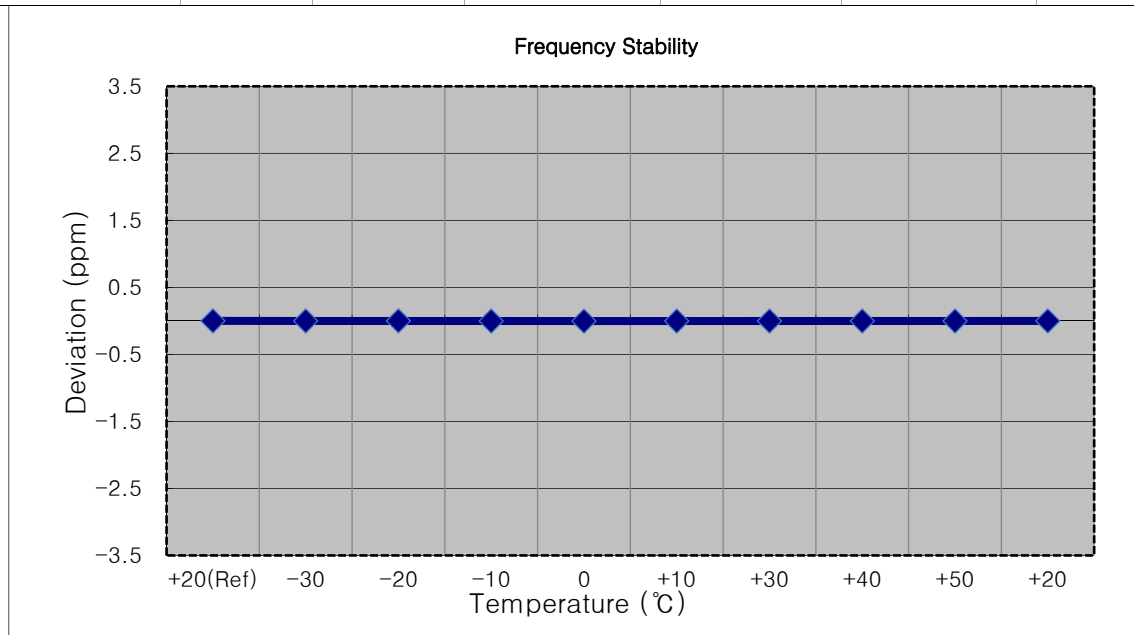
■ MODE: LTE B25
 ■ OPERATING FREQUENCY: 1857,500,000 Hz
 ■ CHANNEL: 26115 (15 MHz)
 ■ REFERENCE VOLTAGE: 3.880 VDC
 ■ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1857 500 002	0.0	0.000 000	0.000
100 %		-30	1857 500 003	1.2	0.000 000	0.001
100 %		-20	1857 500 005	3.3	0.000 000	0.002
100 %		-10	1857 500 005	3.2	0.000 000	0.002
100 %		0	1857 500 006	3.5	0.000 000	0.002
100 %		+10	1857 500 006	4.1	0.000 000	0.002
100 %		+30	1857 500 005	3.1	0.000 000	0.002
100 %		+40	1857 500 006	3.7	0.000 000	0.002
100 %		+50	1857 500 006	4.1	0.000 000	0.002
Batt. Endpoint	3.300	+20	1857 500 005	3.1	0.000 000	0.002



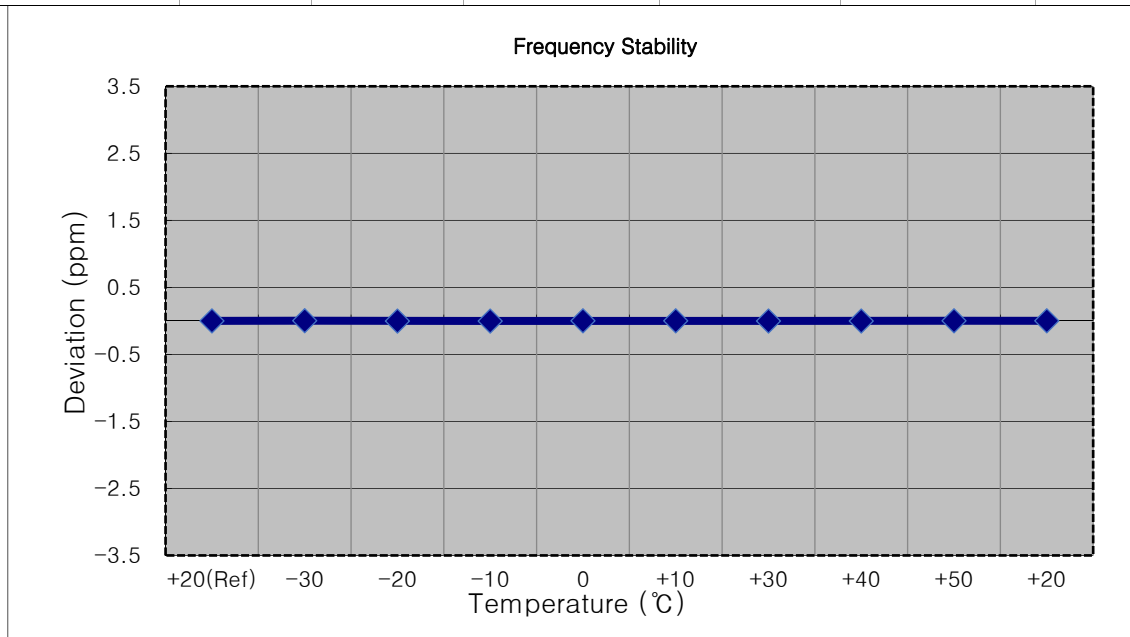
■ MODE:	<u>LTE B25</u>
■ OPERATING FREQUENCY:	<u>1860,000,000 Hz</u>
■ CHANNEL:	<u>26140 (20 MHz)</u>
■ REFERENCE VOLTAGE:	<u>3.880 VDC</u>
■ DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1859 999 998	0.0	0.000 000	0.000
100 %		-30	1859 999 996	-2.0	0.000 000	-0.001
100 %		-20	1860 000 000	1.7	0.000 000	0.001
100 %		-10	1859 999 993	-5.1	0.000 000	-0.003
100 %		0	1859 999 991	-6.4	0.000 000	-0.003
100 %		+10	1859 999 994	-4.2	0.000 000	-0.002
100 %		+30	1859 999 995	-2.7	0.000 000	-0.001
100 %		+40	1859 999 995	-2.8	0.000 000	-0.002
100 %		+50	1859 999 995	-2.7	0.000 000	-0.001
Batt. Endpoint	3.300	+20	1859 999 996	-1.6	0.000 000	-0.001



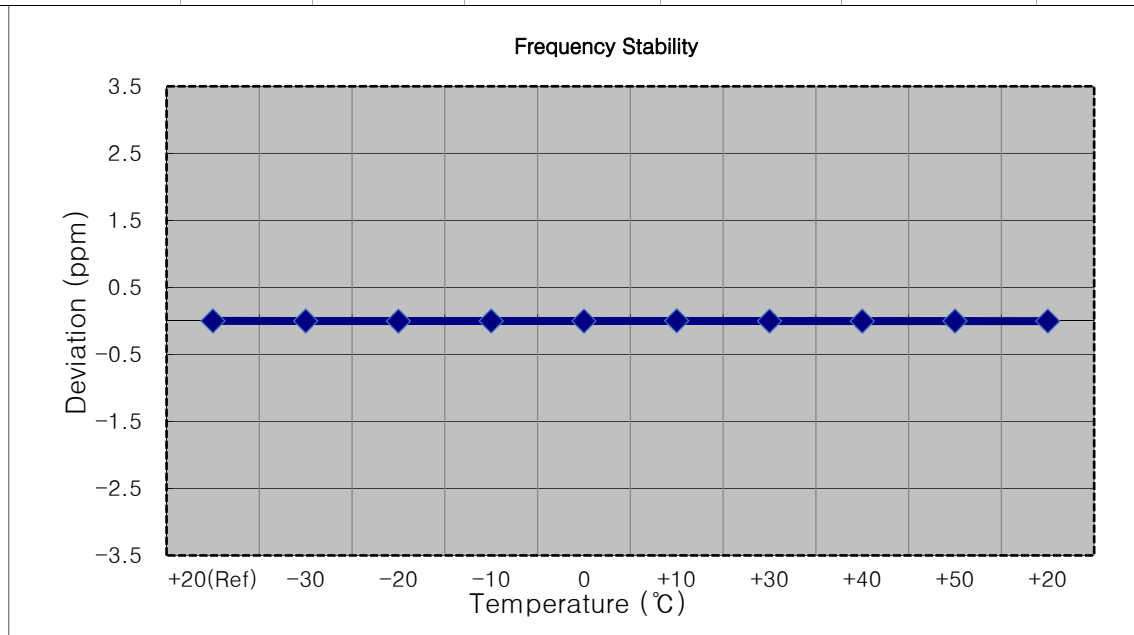
MODE:	<u>LTE B25</u>
OPERATING FREQUENCY:	<u>1882,500,000 Hz</u>
CHANNEL:	<u>26365 (1.4 MHz)</u>
REFERENCE VOLTAGE:	<u>3.880 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1882 500 002	0.0	0.000 000	0.000
100 %		-30	1882 500 008	5.6	0.000 000	0.003
100 %		-20	1882 499 998	-4.2	0.000 000	-0.002
100 %		-10	1882 499 998	-4.0	0.000 000	-0.002
100 %		0	1882 500 005	3.2	0.000 000	0.002
100 %		+10	1882 500 004	2.2	0.000 000	0.001
100 %		+30	1882 499 999	-2.6	0.000 000	-0.001
100 %		+40	1882 499 998	-3.9	0.000 000	-0.002
100 %		+50	1882 500 005	3.1	0.000 000	0.002
Batt. Endpoint	3.300	+20	1882 500 004	2.4	0.000 000	0.001



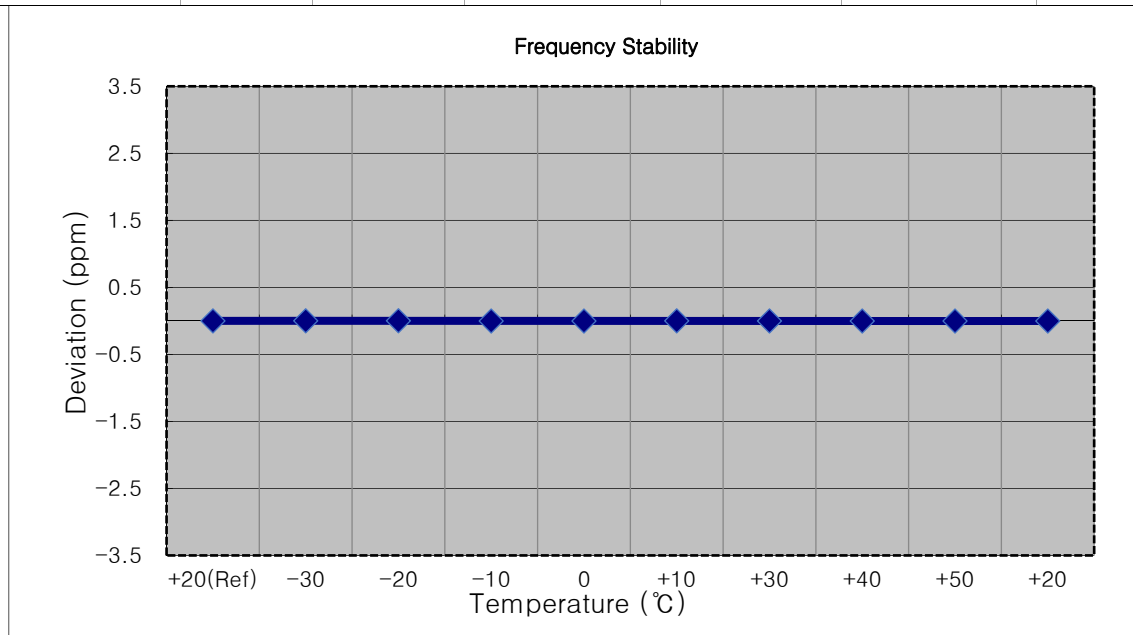
■ MODE:	<u>LTE B25</u>
■ OPERATING FREQUENCY:	<u>1882,500,000 Hz</u>
■ CHANNEL:	<u>26365 (3 MHz)</u>
■ REFERENCE VOLTAGE:	<u>3.880 VDC</u>
■ DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1882 499 997	0.0	0.000 000	0.000
100 %		-30	1882 499 993	-3.6	0.000 000	-0.002
100 %		-20	1882 499 990	-7.5	0.000 000	-0.004
100 %		-10	1882 499 994	-2.9	0.000 000	-0.002
100 %		0	1882 499 992	-5.4	0.000 000	-0.003
100 %		+10	1882 500 001	3.6	0.000 000	0.002
100 %		+30	1882 499 992	-4.9	0.000 000	-0.003
100 %		+40	1882 499 989	-8.3	0.000 000	-0.004
100 %		+50	1882 499 992	-5.3	0.000 000	-0.003
Batt. Endpoint	3.300	+20	1882 499 990	-6.6	0.000 000	-0.004



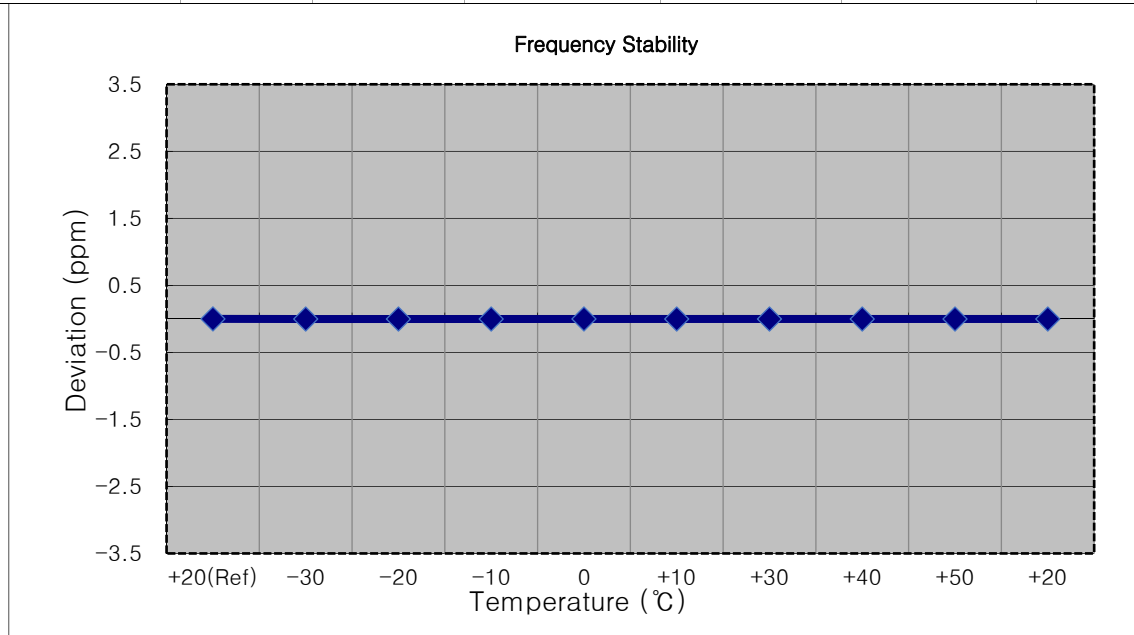
- ▣ MODE: LTE B25
- ▣ OPERATING FREQUENCY: 1882,500,000 Hz
- ▣ CHANNEL: 26365 (5 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1882 500 004	0.0	0.000 000	0.000
100 %		-30	1882 500 006	2.4	0.000 000	0.001
100 %		-20	1882 500 008	3.9	0.000 000	0.002
100 %		-10	1882 500 001	-2.9	0.000 000	-0.002
100 %		0	1882 500 001	-2.8	0.000 000	-0.001
100 %		+10	1882 500 006	2.0	0.000 000	0.001
100 %		+30	1882 500 002	-2.2	0.000 000	-0.001
100 %		+40	1882 500 001	-2.8	0.000 000	-0.001
100 %		+50	1882 500 001	-3.3	0.000 000	-0.002
Batt. Endpoint	3.300	+20	1882 500 001	-3.1	0.000 000	-0.002



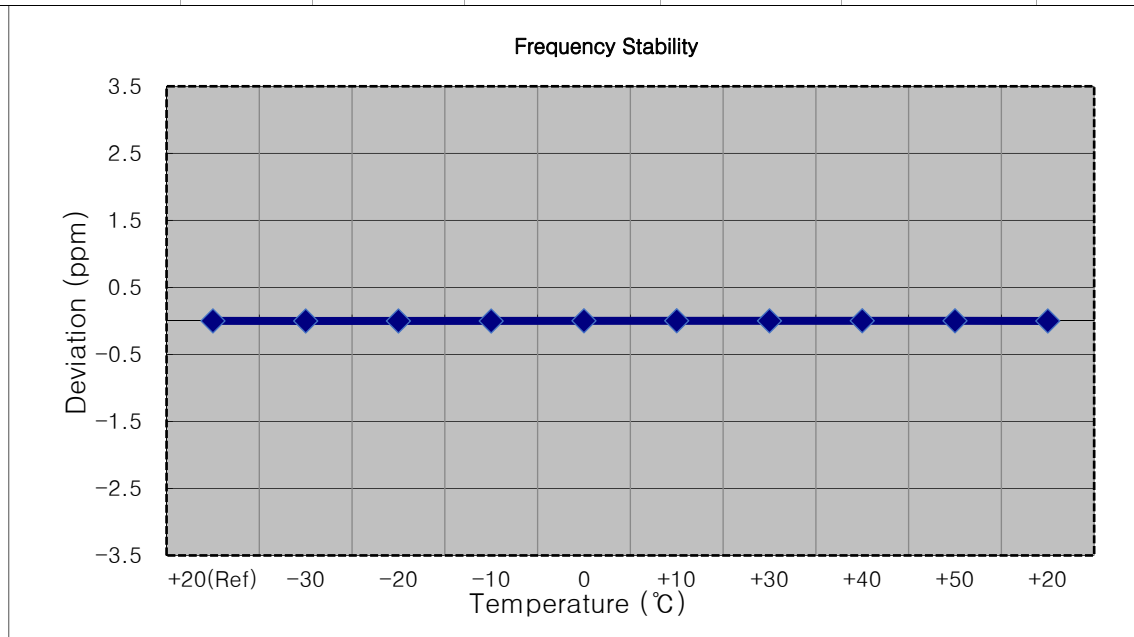
MODE:	<u>LTE B25</u>
OPERATING FREQUENCY:	<u>1882,500,000 Hz</u>
CHANNEL:	<u>26365 (10 MHz)</u>
REFERENCE VOLTAGE:	<u>3.880 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1882 499 997	0.0	0.000 000	0.000
100 %		-30	1882 499 994	-3.7	0.000 000	-0.002
100 %		-20	1882 499 994	-3.2	0.000 000	-0.002
100 %		-10	1882 499 995	-2.5	0.000 000	-0.001
100 %		0	1882 499 995	-2.4	0.000 000	-0.001
100 %		+10	1882 499 994	-3.9	0.000 000	-0.002
100 %		+30	1882 499 995	-2.9	0.000 000	-0.002
100 %		+40	1882 499 994	-3.2	0.000 000	-0.002
100 %		+50	1882 499 995	-2.5	0.000 000	-0.001
Batt. Endpoint	3.300	+20	1882 499 994	-3.1	0.000 000	-0.002



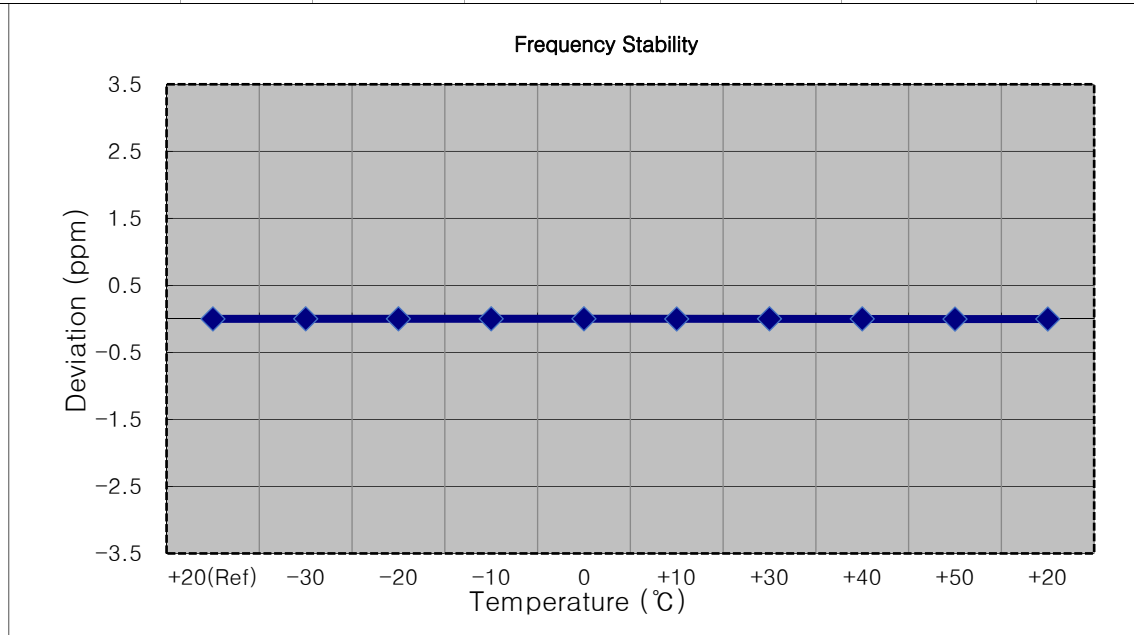
MODE:	<u>LTE B25</u>
OPERATING FREQUENCY:	<u>1882,500,000 Hz</u>
CHANNEL:	<u>26365 (15 MHz)</u>
REFERENCE VOLTAGE:	<u>3.880 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1882 499 995	0.0	0.000 000	0.000
100 %		-30	1882 499 994	-1.8	0.000 000	-0.001
100 %		-20	1882 499 993	-2.1	0.000 000	-0.001
100 %		-10	1882 499 992	-3.4	0.000 000	-0.002
100 %		0	1882 499 998	2.3	0.000 000	0.001
100 %		+10	1882 499 999	4.0	0.000 000	0.002
100 %		+30	1882 499 997	1.4	0.000 000	0.001
100 %		+40	1882 499 999	3.9	0.000 000	0.002
100 %		+50	1882 499 998	2.6	0.000 000	0.001
Batt. Endpoint	3.300	+20	1882 499 993	-2.1	0.000 000	-0.001



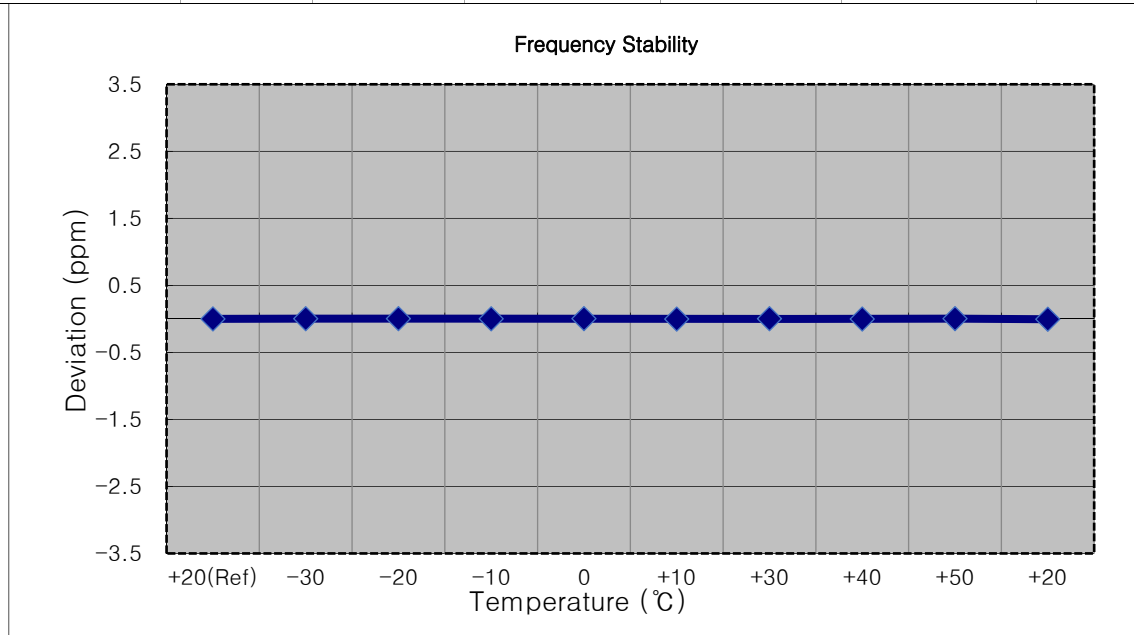
■ MODE:	<u>LTE B25</u>
■ OPERATING FREQUENCY:	<u>1882,500,000 Hz</u>
■ CHANNEL:	<u>26365 (20 MHz)</u>
■ REFERENCE VOLTAGE:	<u>3.880 VDC</u>
■ DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1882 499 998	0.0	0.000 000	0.000
100 %		-30	1882 500 001	2.5	0.000 000	0.001
100 %		-20	1882 500 001	3.0	0.000 000	0.002
100 %		-10	1882 500 002	3.2	0.000 000	0.002
100 %		0	1882 500 001	3.1	0.000 000	0.002
100 %		+10	1882 499 996	-2.4	0.000 000	-0.001
100 %		+30	1882 500 000	2.1	0.000 000	0.001
100 %		+40	1882 500 000	1.7	0.000 000	0.001
100 %		+50	1882 499 993	-5.3	0.000 000	-0.003
Batt. Endpoint	3.300	+20	1882 499 994	-3.9	0.000 000	-0.002



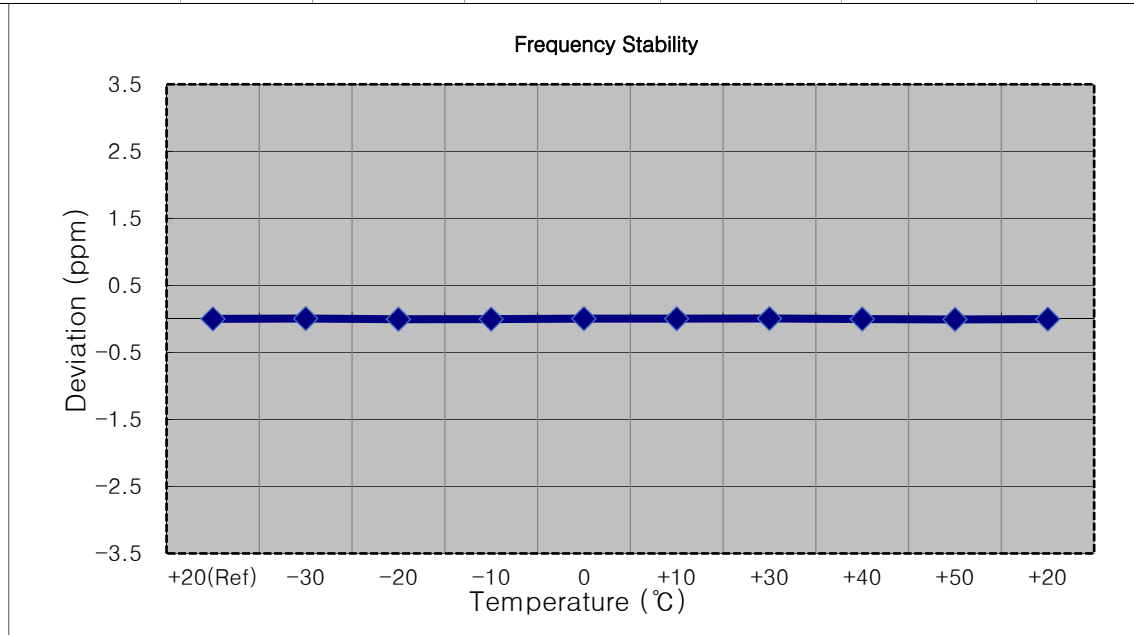
■ MODE:	<u>LTE B25</u>
■ OPERATING FREQUENCY:	<u>1914,300,000 Hz</u>
■ CHANNEL:	<u>26683 (1.4 MHz)</u>
■ REFERENCE VOLTAGE:	<u>3.880 VDC</u>
■ DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1914 300 005	0.0	0.000 000	0.000
100 %		-30	1914 300 012	6.4	0.000 000	0.003
100 %		-20	1914 300 013	8.0	0.000 000	0.004
100 %		-10	1914 300 009	3.4	0.000 000	0.002
100 %		0	1914 300 012	7.3	0.000 000	0.004
100 %		+10	1914 300 000	-5.4	0.000 000	-0.003
100 %		+30	1914 300 011	6.3	0.000 000	0.003
100 %		+40	1914 300 002	-2.7	0.000 000	-0.001
100 %		+50	1914 300 012	7.2	0.000 000	0.004
Batt. Endpoint	3.300	+20	1914 299 996	-9.4	0.000 000	-0.005



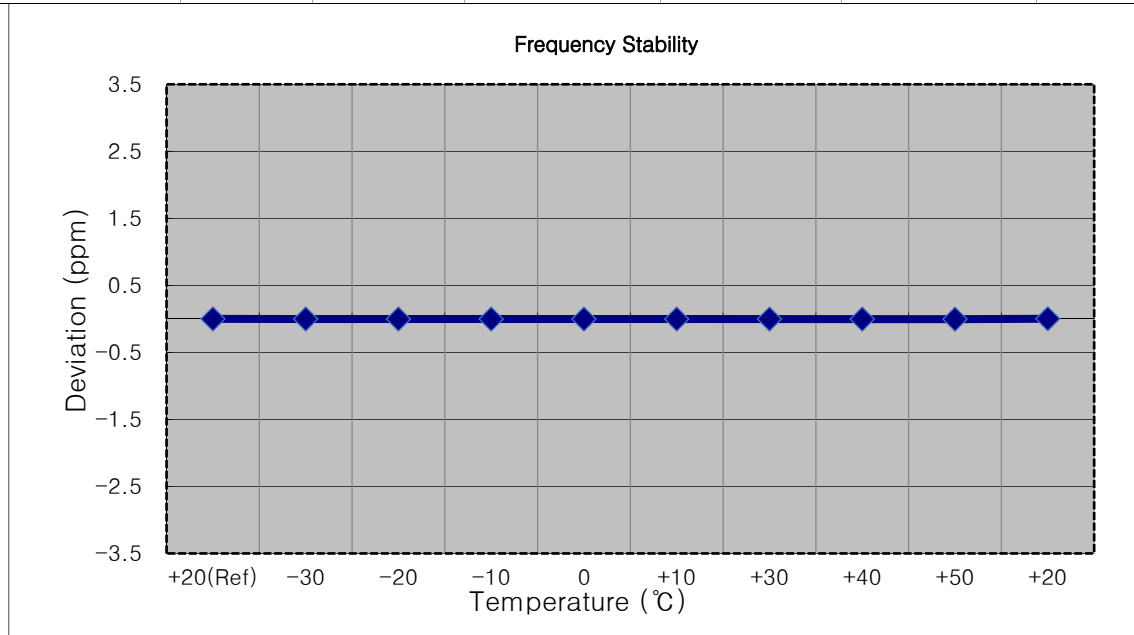
■ MODE:	<u>LTE B25</u>
■ OPERATING FREQUENCY:	<u>1913,500,000 Hz</u>
■ CHANNEL:	<u>26675 (3 MHz)</u>
■ REFERENCE VOLTAGE:	<u>3.880 VDC</u>
■ DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1913 499 991	0.0	0.000 000	0.000
100 %		-30	1913 500 000	8.9	0.000 000	0.005
100 %		-20	1913 499 981	-9.7	-0.000 001	-0.005
100 %		-10	1913 499 984	-7.2	0.000 000	-0.004
100 %		0	1913 499 998	7.1	0.000 000	0.004
100 %		+10	1913 499 997	6.5	0.000 000	0.003
100 %		+30	1913 500 002	10.8	0.000 001	0.006
100 %		+40	1913 499 986	-5.3	0.000 000	-0.003
100 %		+50	1913 499 975	-15.8	-0.000 001	-0.008
Batt. Endpoint	3.300	+20	1913 499 985	-6.3	0.000 000	-0.003



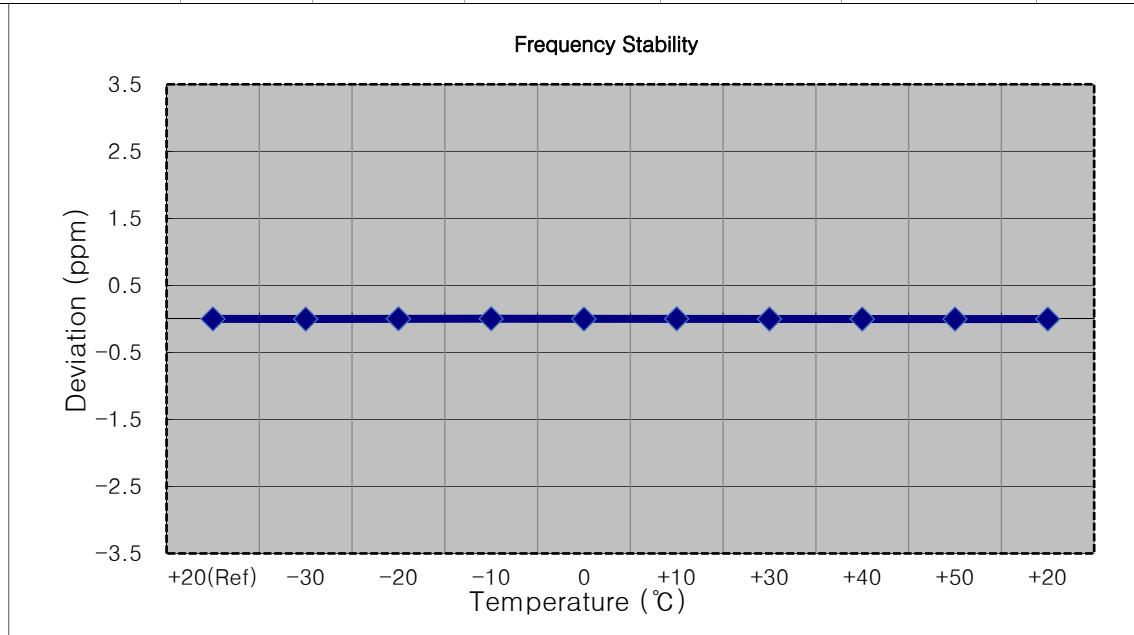
MODE:	<u>LTE B25</u>
OPERATING FREQUENCY:	<u>1912,500,000 Hz</u>
CHANNEL:	<u>26665 (5 MHz)</u>
REFERENCE VOLTAGE:	<u>3.880 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1912 499 996	0.0	0.000 000	0.000
100 %		-30	1912 499 993	-3.7	0.000 000	-0.002
100 %		-20	1912 499 993	-3.4	0.000 000	-0.002
100 %		-10	1912 499 992	-4.2	0.000 000	-0.002
100 %		0	1912 499 991	-5.1	0.000 000	-0.003
100 %		+10	1912 499 992	-4.3	0.000 000	-0.002
100 %		+30	1912 499 993	-3.3	0.000 000	-0.002
100 %		+40	1912 499 990	-6.2	0.000 000	-0.003
100 %		+50	1912 499 988	-8.4	0.000 000	-0.004
Batt. Endpoint	3.300	+20	1912 500 000	3.8	0.000 000	0.002



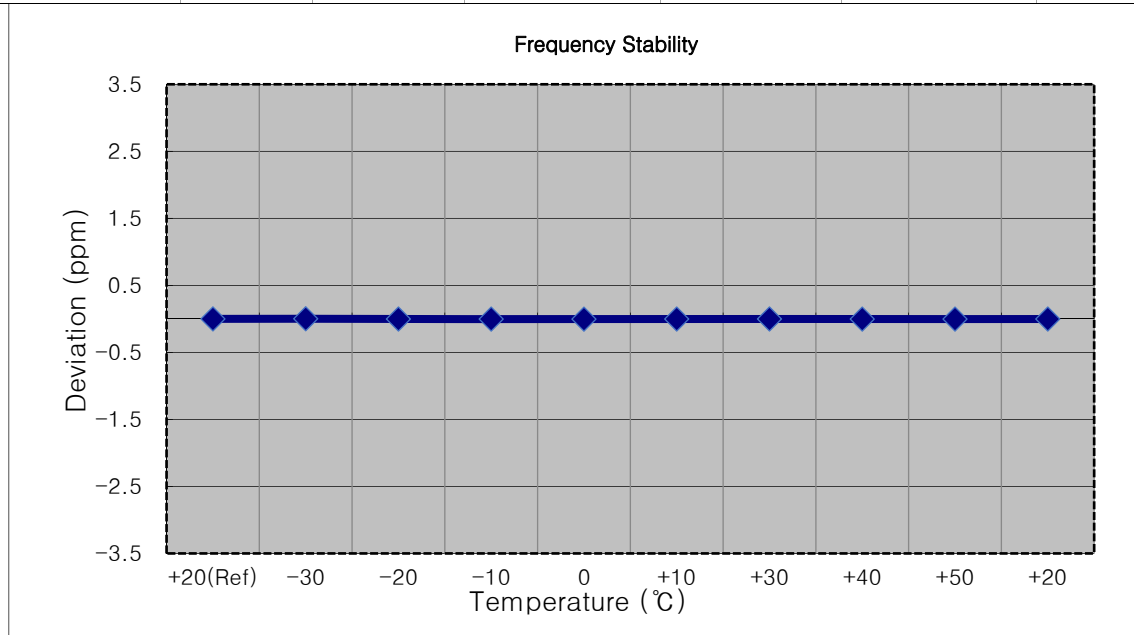
MODE:	<u>LTE B25</u>
OPERATING FREQUENCY:	<u>1910,000,000 Hz</u>
CHANNEL:	<u>26640 (10 MHz)</u>
REFERENCE VOLTAGE:	<u>3.880 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1910 000 002	0.0	0.000 000	0.000
100 %		-30	1909 999 998	-4.5	0.000 000	-0.002
100 %		-20	1910 000 006	3.8	0.000 000	0.002
100 %		-10	1910 000 008	5.3	0.000 000	0.003
100 %		0	1909 999 999	-3.3	0.000 000	-0.002
100 %		+10	1910 000 007	4.5	0.000 000	0.002
100 %		+30	1909 999 999	-2.8	0.000 000	-0.001
100 %		+40	1909 999 999	-3.4	0.000 000	-0.002
100 %		+50	1909 999 997	-5.5	0.000 000	-0.003
Batt. Endpoint	3.300	+20	1909 999 998	-4.4	0.000 000	-0.002



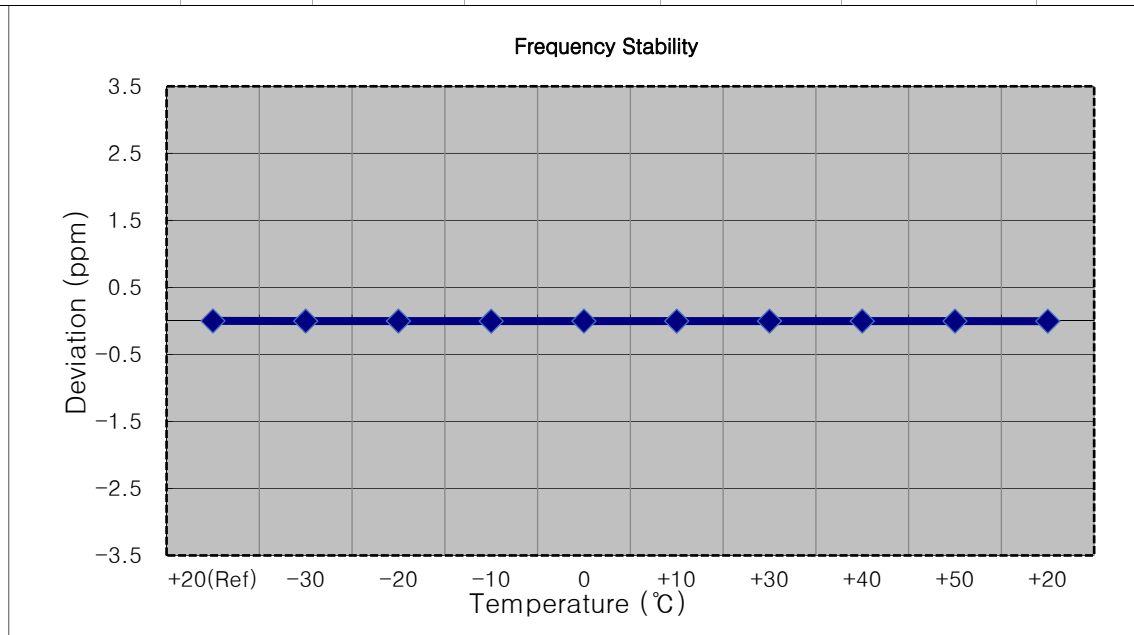
■ MODE:	<u>LTE B25</u>
■ OPERATING FREQUENCY:	<u>1907,500,000 Hz</u>
■ CHANNEL:	<u>26615 (15 MHz)</u>
■ REFERENCE VOLTAGE:	<u>3.880 VDC</u>
■ DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1907 499 995	0.0	0.000 000	0.000
100 %		-30	1907 499 999	4.3	0.000 000	0.002
100 %		-20	1907 499 992	-3.6	0.000 000	-0.002
100 %		-10	1907 499 990	-5.4	0.000 000	-0.003
100 %		0	1907 499 989	-6.2	0.000 000	-0.003
100 %		+10	1907 499 992	-3.4	0.000 000	-0.002
100 %		+30	1907 499 993	-2.5	0.000 000	-0.001
100 %		+40	1907 499 990	-5.2	0.000 000	-0.003
100 %		+50	1907 499 990	-5.4	0.000 000	-0.003
Batt. Endpoint	3.300	+20	1907 499 992	-3.4	0.000 000	-0.002



- MODE: LTE B25
- OPERATING FREQUENCY: 1905,000,000 Hz
- CHANNEL: 26590 (20 MHz)
- REFERENCE VOLTAGE: 3.880 VDC
- DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1904 999 994	0.0	0.000 000	0.000
100 %		-30	1904 999 988	-5.3	0.000 000	-0.003
100 %		-20	1904 999 989	-4.2	0.000 000	-0.002
100 %		-10	1904 999 987	-7.1	0.000 000	-0.004
100 %		0	1904 999 988	-5.3	0.000 000	-0.003
100 %		+10	1904 999 988	-5.8	0.000 000	-0.003
100 %		+30	1904 999 988	-6.0	0.000 000	-0.003
100 %		+40	1904 999 989	-4.9	0.000 000	-0.003
100 %		+50	1904 999 987	-6.3	0.000 000	-0.003
Batt. Endpoint	3.300	+20	1904 999 985	-8.3	0.000 000	-0.004



9. TEST DATA(Sub1)

9.1 EQUIVALENT ISOTROPIC RADIATED POWER

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
								W	W	dBm	Size	Offset
1850.7	LTE B25 1.4 MHz	QPSK	-20.58	13.94	10.40	2.07	V	< 2.00	0.169	22.27	1	0
		16-QAM	-21.24	13.28	10.40	2.07	V		0.145	21.61		
		64-QAM	-22.32	12.20	10.40	2.07	V		0.113	20.53		
		256-QAM	-25.42	9.10	10.40	2.07	V		0.055	17.43		
1882.5		QPSK	-21.54	13.44	10.40	2.21	V		0.146	21.63	1	0
		16-QAM	-22.13	12.85	10.40	2.21	V		0.127	21.04		
		64-QAM	-23.22	11.76	10.40	2.21	V		0.099	19.95		
		256-QAM	-26.36	8.62	10.40	2.21	V		0.048	16.81		
1914.3		QPSK	-22.32	12.69	10.40	2.17	V		0.124	20.92	1	0
		16-QAM	-23.04	11.97	10.40	2.17	V		0.105	20.20		
		64-QAM	-24.15	10.86	10.40	2.17	V		0.081	19.09		
		256-QAM	-27.21	7.80	10.40	2.17	V		0.040	16.03		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
								W	W	dBm	Size	Offset
1851.5	LTE B25 3 MHz	QPSK	-20.52	14.00	10.40	2.07	V	< 2.00	0.171	22.33	1	0
		16-QAM	-21.19	13.33	10.40	2.07	V		0.147	21.66		
		64-QAM	-22.25	12.27	10.40	2.07	V		0.115	20.60		
		256-QAM	-25.35	9.17	10.40	2.07	V		0.056	17.50		
1882.5		QPSK	-21.25	13.73	10.40	2.21	V		0.156	21.92	1	0
		16-QAM	-21.98	13.00	10.40	2.21	V		0.132	21.19		
		64-QAM	-23.06	11.92	10.40	2.21	V		0.103	20.11		
		256-QAM	-26.11	8.87	10.40	2.21	V		0.051	17.06		
1913.5		QPSK	-22.27	12.74	10.40	2.17	V		0.125	20.97	1	0
		16-QAM	-23.07	11.94	10.40	2.17	V		0.104	20.17		
		64-QAM	-24.15	10.86	10.40	2.17	V		0.081	19.09		
		256-QAM	-27.18	7.83	10.40	2.17	V		0.040	16.06		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
								W	W	dBm	Size	Offset
1852.5	LTE B25 5 MHz	QPSK	-20.42	14.15	10.40	2.08	V	< 2.00	0.177	22.47	1	0
		16-QAM	-21.13	13.44	10.40	2.08	V		0.150	21.76		
		64-QAM	-22.28	12.29	10.40	2.08	V		0.115	20.61		
		256-QAM	-25.43	9.14	10.40	2.08	V		0.056	17.46		
1882.5		QPSK	-21.08	13.90	10.40	2.21	V		0.162	22.09	1	0
		16-QAM	-21.80	13.18	10.40	2.21	V		0.137	21.37		
		64-QAM	-22.94	12.04	10.40	2.21	V		0.105	20.23		
		256-QAM	-26.06	8.92	10.40	2.21	V		0.051	17.11		
1912.5		QPSK	-22.18	12.83	10.40	2.17	V		0.128	21.06	1	0
		16-QAM	-22.98	12.03	10.40	2.17	V		0.106	20.26		
		64-QAM	-24.04	10.97	10.40	2.17	V		0.083	19.20		
		256-QAM	-27.30	7.71	10.40	2.17	V		0.039	15.94		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
								W	W	dBm	Size	Offset
1855.0	LTE B25 10 MHz	QPSK	-20.52	14.05	10.40	2.08	V	< 2.00	0.173	22.37	1	0
		16-QAM	-21.33	13.24	10.40	2.08	V		0.143	21.56		
		64-QAM	-22.40	12.17	10.40	2.08	V		0.112	20.49		
		256-QAM	-25.44	9.13	10.40	2.08	V		0.056	17.45		
1882.5		QPSK	-21.13	13.85	10.40	2.21	V		0.160	22.04	1	0
		16-QAM	-21.96	13.02	10.40	2.21	V		0.132	21.21		
		64-QAM	-23.04	11.94	10.40	2.21	V		0.103	20.13		
		256-QAM	-26.14	8.84	10.40	2.21	V		0.050	17.03		
1910.0		QPSK	-22.07	12.87	10.40	2.17	V		0.129	21.10	1	0
		16-QAM	-22.81	12.13	10.40	2.17	V		0.109	20.36		
		64-QAM	-23.92	11.02	10.40	2.17	V		0.084	19.25		
		256-QAM	-27.05	7.89	10.40	2.17	V		0.041	16.12		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
								W	W	dBm	Size	Offset
1857.5	LTE B25 15 MHz	QPSK	-20.48	14.16	10.40	2.10	V	< 2.00	0.176	22.46	1	0
		16-QAM	-21.36	13.28	10.40	2.10	V		0.144	21.58		
		64-QAM	-22.41	12.23	10.40	2.10	V		0.113	20.53		
		256-QAM	-25.46	9.18	10.40	2.10	V		0.056	17.48		
1882.5		QPSK	-20.94	14.04	10.40	2.21	V		0.167	22.23	1	0
		16-QAM	-21.81	13.17	10.40	2.21	V		0.137	21.36		
		64-QAM	-22.86	12.12	10.40	2.21	V		0.107	20.31		
		256-QAM	-26.04	8.94	10.40	2.21	V		0.052	17.13		
1907.5		QPSK	-21.71	13.23	10.40	2.17	V		0.140	21.46	1	0
		16-QAM	-22.65	12.29	10.40	2.17	V		0.113	20.52		
		64-QAM	-23.68	11.26	10.40	2.17	V		0.089	19.49		
		256-QAM	-26.80	8.14	10.40	2.17	V		0.043	16.37		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
								W	W	dBm	Size	Offset
1860.0	LTE B25 20 MHz	QPSK	-20.52	14.12	10.40	2.10	V	< 2.00	0.175	22.42	1	0
		16-QAM	-21.38	13.26	10.40	2.10	V		0.143	21.56		
		64-QAM	-22.41	12.23	10.40	2.10	V		0.113	20.53		
		256-QAM	-25.56	9.08	10.40	2.10	V		0.055	17.38		
1882.5		QPSK	-20.82	14.16	10.40	2.21	V		0.172	22.35	1	0
		16-QAM	-21.68	13.30	10.40	2.21	V		0.141	21.49		
		64-QAM	-22.71	12.27	10.40	2.21	V		0.111	20.46		
		256-QAM	-25.84	9.14	10.40	2.21	V		0.054	17.33		
1905.0		QPSK	-21.80	13.12	10.40	2.19	V		0.136	21.33	1	0
		16-QAM	-22.71	12.21	10.40	2.19	V		0.110	20.42		
		64-QAM	-23.73	11.19	10.40	2.19	V		0.087	19.40		
		256-QAM	-26.81	8.11	10.40	2.19	V		0.043	16.32		

9.2 RADIATED SPURIOUS EMISSIONS

▣ OPERATING FREQUENCY:	<u>1852.5 MHz</u>
▣ MEASURED OUTPUT POWER:	<u>22.47 dBm = 0.177 W</u>
▣ MOD:	<u>LTE B25</u>
▣ MODULATION SIGNAL:	<u>5 MHz QPSK</u>
▣ DISTANCE:	<u>3 meters</u>
▣ LIMIT: $43 + 10 \log_{10} (W) =$	<u>-13 dBm</u>

Ch	Freq (MHz)	Measured Level (dBm)	Ant. Gain (dBi)	Substitute Level (dBm)	C.L	Pol	Result (dBm)	RB	
								Size	Offset
26065 (1852.5)	3 705.00	-48.78	12.30	-61.35	3.08	V	-52.13	1	0
	5 557.50	-51.58	13.20	-56.97	3.88	V	-47.65		
	7 410.00	-52.29	10.80	-48.28	4.57	V	-42.05		
26365 (1882.5)	3 765.00	-48.23	12.33	-60.67	3.11	V	-51.45	1	0
	5 647.50	-51.90	13.10	-57.39	3.96	V	-48.25		
	7 530.00	-51.05	10.86	-46.94	4.60	V	-40.68		
26665 (1912.5)	3 825.00	-48.78	12.40	-60.44	3.18	V	-51.22	1	0
	5 737.50	-50.73	13.02	-55.67	3.99	V	-46.64		
	7 650.00	-50.94	11.30	-47.52	4.68	V	-40.90		

9.3 PEAK-TO-AVERAGE RATIO

Band	Band Width	Frequency (MHz)	Modulation	Resource Block Size	Resource Block Offset	Data (dB)
25	1.4 MHz	1882.5	QPSK	6	0	4.81
			16-QAM	6	0	6.00
			64-QAM	6	0	6.55
			256-QAM	6	0	6.75
	3 MHz		QPSK	15	0	4.76
			16-QAM	15	0	6.05
			64-QAM	15	0	6.56
			256-QAM	15	0	6.72
	5 MHz		QPSK	25	0	4.86
			16-QAM	25	0	5.87
			64-QAM	25	0	6.52
			256-QAM	25	0	6.70
	10 MHz		QPSK	50	0	4.93
			16-QAM	50	0	5.91
			64-QAM	50	0	6.50
			256-QAM	50	0	6.70
	15 MHz		QPSK	75	0	4.92
			16-QAM	75	0	6.05
			64-QAM	75	0	6.61
			256-QAM	75	0	6.72
	20 MHz		QPSK	100	0	4.99
			16-QAM	100	0	5.98
			64-QAM	100	0	6.59
			256-QAM	100	0	6.74

Note:

1. Plots of the EUT's Peak- to- Average Ratio are shown Page 198 ~ 221.

9.4 OCCUPIED BANDWIDTH

Band	Band Width	Frequency (MHz)	Modulation	Resource Block Size	Resource Block Offset	Data (MHz)
25	1.4 MHz	1882.5	QPSK	6	0	1.1029
			16-QAM	6	0	1.1016
			64-QAM	6	0	1.0968
			256-QAM	6	0	1.0989
	3 MHz		QPSK	15	0	2.7162
			16-QAM	15	0	2.7178
			64-QAM	15	0	2.7146
			256-QAM	15	0	2.7137
	5 MHz		QPSK	25	0	4.5135
			16-QAM	25	0	4.5144
			64-QAM	25	0	4.5207
			256-QAM	25	0	4.5067
	10 MHz		QPSK	50	0	9.0086
			16-QAM	50	0	9.0037
			64-QAM	50	0	9.0025
			256-QAM	50	0	8.9864
	15 MHz		QPSK	75	0	13.475
			16-QAM	75	0	13.499
			64-QAM	75	0	13.469
			256-QAM	75	0	13.505
	20 MHz		QPSK	100	0	17.940
			16-QAM	100	0	17.957
			64-QAM	100	0	17.967
			256-QAM	100	0	17.994

Note:

1. Plots of the EUT's Occupied Bandwidth are shown Page 222 ~ 245.

9.5 CONDUCTED SPURIOUS EMISSIONS

Band	Band Width (MHz)	Frequency (MHz)	Frequency of Maximum Harmonic (GHz)	Factor (dB)	Measurement Maximum Data (dBm)	Result (dBm)	Limit (dBm)
25	1.4	1850.7	3.6975	27.976	-77.497	-49.521	-13.00
		1882.5	3.6795	27.976	-77.299	-49.323	
		1914.3	3.7054	27.976	-77.067	-49.091	
	3	1851.5	3.6955	27.976	-77.220	-49.244	
		1882.5	3.6705	27.976	-77.141	-49.165	
		1913.5	3.1785	27.976	-77.342	-49.366	
	5	1852.5	3.6860	27.976	-77.064	-49.088	
		1882.5	3.7010	27.976	-77.131	-49.155	
		1912.5	3.6960	27.976	-77.108	-49.132	
	10	1855.0	3.6990	27.976	-77.271	-49.295	
		1882.5	3.7054	27.976	-77.108	-49.132	
		1910.0	3.7084	27.976	-77.304	-49.328	
	15	1857.5	3.7010	27.976	-77.140	-49.164	
		1882.5	3.7149	27.976	-77.498	-49.522	
		1907.5	3.6691	27.976	-77.297	-49.321	
	20	1860.0	3.6666	27.976	-77.036	-49.060	
		1882.5	3.7094	27.976	-76.661	-48.685	
		1905.0	3.0709	27.976	-77.340	-49.364	

Note:

1. Plots of the EUT's Conducted Spurious Emissions are shown Page 246 ~ 281.
2. Conducted Spurious Emissions was Tested QPSK Modulation, Resource Block Size 1 and Resource Block Offset 0
3. Result (dBm) = Measurement Maximum Data (dBm) + Factor (dB)
4. Factor(dB) = Cable Loss + Ext. Attenuator + Power Splitter

Frequency Range (GHz)	Factor [dB]
0.03 – 1	25.270
1 – 5	27.976
5 – 10	28.591
10 – 15	29.116
15 – 20	29.489
Above 20(26.5)	30.131

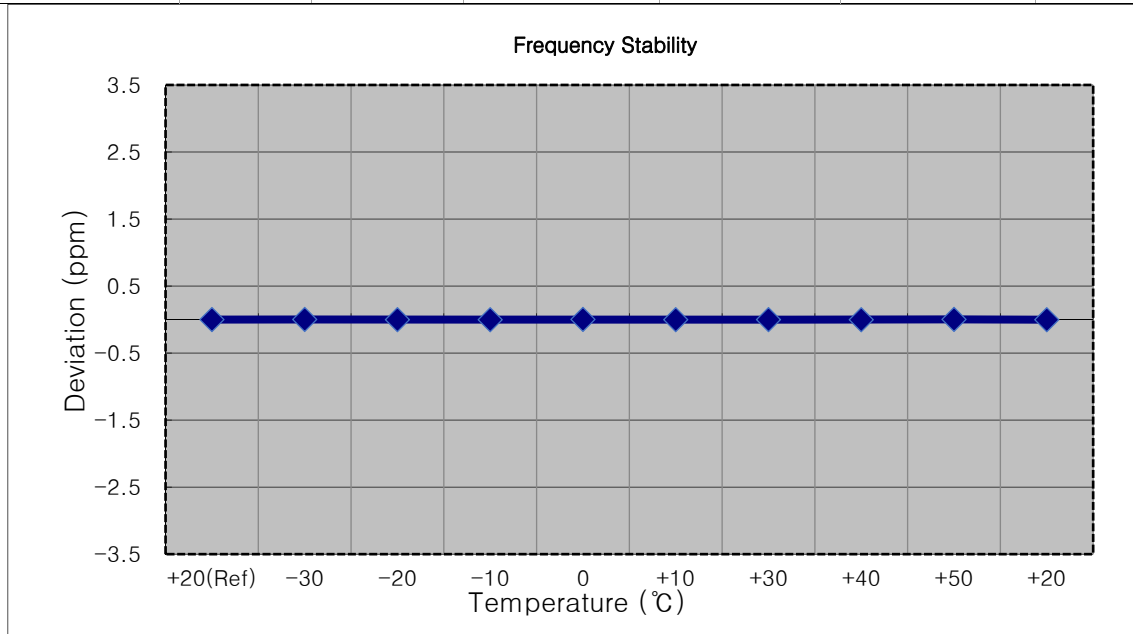
9.6 BAND EDGE

- Plots of the EUT's Band Edge are shown Page 282 ~ 317.

9.7 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE

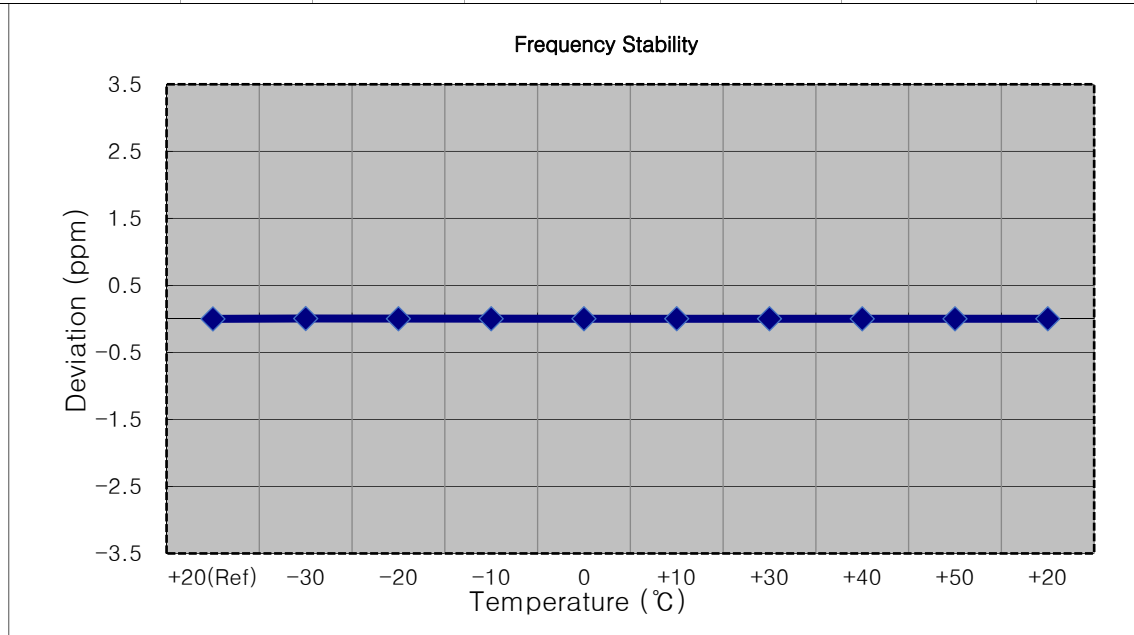
MODE:	<u>LTE B25</u>
OPERATING FREQUENCY:	<u>1850,700,000 Hz</u>
CHANNEL:	<u>26047 (1.4 MHz)</u>
REFERENCE VOLTAGE:	<u>3.880 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.880	+20(Ref)	1850 700 002	0.0	0.000 000	0.000
100%		-30	1850 700 005	2.8	0.000 000	0.002
100%		-20	1850 699 999	-3.3	0.000 000	-0.002
100%		-10	1850 699 998	-4.2	0.000 000	-0.002
100%		0	1850 700 007	4.2	0.000 000	0.002
100%		+10	1850 700 000	-2.4	0.000 000	-0.001
100%		+30	1850 700 000	-2.1	0.000 000	-0.001
100%		+40	1850 699 999	-3.7	0.000 000	-0.002
100%		+50	1850 700 008	5.2	0.000 000	0.003
Batt. Endpoint	3.300	+20	1850 699 998	-4.3	0.000 000	-0.002



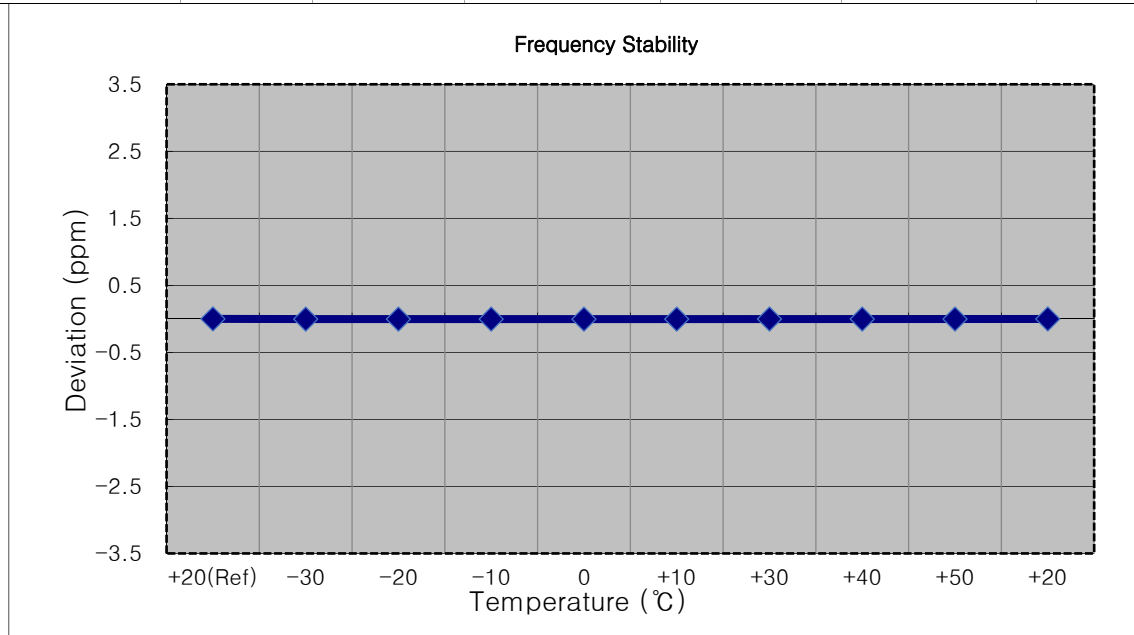
■ MODE:	<u>LTE B25</u>
■ OPERATING FREQUENCY:	<u>1851,500,000 Hz</u>
■ CHANNEL:	<u>26055 (3 MHz)</u>
■ REFERENCE VOLTAGE:	<u>3.880 VDC</u>
■ DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.880	+20(Ref)	1851 500 004	0.0	0.000 000	0.000
100%		-30	1851 500 014	10.2	0.000 001	0.006
100%		-20	1851 500 008	4.4	0.000 000	0.002
100%		-10	1851 500 008	4.4	0.000 000	0.002
100%		0	1851 500 008	4.1	0.000 000	0.002
100%		+10	1851 500 009	5.0	0.000 000	0.003
100%		+30	1851 500 008	4.7	0.000 000	0.003
100%		+40	1851 500 006	2.3	0.000 000	0.001
100%		+50	1851 500 007	3.3	0.000 000	0.002
Batt. Endpoint	3.300	+20	1851 500 008	3.9	0.000 000	0.002



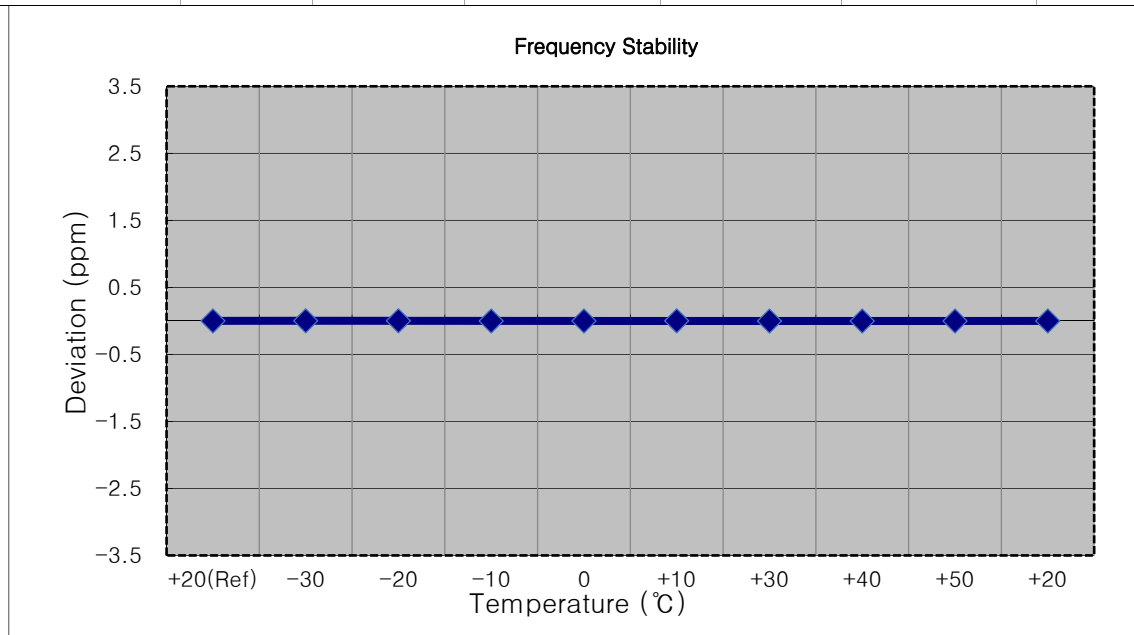
MODE:	<u>LTE B25</u>
OPERATING FREQUENCY:	<u>1852,500,000 Hz</u>
CHANNEL:	<u>26065 (5 MHz)</u>
REFERENCE VOLTAGE:	<u>3.880 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.880	+20(Ref)	1852 499 995	0.0	0.000 000	0.000
100%		-30	1852 499 989	-5.9	0.000 000	-0.003
100%		-20	1852 499 988	-6.5	0.000 000	-0.004
100%		-10	1852 499 988	-6.5	0.000 000	-0.004
100%		0	1852 499 987	-8.1	0.000 000	-0.004
100%		+10	1852 499 989	-5.7	0.000 000	-0.003
100%		+30	1852 499 992	-2.8	0.000 000	-0.002
100%		+40	1852 499 991	-4.1	0.000 000	-0.002
100%		+50	1852 499 990	-4.3	0.000 000	-0.002
Batt. Endpoint	3.300	+20	1852 499 993	-2.1	0.000 000	-0.001



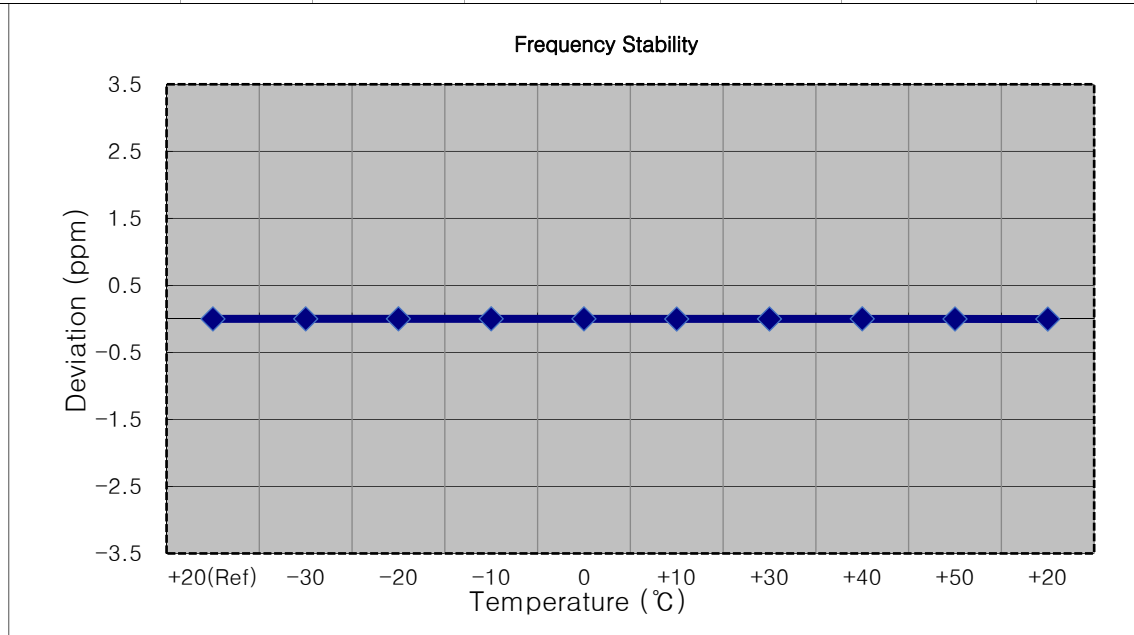
MODE:	<u>LTE B25</u>
OPERATING FREQUENCY:	<u>1855,000,000 Hz</u>
CHANNEL:	<u>26090 (10 MHz)</u>
REFERENCE VOLTAGE:	<u>3.880 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.880	+20(Ref)	1855 000 003	0.0	0.000 000	0.000
100%		-30	1855 000 006	3.0	0.000 000	0.002
100%		-20	1855 000 005	2.1	0.000 000	0.001
100%		-10	1855 000 000	-3.2	0.000 000	-0.002
100%		0	1855 000 001	-2.2	0.000 000	-0.001
100%		+10	1855 000 006	3.2	0.000 000	0.002
100%		+30	1854 999 998	-4.6	0.000 000	-0.002
100%		+40	1855 000 000	-3.3	0.000 000	-0.002
100%		+50	1855 000 000	-2.8	0.000 000	-0.002
Batt. Endpoint	3.300	+20	1855 000 001	-1.7	0.000 000	-0.001



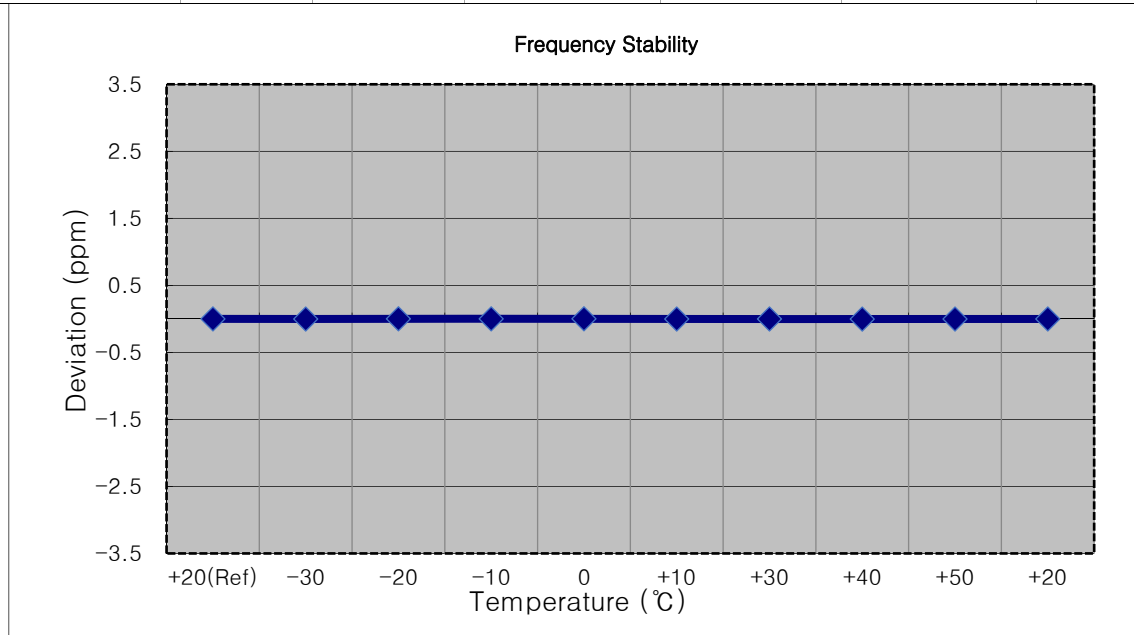
MODE:	<u>LTE B25</u>
OPERATING FREQUENCY:	<u>1857,500,000 Hz</u>
CHANNEL:	<u>26115 (15 MHz)</u>
REFERENCE VOLTAGE:	<u>3.880 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.880	+20(Ref)	1857 500 004	0.0	0.000 000	0.000
100%		-30	1857 500 006	1.5	0.000 000	0.001
100%		-20	1857 500 007	3.1	0.000 000	0.002
100%		-10	1857 500 006	2.2	0.000 000	0.001
100%		0	1857 500 006	1.9	0.000 000	0.001
100%		+10	1857 500 002	-2.5	0.000 000	-0.001
100%		+30	1857 500 002	-1.8	0.000 000	-0.001
100%		+40	1857 500 007	2.5	0.000 000	0.001
100%		+50	1857 500 003	-1.3	0.000 000	-0.001
Batt. Endpoint	3.300	+20	1857 499 999	-5.1	0.000 000	-0.003



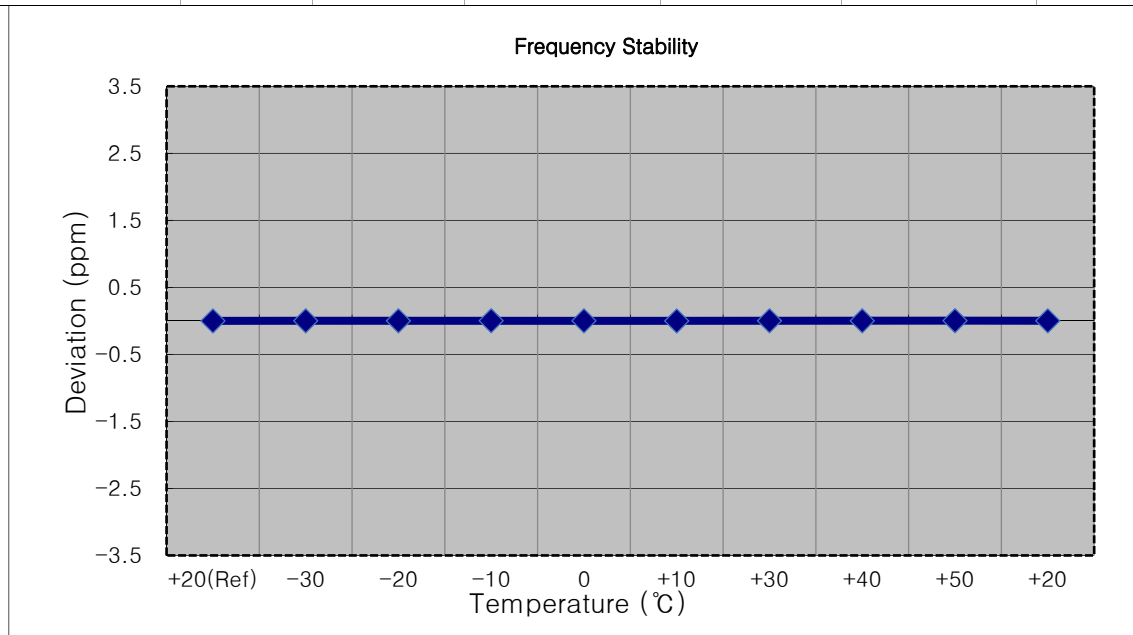
MODE:	<u>LTE B25</u>
OPERATING FREQUENCY:	<u>1860,000,000 Hz</u>
CHANNEL:	<u>26140 (20 MHz)</u>
REFERENCE VOLTAGE:	<u>3.880 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.880	+20(Ref)	1859 999 997	0.0	0.000 000	0.000
100%		-30	1859 999 995	-2.5	0.000 000	-0.001
100%		-20	1860 000 000	2.4	0.000 000	0.001
100%		-10	1859 999 999	1.9	0.000 000	0.001
100%		0	1859 999 999	2.1	0.000 000	0.001
100%		+10	1859 999 994	-2.7	0.000 000	-0.001
100%		+30	1859 999 995	-2.0	0.000 000	-0.001
100%		+40	1859 999 992	-5.0	0.000 000	-0.003
100%		+50	1859 999 994	-2.9	0.000 000	-0.002
Batt. Endpoint	3.300	+20	1859 999 995	-1.8	0.000 000	-0.001



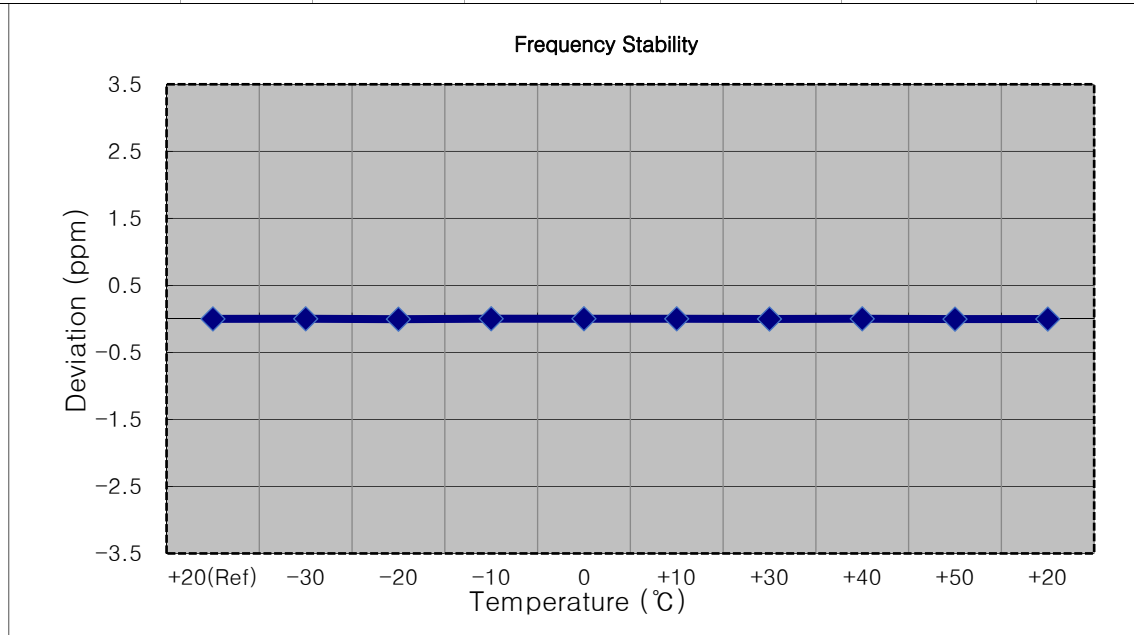
■ MODE:	<u>LTE B25</u>
■ OPERATING FREQUENCY:	<u>1882,500,000 Hz</u>
■ CHANNEL:	<u>26365 (1.4 MHz)</u>
■ REFERENCE VOLTAGE:	<u>3.880 VDC</u>
■ DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.880	+20(Ref)	1882 500 003	0.0	0.000 000	0.000
100%		-30	1882 500 006	3.0	0.000 000	0.002
100%		-20	1882 500 005	2.4	0.000 000	0.001
100%		-10	1882 500 009	6.1	0.000 000	0.003
100%		0	1882 500 006	3.2	0.000 000	0.002
100%		+10	1882 500 001	-2.0	0.000 000	-0.001
100%		+30	1882 500 006	3.8	0.000 000	0.002
100%		+40	1882 500 006	3.2	0.000 000	0.002
100%		+50	1882 500 009	6.4	0.000 000	0.003
Batt. Endpoint	3.300	+20	1882 500 006	3.4	0.000 000	0.002



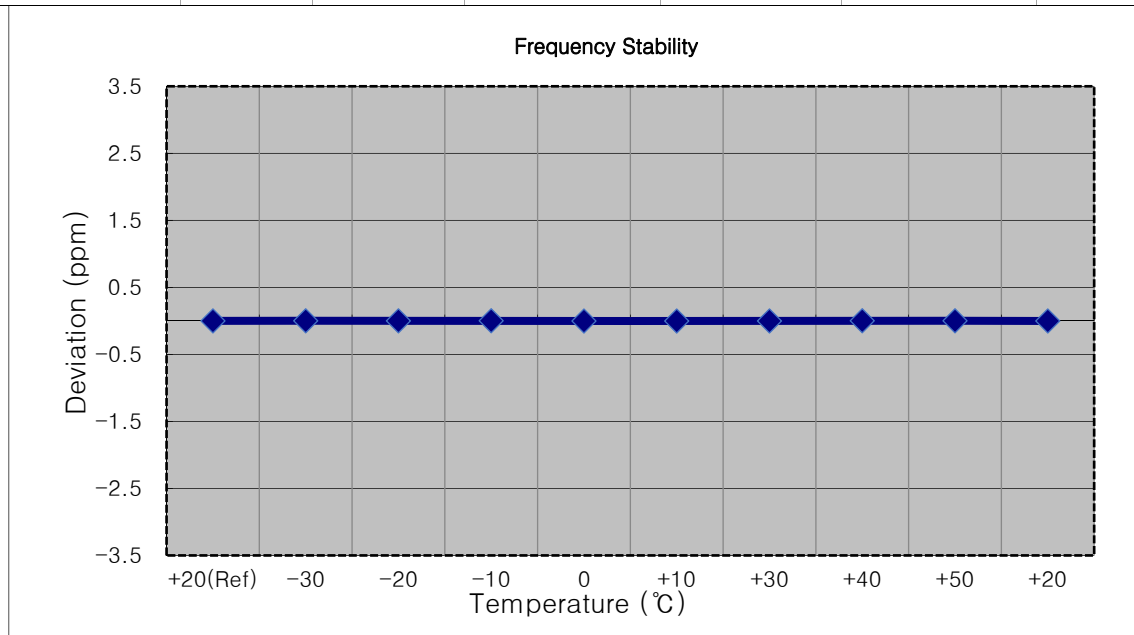
■ MODE:	<u>LTE B25</u>
■ OPERATING FREQUENCY:	<u>1882,500,000 Hz</u>
■ CHANNEL:	<u>26365 (3 MHz)</u>
■ REFERENCE VOLTAGE:	<u>3.880 VDC</u>
■ DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.880	+20(Ref)	1882 499 996	0.0	0.000 000	0.000
100%		-30	1882 500 000	3.5	0.000 000	0.002
100%		-20	1882 499 989	-7.9	0.000 000	-0.004
100%		-10	1882 500 001	4.8	0.000 000	0.003
100%		0	1882 500 000	3.6	0.000 000	0.002
100%		+10	1882 500 000	3.1	0.000 000	0.002
100%		+30	1882 499 993	-3.2	0.000 000	-0.002
100%		+40	1882 500 000	3.1	0.000 000	0.002
100%		+50	1882 499 990	-6.2	0.000 000	-0.003
Batt. Endpoint	3.300	+20	1882 499 992	-4.2	0.000 000	-0.002



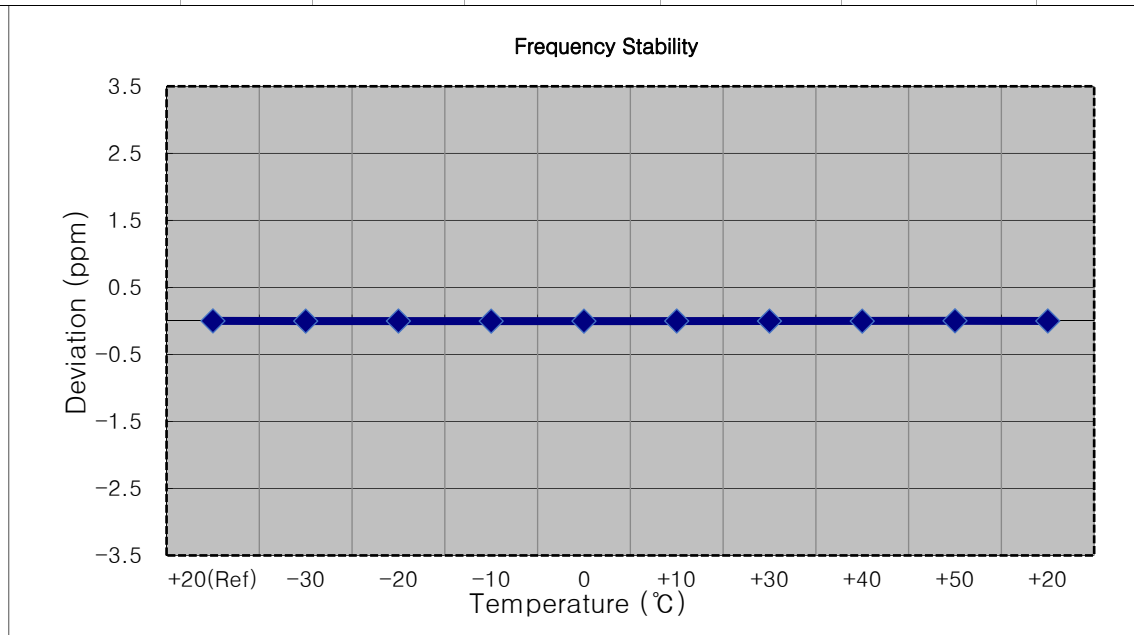
MODE:	<u>LTE B25</u>
OPERATING FREQUENCY:	<u>1882,500,000 Hz</u>
CHANNEL:	<u>26365 (5 MHz)</u>
REFERENCE VOLTAGE:	<u>3.880 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.880	+20(Ref)	1882 499 997	0.0	0.000 000	0.000
100%		-30	1882 500 000	2.9	0.000 000	0.002
100%		-20	1882 499 999	2.0	0.000 000	0.001
100%		-10	1882 500 001	4.1	0.000 000	0.002
100%		0	1882 499 994	-2.6	0.000 000	-0.001
100%		+10	1882 499 993	-3.6	0.000 000	-0.002
100%		+30	1882 499 995	-2.2	0.000 000	-0.001
100%		+40	1882 500 001	3.9	0.000 000	0.002
100%		+50	1882 500 000	2.8	0.000 000	0.001
Batt. Endpoint	3.300	+20	1882 499 995	-2.4	0.000 000	-0.001



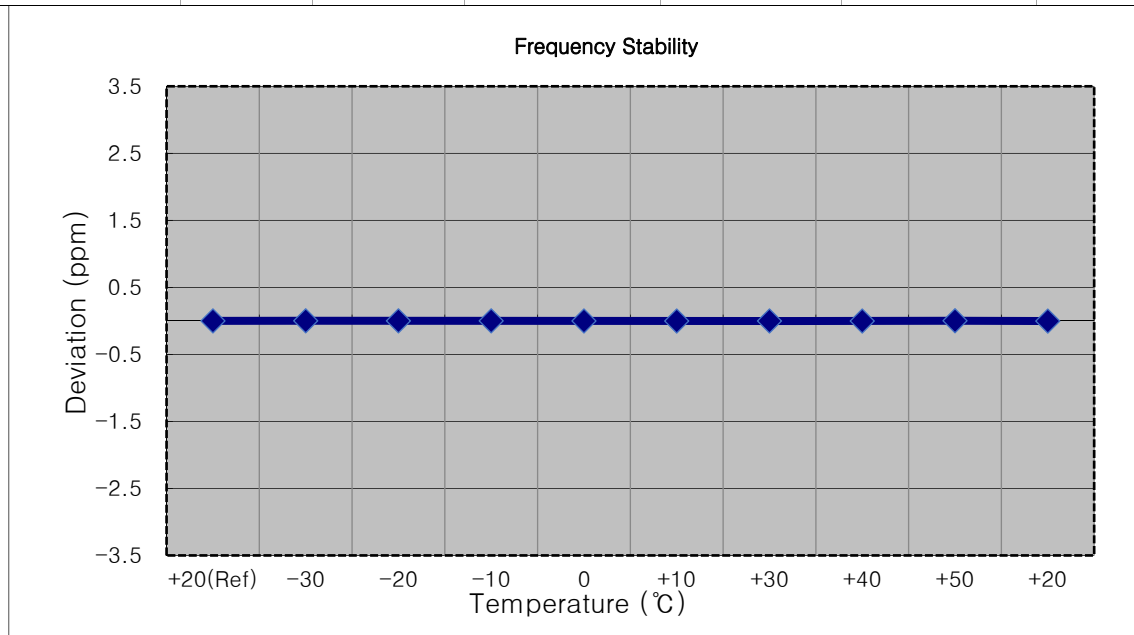
MODE:	<u>LTE B25</u>
OPERATING FREQUENCY:	<u>1882,500,000 Hz</u>
CHANNEL:	<u>26365 (10 MHz)</u>
REFERENCE VOLTAGE:	<u>3.880 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.880	+20(Ref)	1882 499 998	0.0	0.000 000	0.000
100%		-30	1882 499 993	-5.1	0.000 000	-0.003
100%		-20	1882 499 994	-3.7	0.000 000	-0.002
100%		-10	1882 499 991	-6.7	0.000 000	-0.004
100%		0	1882 499 992	-5.6	0.000 000	-0.003
100%		+10	1882 499 995	-2.8	0.000 000	-0.001
100%		+30	1882 499 993	-4.6	0.000 000	-0.002
100%		+40	1882 499 991	-6.7	0.000 000	-0.004
100%		+50	1882 500 000	2.6	0.000 000	0.001
Batt. Endpoint	3.300	+20	1882 499 995	-2.3	0.000 000	-0.001



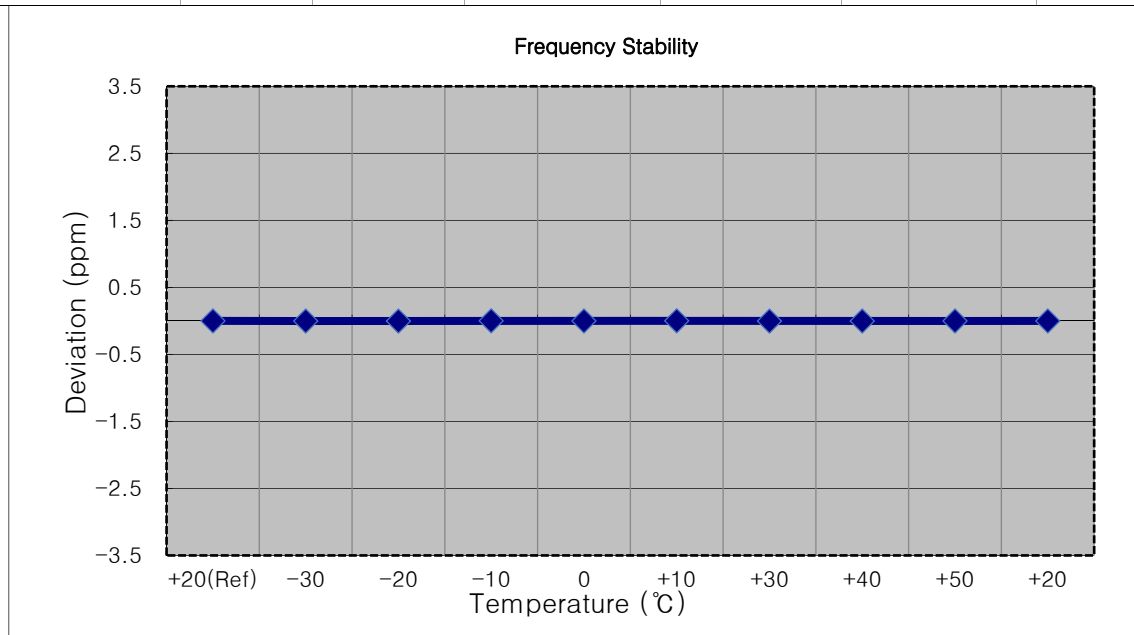
MODE:	<u>LTE B25</u>
OPERATING FREQUENCY:	<u>1882,500,000 Hz</u>
CHANNEL:	<u>26365 (15 MHz)</u>
REFERENCE VOLTAGE:	<u>3.880 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.880	+20(Ref)	1882 500 002	0.0	0.000 000	0.000
100%		-30	1882 500 004	2.8	0.000 000	0.001
100%		-20	1882 500 004	2.0	0.000 000	0.001
100%		-10	1882 500 003	1.4	0.000 000	0.001
100%		0	1882 499 999	-2.2	0.000 000	-0.001
100%		+10	1882 499 999	-2.7	0.000 000	-0.001
100%		+30	1882 500 000	-1.6	0.000 000	-0.001
100%		+40	1882 499 998	-3.5	0.000 000	-0.002
100%		+50	1882 500 006	4.2	0.000 000	0.002
Batt. Endpoint	3.300	+20	1882 499 997	-4.2	0.000 000	-0.002



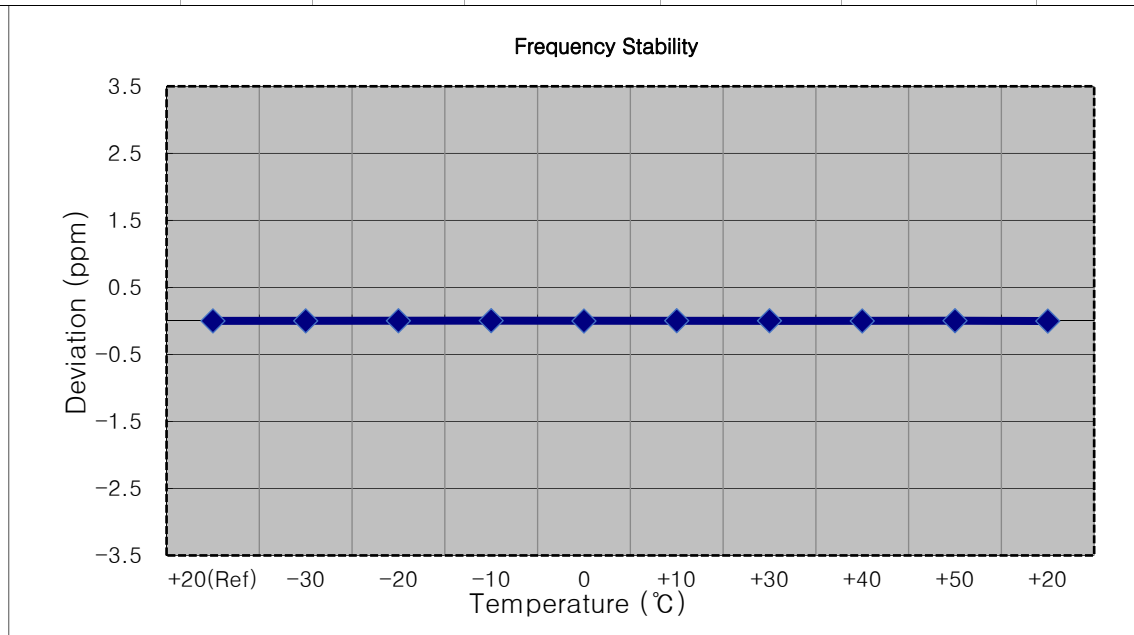
■ MODE:	<u>LTE B25</u>
■ OPERATING FREQUENCY:	<u>1882,500,000 Hz</u>
■ CHANNEL:	<u>26365 (20 MHz)</u>
■ REFERENCE VOLTAGE:	<u>3.880 VDC</u>
■ DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.880	+20(Ref)	1882 499 997	0.0	0.000 000	0.000
100%		-30	1882 499 994	-3.8	0.000 000	-0.002
100%		-20	1882 499 993	-4.4	0.000 000	-0.002
100%		-10	1882 500 001	3.4	0.000 000	0.002
100%		0	1882 499 995	-2.3	0.000 000	-0.001
100%		+10	1882 500 001	3.4	0.000 000	0.002
100%		+30	1882 499 993	-4.2	0.000 000	-0.002
100%		+40	1882 499 994	-3.7	0.000 000	-0.002
100%		+50	1882 499 995	-2.1	0.000 000	-0.001
Batt. Endpoint	3.300	+20	1882 499 996	-1.6	0.000 000	-0.001



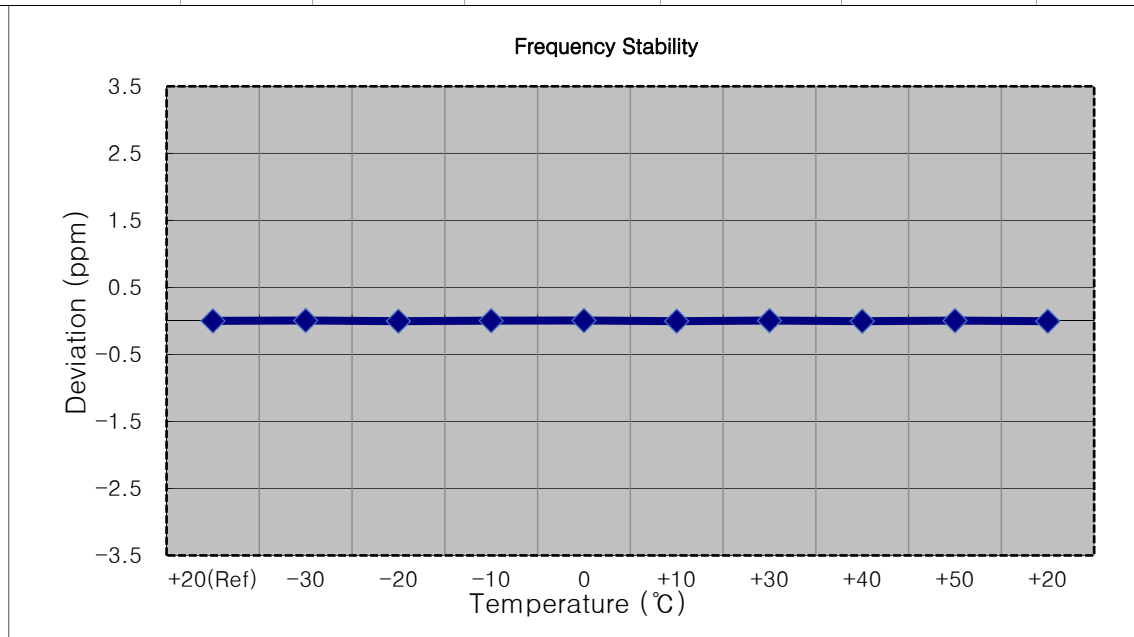
■ MODE:	<u>LTE B25</u>
■ OPERATING FREQUENCY:	<u>1914,300,000 Hz</u>
■ CHANNEL:	<u>26683 (1.4 MHz)</u>
■ REFERENCE VOLTAGE:	<u>3.880 VDC</u>
■ DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.880	+20(Ref)	1914 300 004	0.0	0.000 000	0.000
100%		-30	1914 300 006	1.7	0.000 000	0.001
100%		-20	1914 300 008	4.5	0.000 000	0.002
100%		-10	1914 300 011	7.5	0.000 000	0.004
100%		0	1914 300 001	-2.8	0.000 000	-0.001
100%		+10	1914 300 010	6.0	0.000 000	0.003
100%		+30	1914 300 008	3.7	0.000 000	0.002
100%		+40	1914 300 002	-2.3	0.000 000	-0.001
100%		+50	1914 300 010	5.8	0.000 000	0.003
Batt. Endpoint	3.300	+20	1914 300 000	-4.4	0.000 000	-0.002



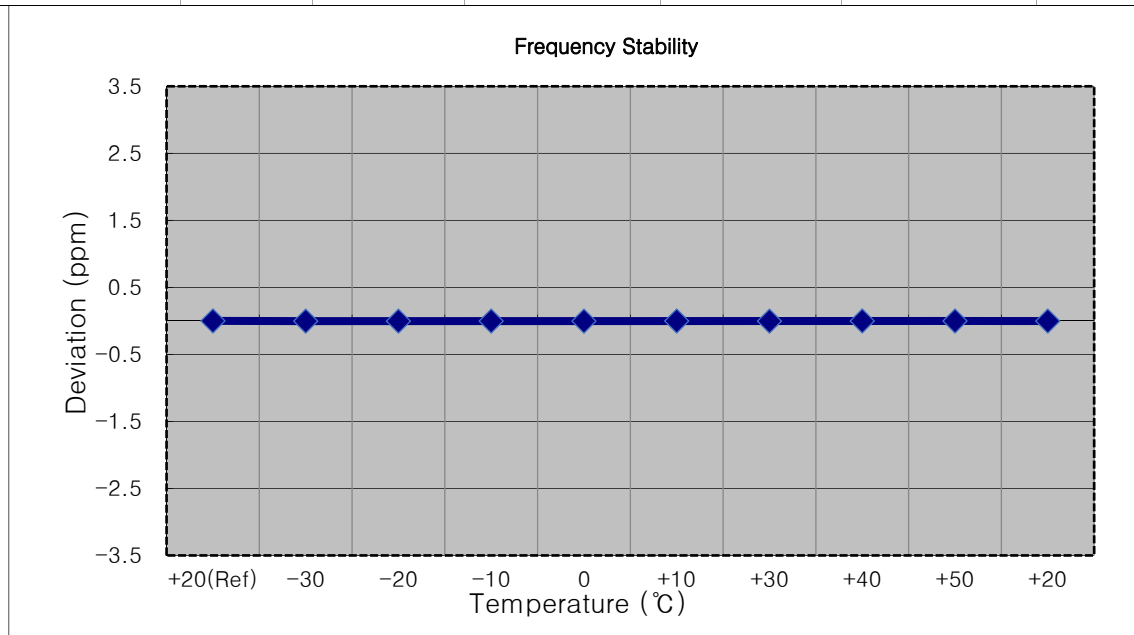
■ MODE:	<u>LTE B25</u>
■ OPERATING FREQUENCY:	<u>1913,500,000 Hz</u>
■ CHANNEL:	<u>26675 (3 MHz)</u>
■ REFERENCE VOLTAGE:	<u>3.880 VDC</u>
■ DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.880	+20(Ref)	1913 500 011	0.0	0.000 000	0.000
100%		-30	1913 500 022	10.9	0.000 001	0.006
100%		-20	1913 500 002	-8.7	0.000 000	-0.005
100%		-10	1913 500 017	6.4	0.000 000	0.003
100%		0	1913 500 022	10.6	0.000 001	0.006
100%		+10	1913 500 002	-9.1	0.000 000	-0.005
100%		+30	1913 500 021	9.5	0.000 000	0.005
100%		+40	1913 500 002	-9.0	0.000 000	-0.005
100%		+50	1913 500 019	7.6	0.000 000	0.004
Batt. Endpoint	3.300	+20	1913 500 002	-9.3	0.000 000	-0.005



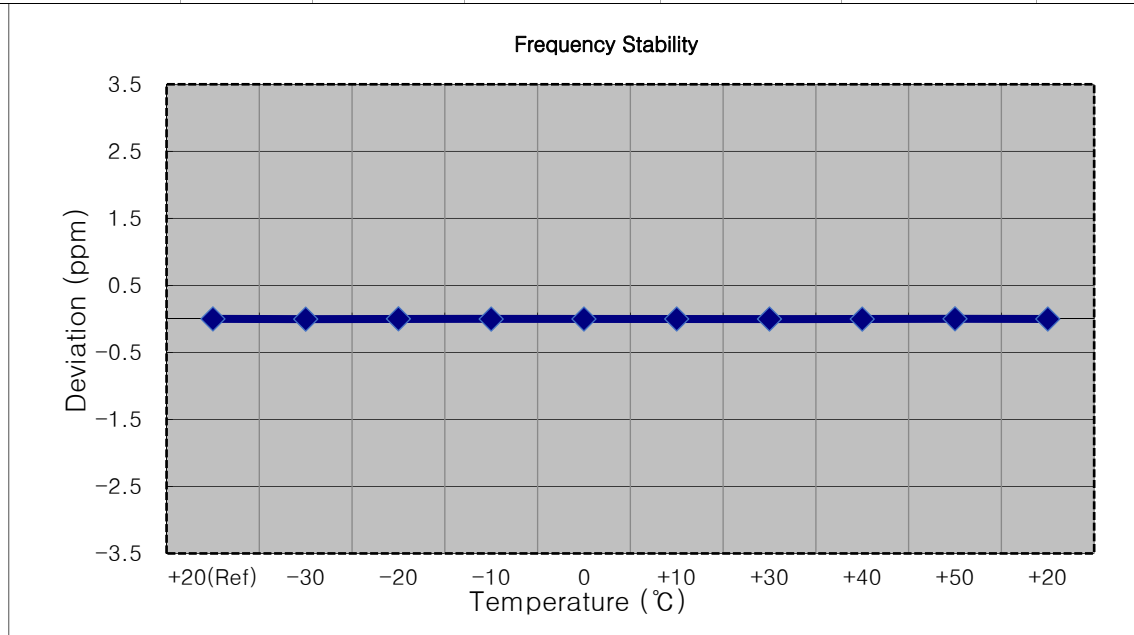
MODE:	<u>LTE B25</u>
OPERATING FREQUENCY:	<u>1912,500,000 Hz</u>
CHANNEL:	<u>26665 (5 MHz)</u>
REFERENCE VOLTAGE:	<u>3.880 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.880	+20(Ref)	1912 499 996	0.0	0.000 000	0.000
100%		-30	1912 499 989	-6.7	0.000 000	-0.004
100%		-20	1912 499 989	-6.7	0.000 000	-0.004
100%		-10	1912 499 990	-5.1	0.000 000	-0.003
100%		0	1912 499 989	-6.6	0.000 000	-0.003
100%		+10	1912 499 992	-3.5	0.000 000	-0.002
100%		+30	1912 499 990	-5.6	0.000 000	-0.003
100%		+40	1912 499 993	-2.4	0.000 000	-0.001
100%		+50	1912 499 993	-2.7	0.000 000	-0.001
Batt. Endpoint	3.300	+20	1912 499 990	-5.3	0.000 000	-0.003



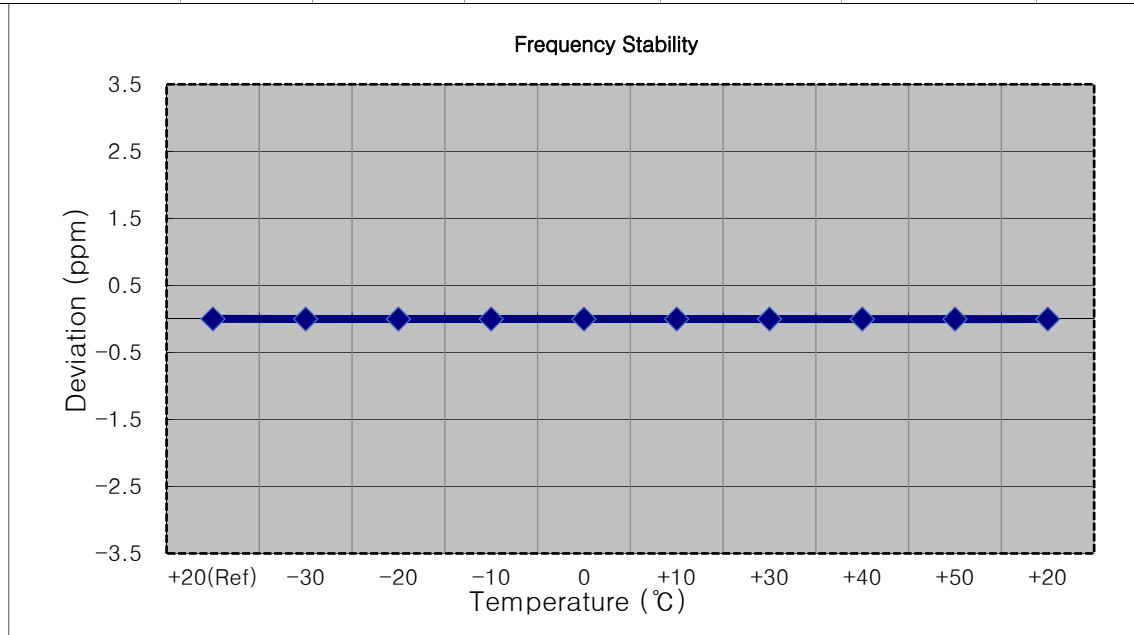
■ MODE:	<u>LTE B25</u>
■ OPERATING FREQUENCY:	<u>1910,000,000 Hz</u>
■ CHANNEL:	<u>26640 (10 MHz)</u>
■ REFERENCE VOLTAGE:	<u>3.880 VDC</u>
■ DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.880	+20(Ref)	1909 999 996	0.0	0.000 000	0.000
100%		-30	1909 999 989	-6.7	0.000 000	-0.004
100%		-20	1909 999 998	2.4	0.000 000	0.001
100%		-10	1909 999 992	-4.2	0.000 000	-0.002
100%		0	1909 999 993	-2.9	0.000 000	-0.002
100%		+10	1909 999 993	-2.4	0.000 000	-0.001
100%		+30	1909 999 992	-4.0	0.000 000	-0.002
100%		+40	1909 999 992	-4.1	0.000 000	-0.002
100%		+50	1909 999 998	2.1	0.000 000	0.001
Batt. Endpoint	3.300	+20	1909 999 993	-3.0	0.000 000	-0.002



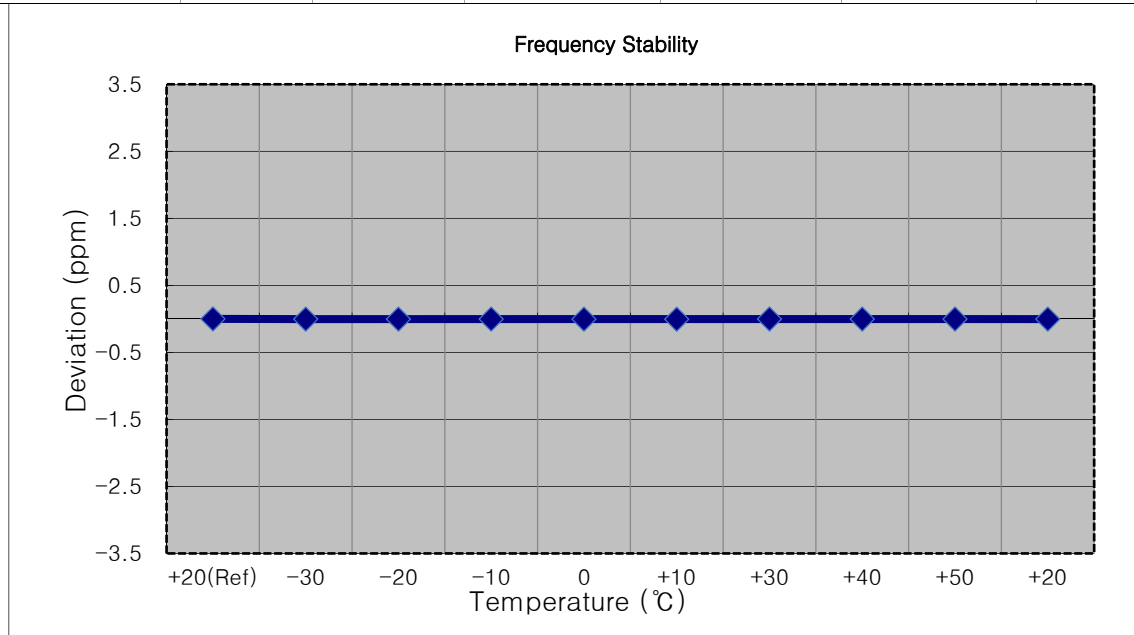
■ MODE:	<u>LTE B25</u>
■ OPERATING FREQUENCY:	<u>1907,500,000 Hz</u>
■ CHANNEL:	<u>26615 (15 MHz)</u>
■ REFERENCE VOLTAGE:	<u>3.880 VDC</u>
■ DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.880	+20(Ref)	1907 499 997	0.0	0.000 000	0.000
100%		-30	1907 499 992	-4.6	0.000 000	-0.002
100%		-20	1907 499 993	-4.3	0.000 000	-0.002
100%		-10	1907 499 994	-2.7	0.000 000	-0.001
100%		0	1907 499 992	-5.1	0.000 000	-0.003
100%		+10	1907 499 994	-3.4	0.000 000	-0.002
100%		+30	1907 499 994	-2.9	0.000 000	-0.002
100%		+40	1907 499 991	-5.5	0.000 000	-0.003
100%		+50	1907 499 990	-6.5	0.000 000	-0.003
Batt. Endpoint	3.300	+20	1907 499 993	-4.4	0.000 000	-0.002



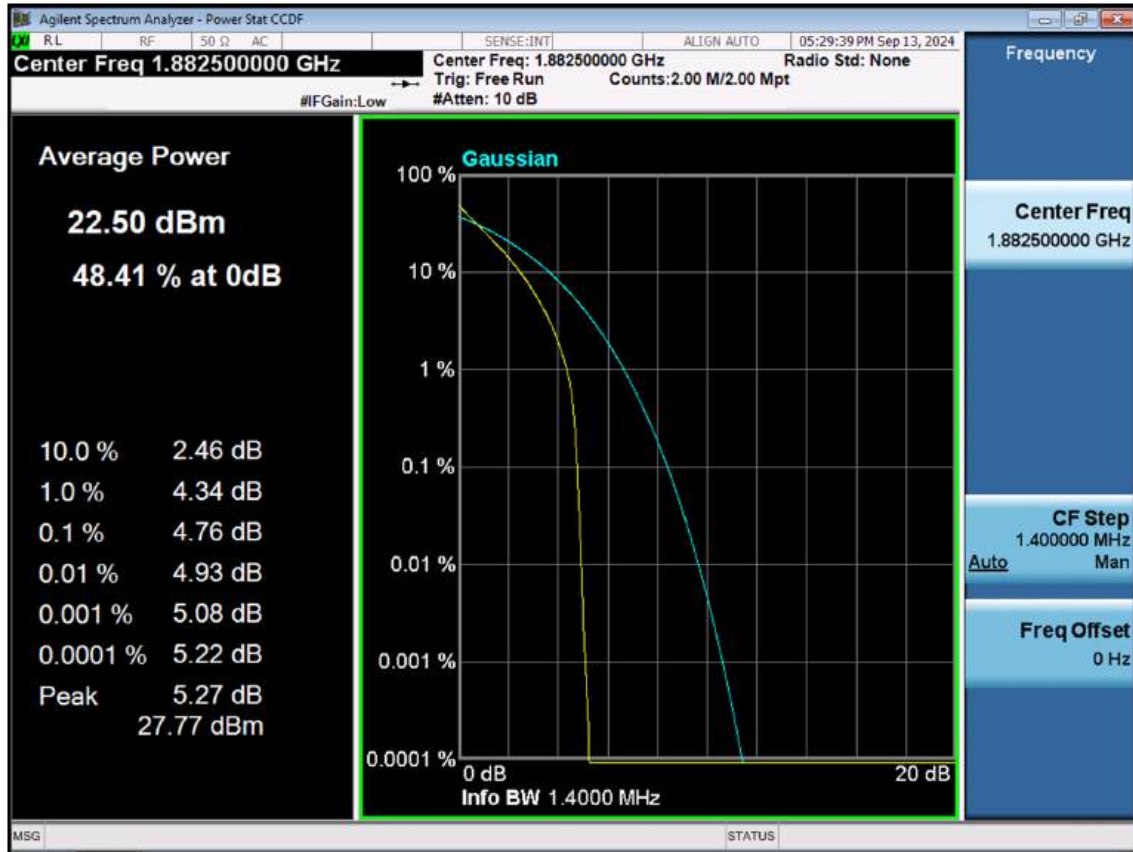
MODE:	<u>LTE B25</u>
OPERATING FREQUENCY:	<u>1905,000,000 Hz</u>
CHANNEL:	<u>26590 (20 MHz)</u>
REFERENCE VOLTAGE:	<u>3.880 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100%	3.880	+20(Ref)	1904 999 995	0.0	0.000 000	0.000
100%		-30	1904 999 988	-6.5	0.000 000	-0.003
100%		-20	1904 999 989	-6.2	0.000 000	-0.003
100%		-10	1904 999 990	-5.0	0.000 000	-0.003
100%		0	1904 999 987	-7.7	0.000 000	-0.004
100%		+10	1904 999 986	-8.6	0.000 000	-0.005
100%		+30	1904 999 992	-3.0	0.000 000	-0.002
100%		+40	1904 999 991	-4.3	0.000 000	-0.002
100%		+50	1904 999 990	-5.0	0.000 000	-0.003
Batt. Endpoint	3.300	+20	1904 999 988	-6.6	0.000 000	-0.003

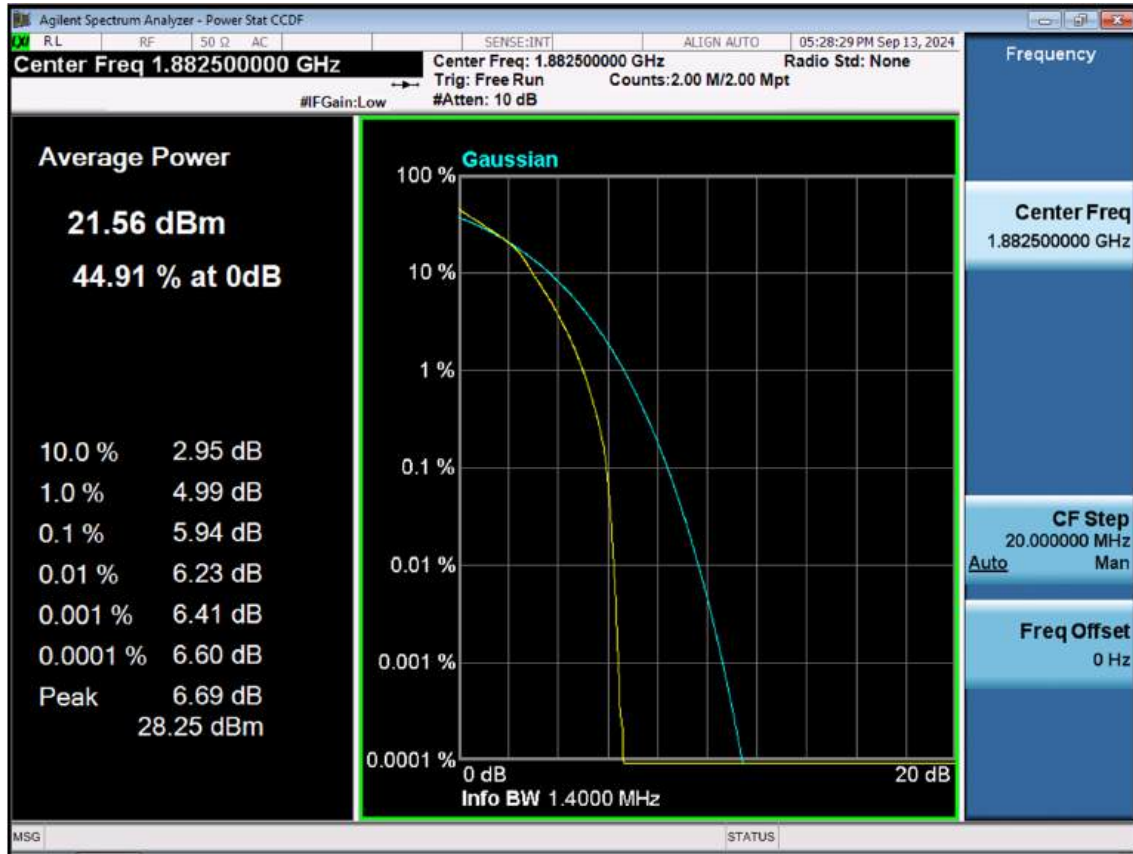


10. TEST PLOTS(Main1)

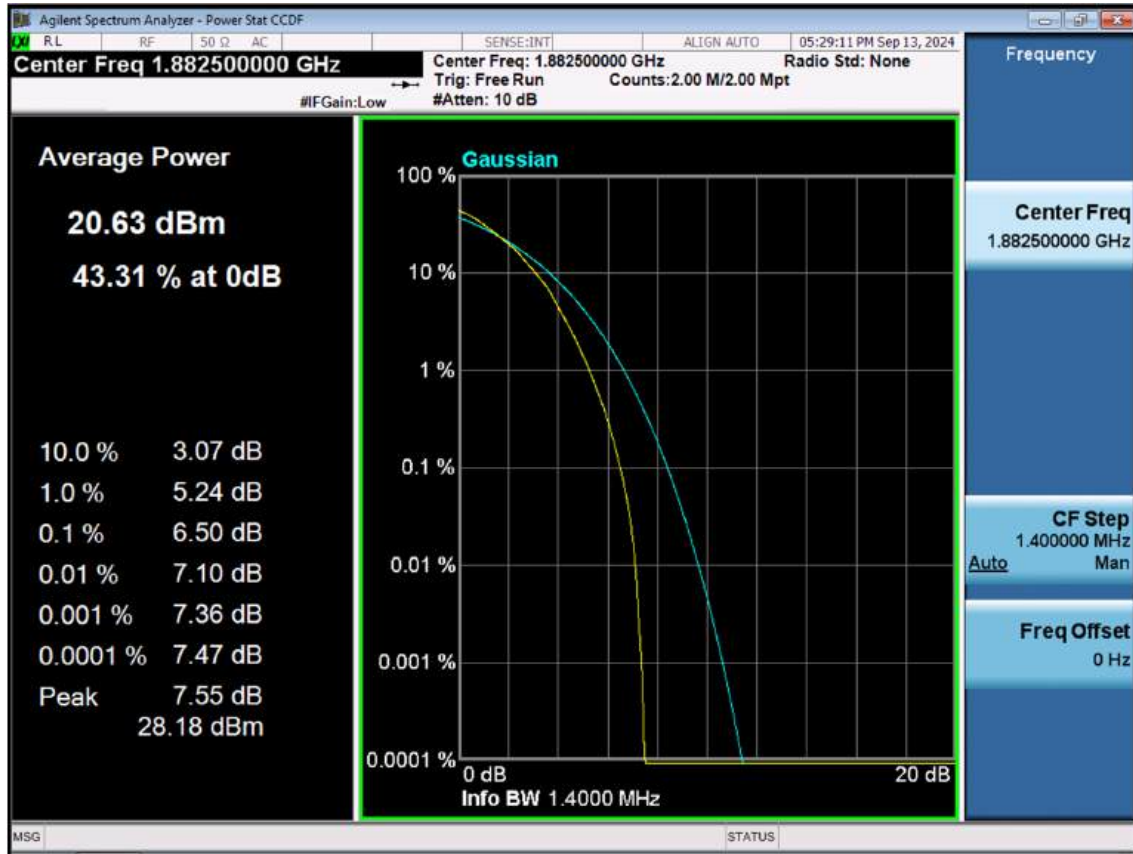
LTE B25_1.4M_PAR_Mid_QPSK_FullRB



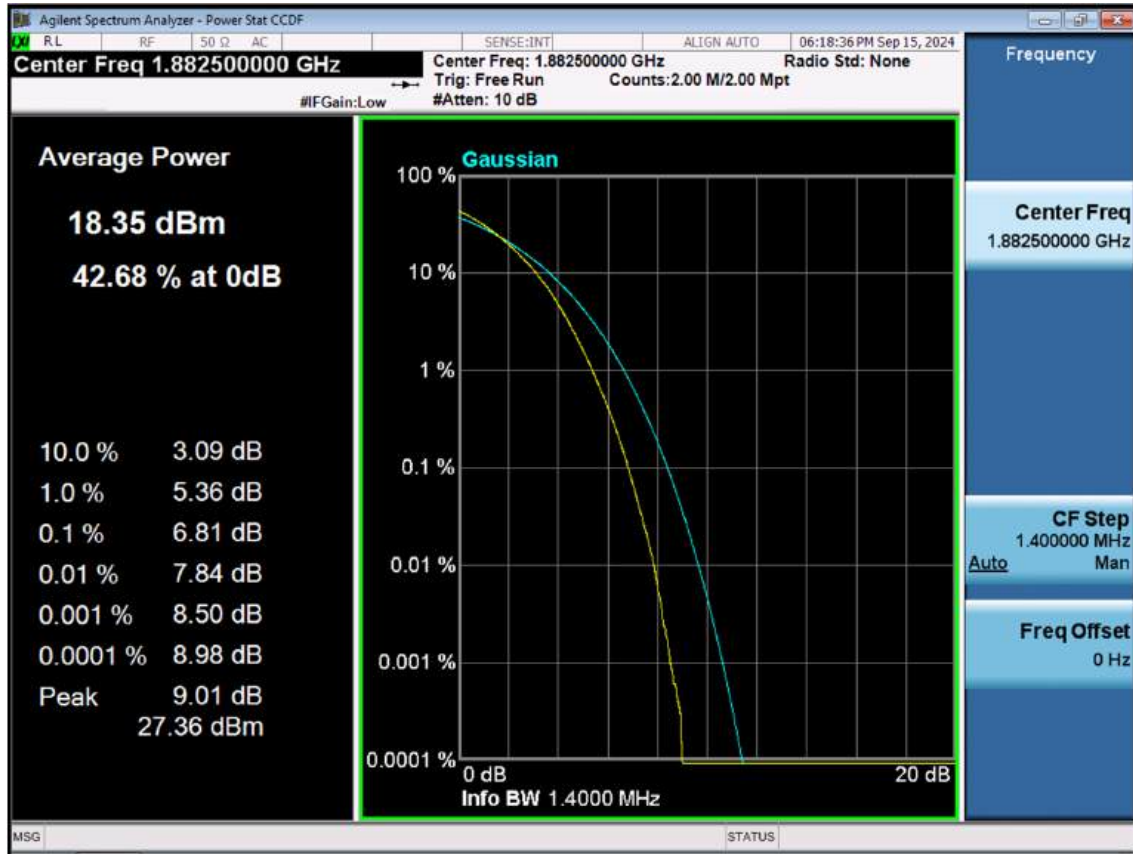
LTE B25_1.4M_PAR_Mid_16QAM_FullRB



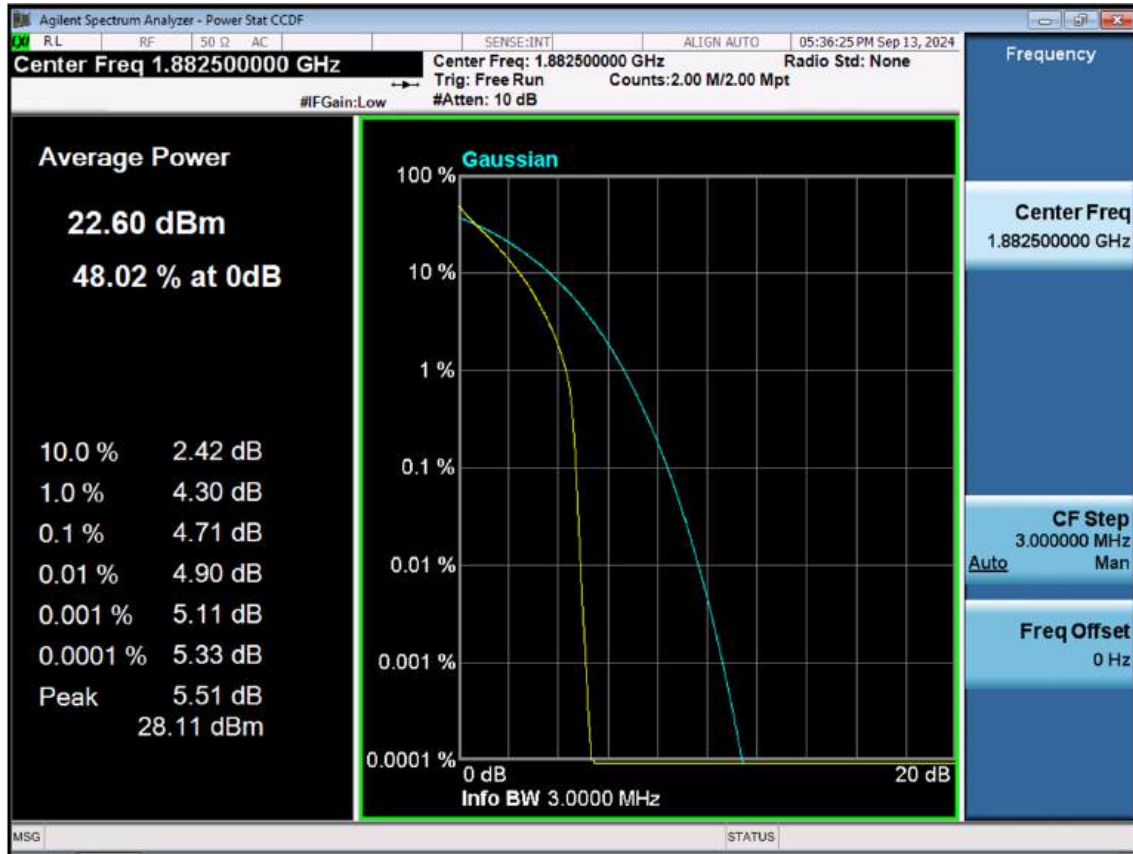
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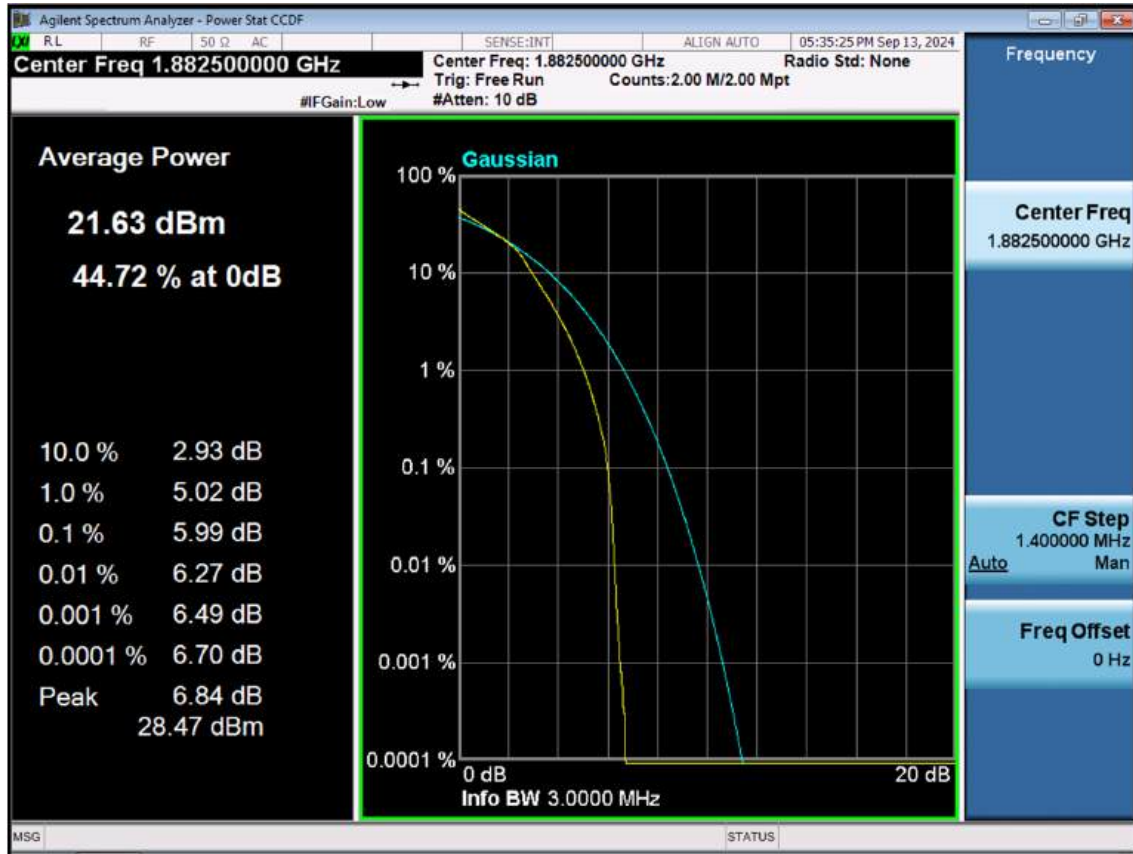
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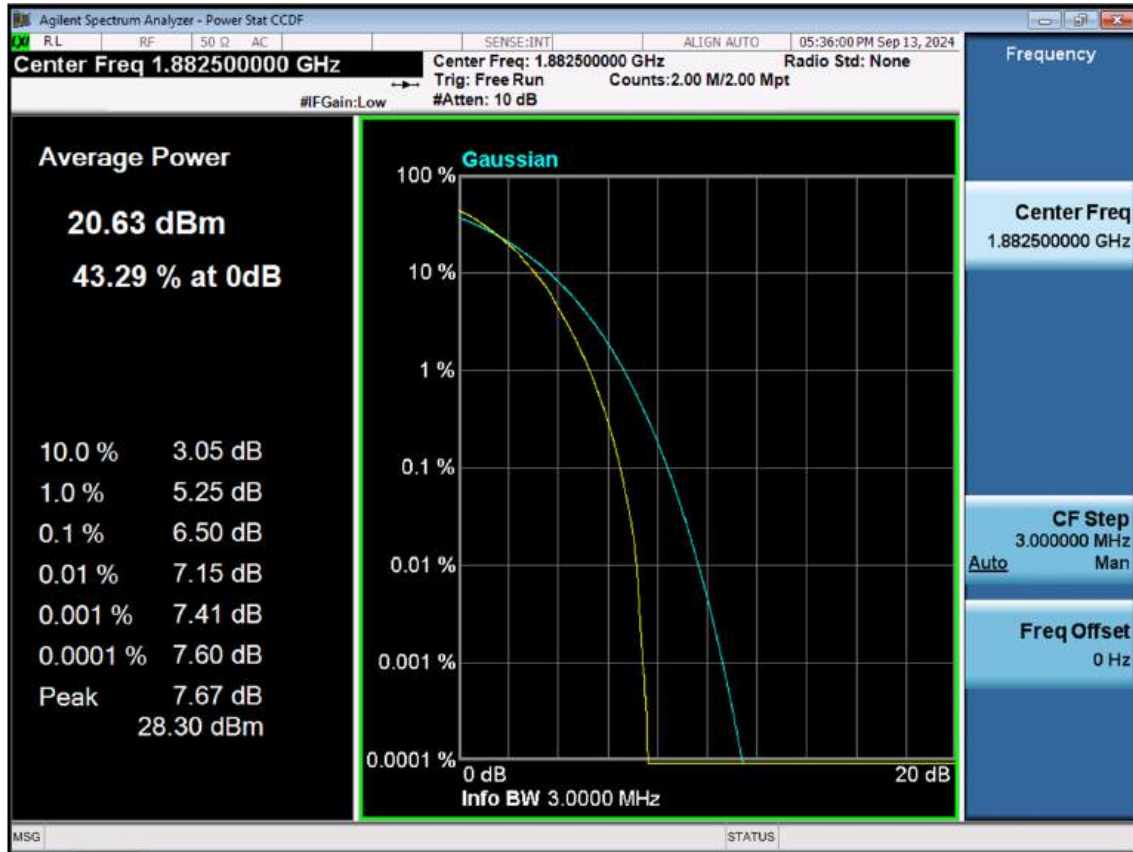
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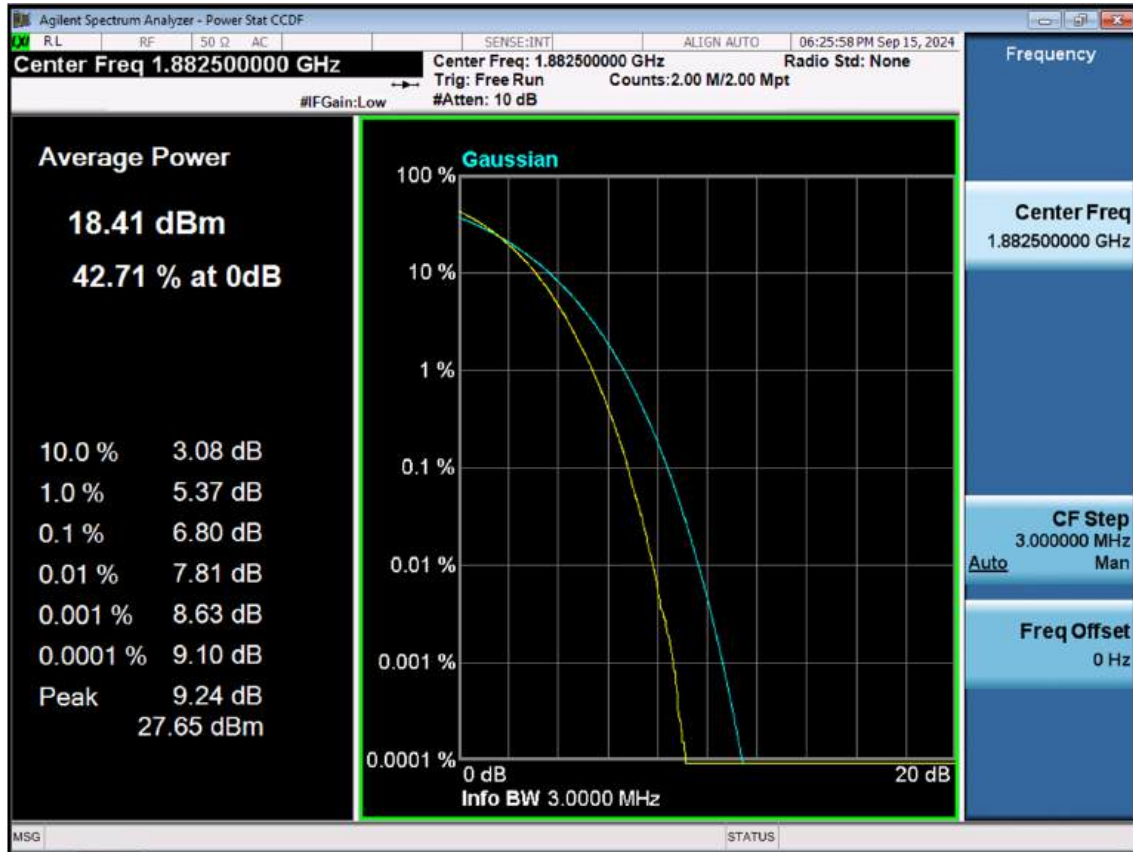
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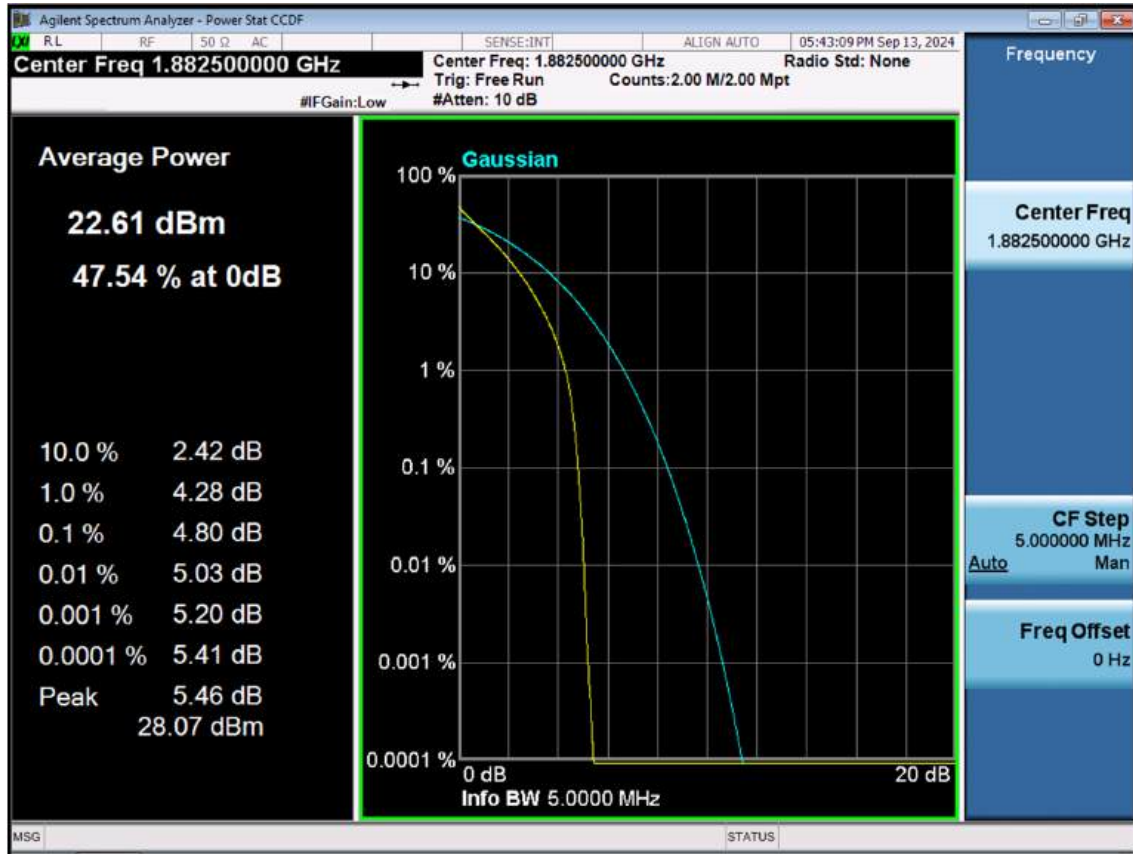
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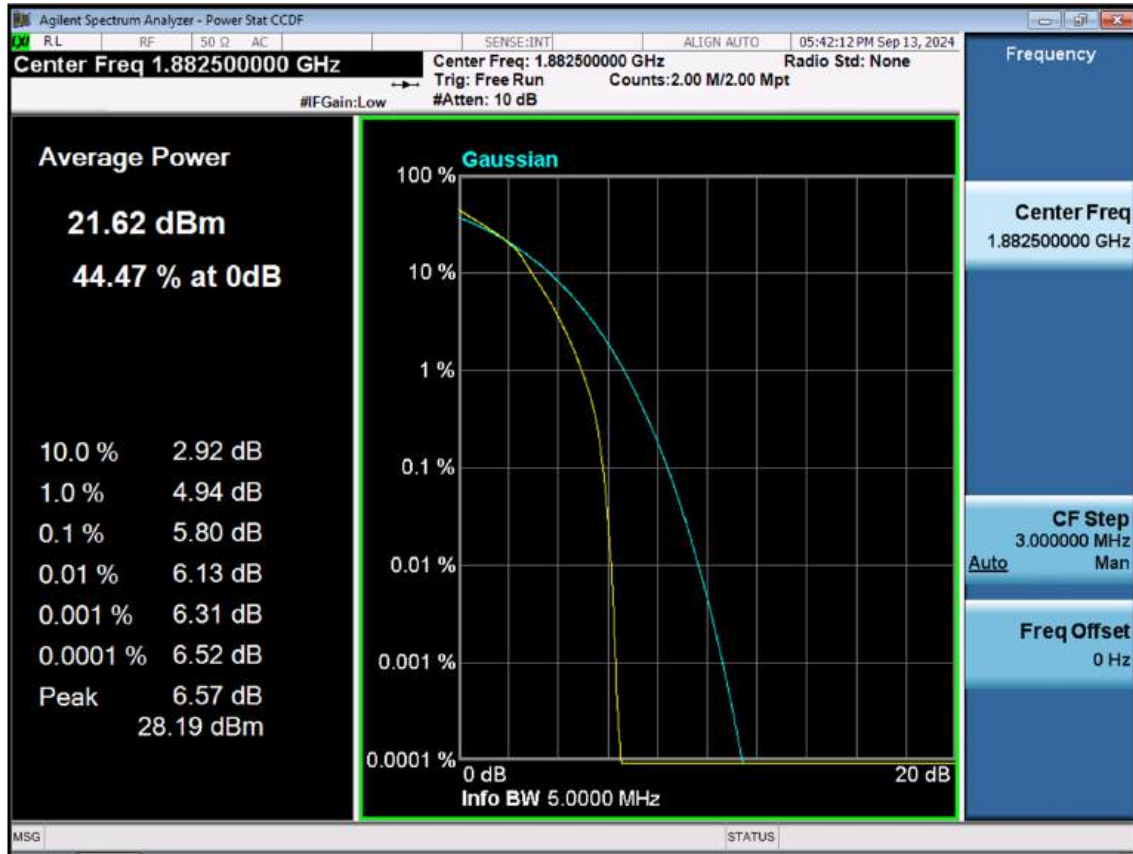
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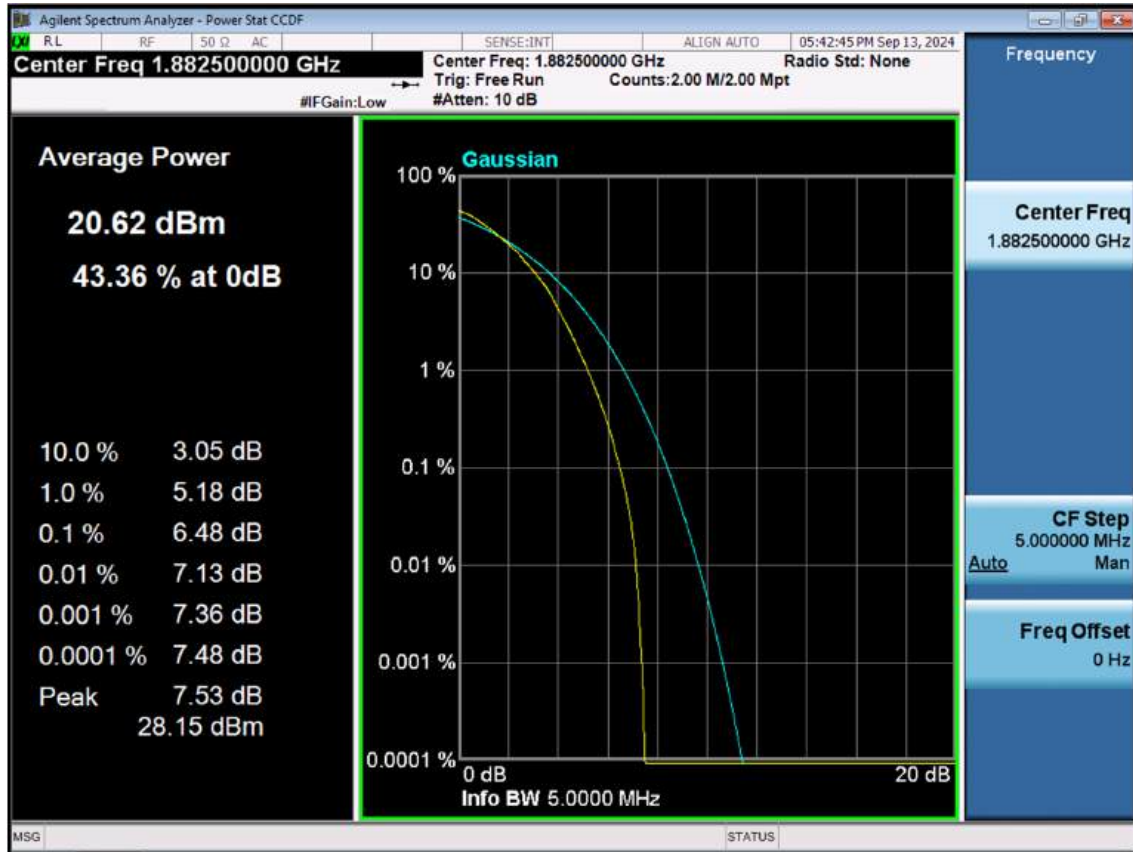
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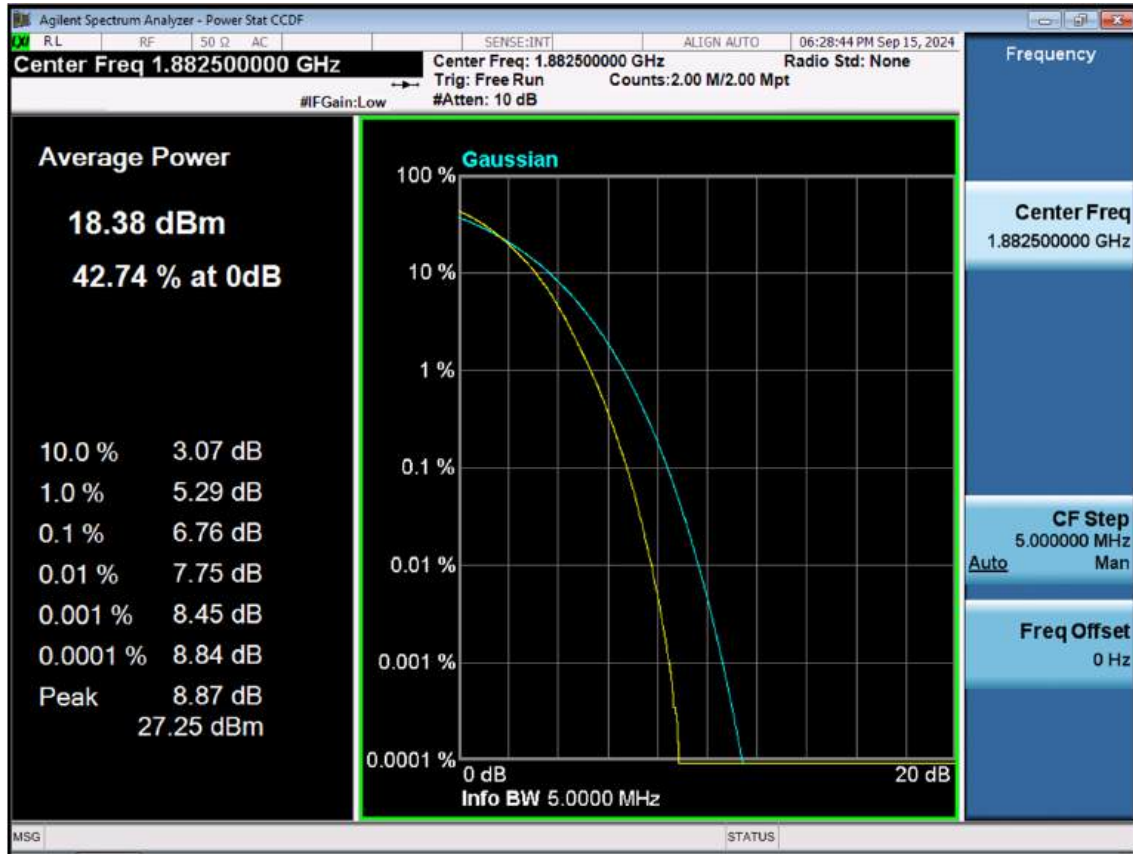
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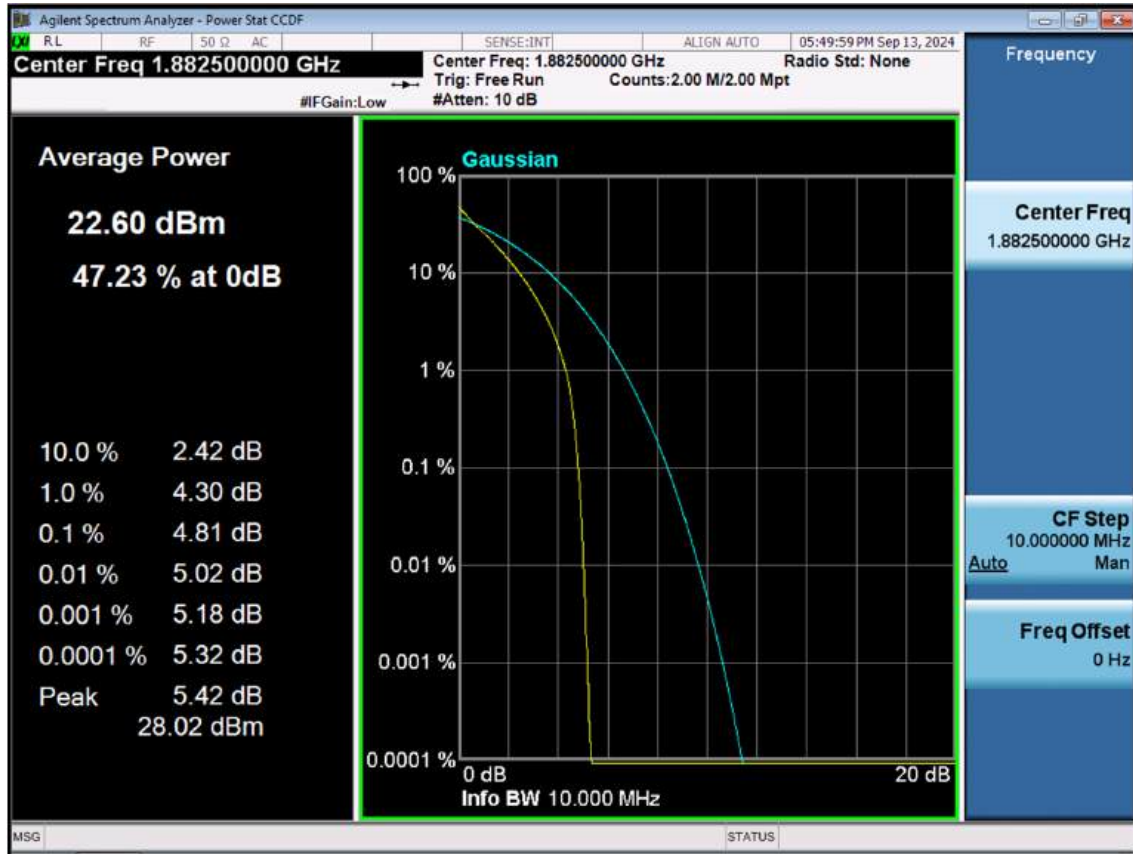
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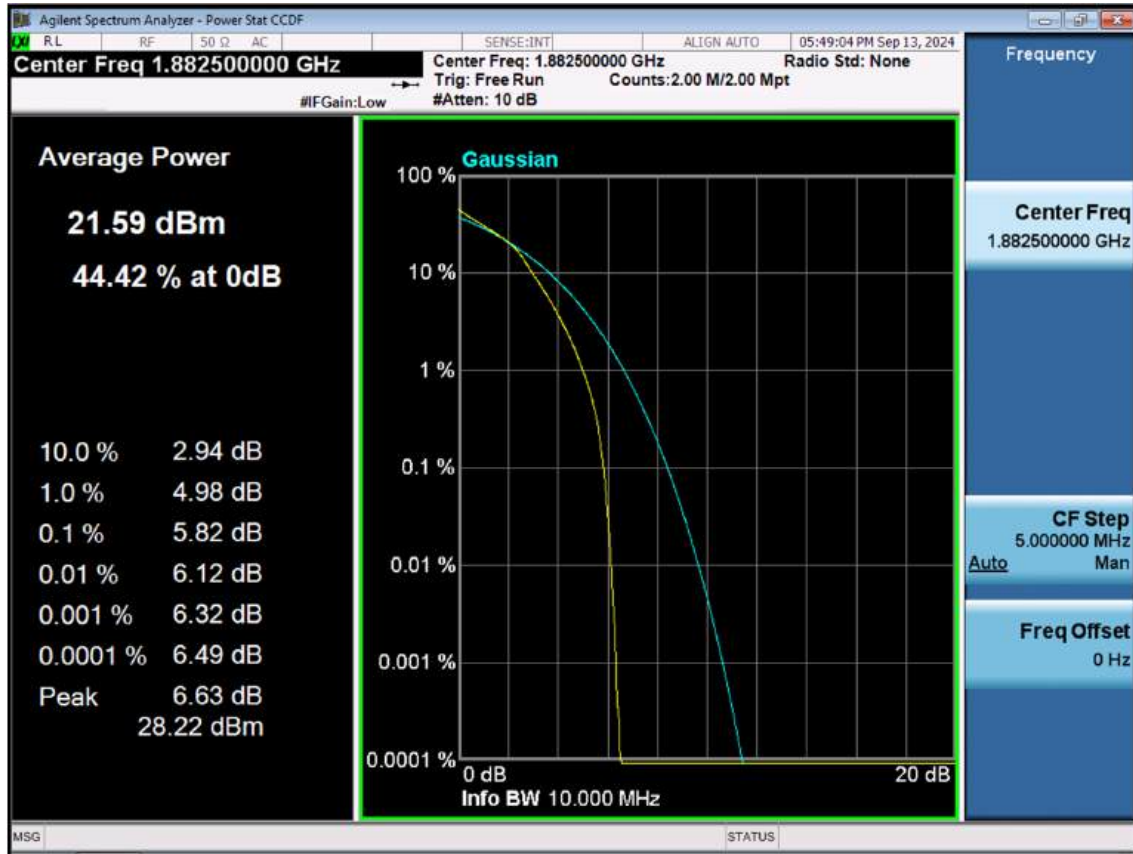
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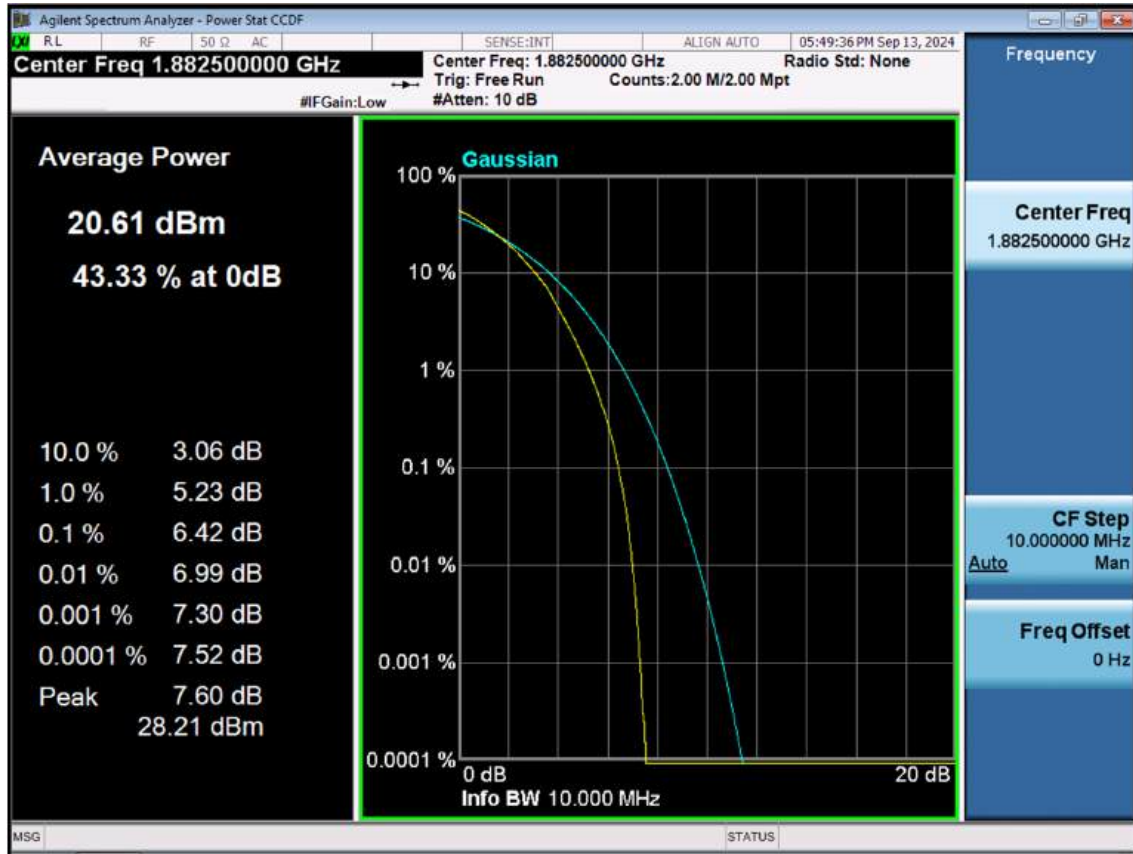
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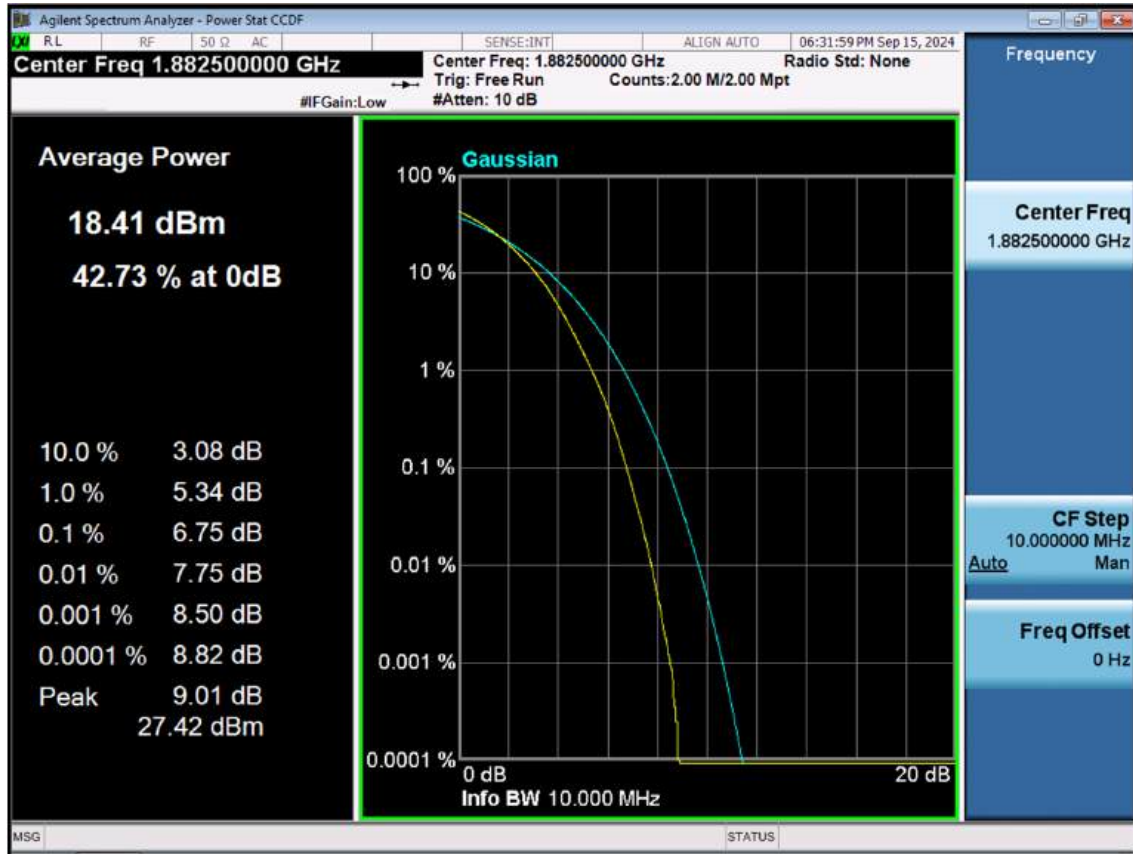
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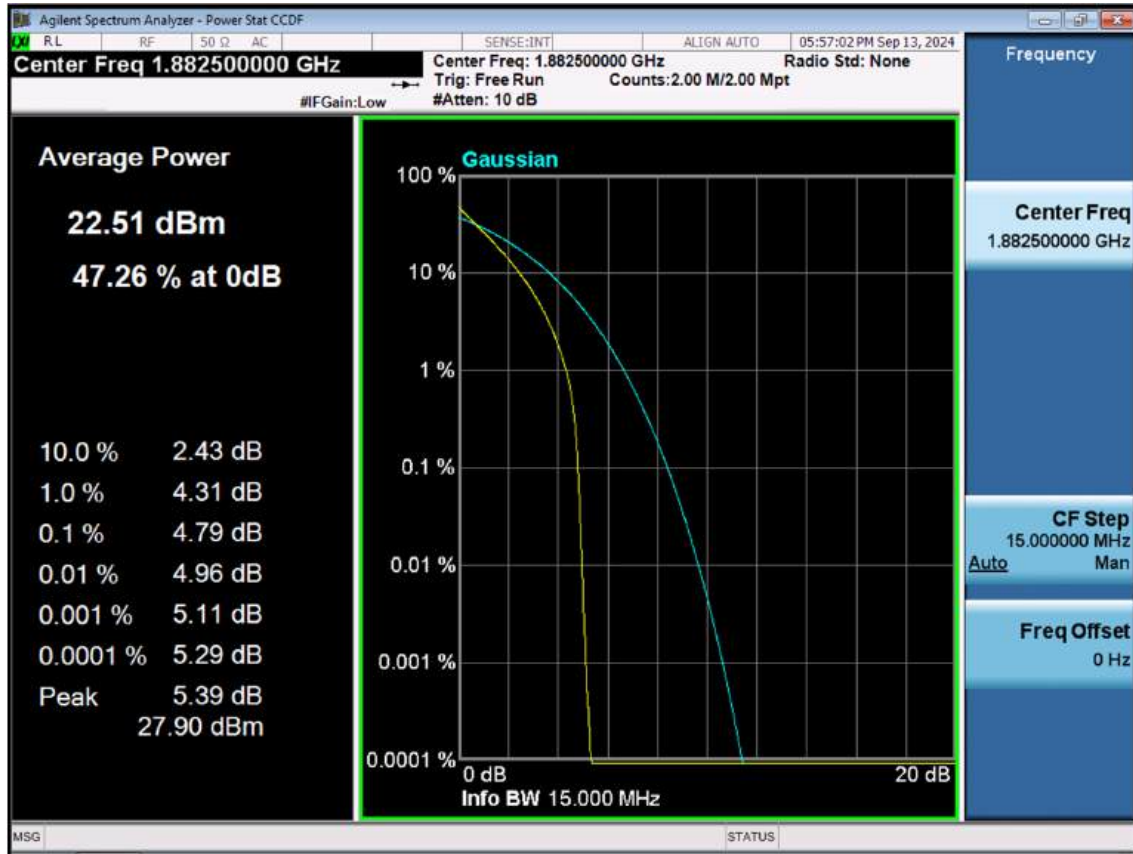
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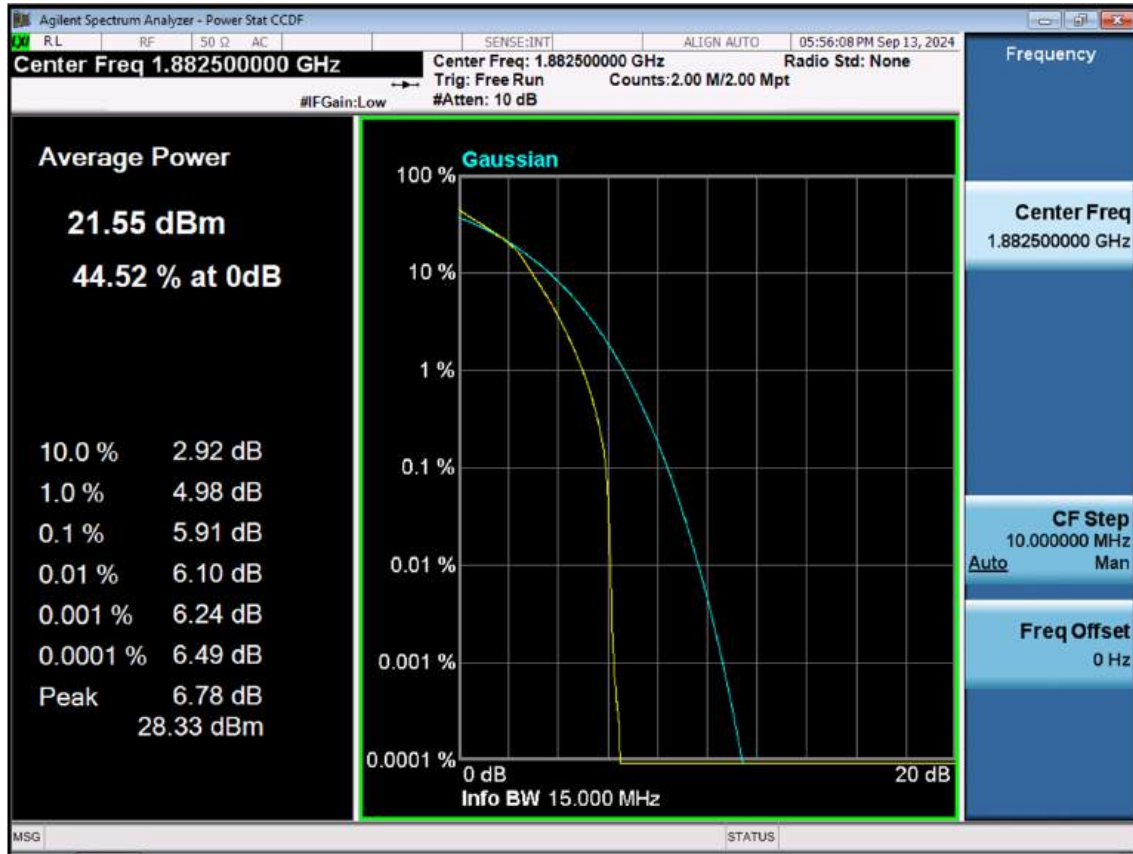
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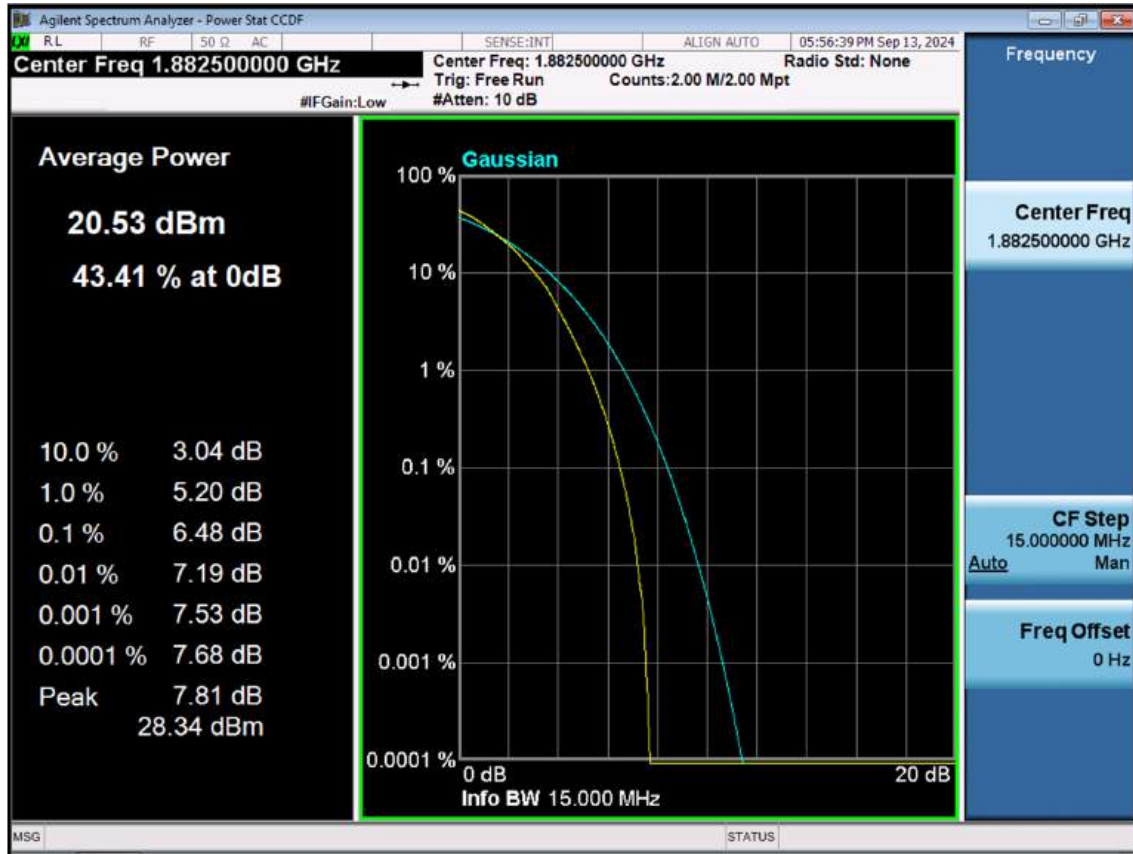
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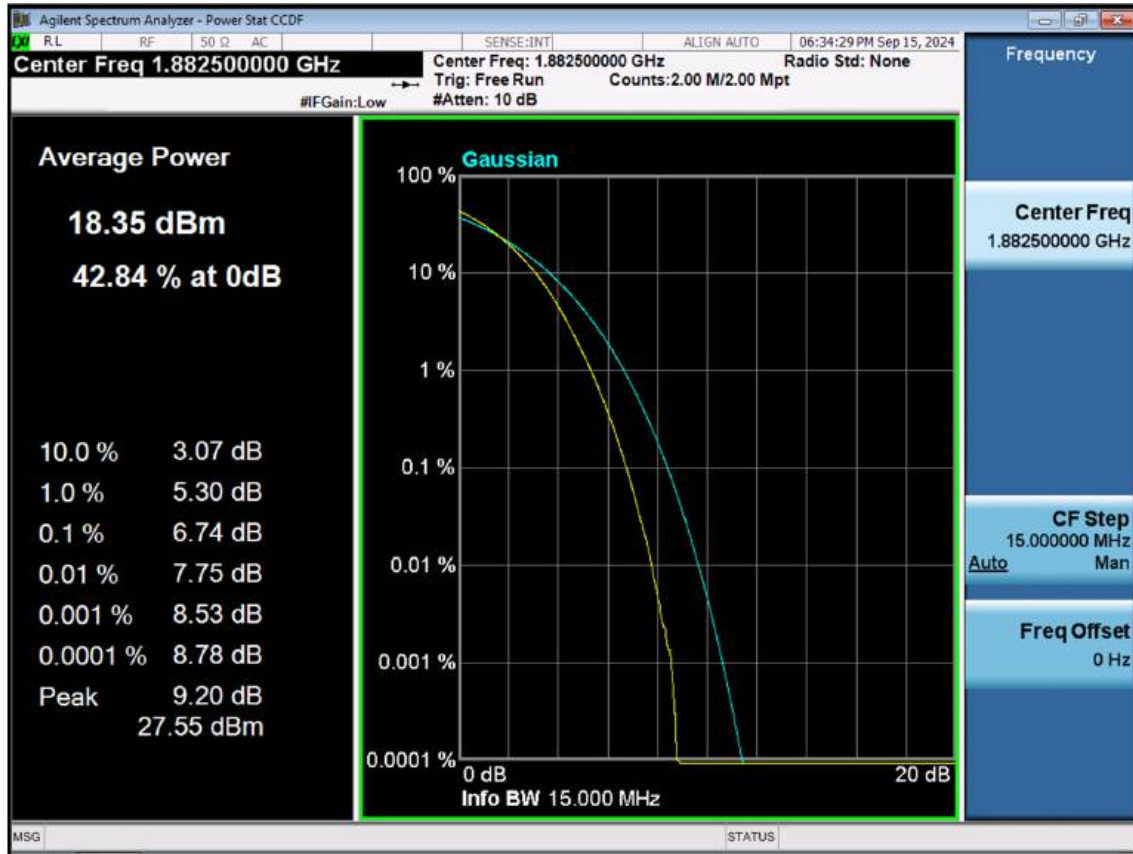
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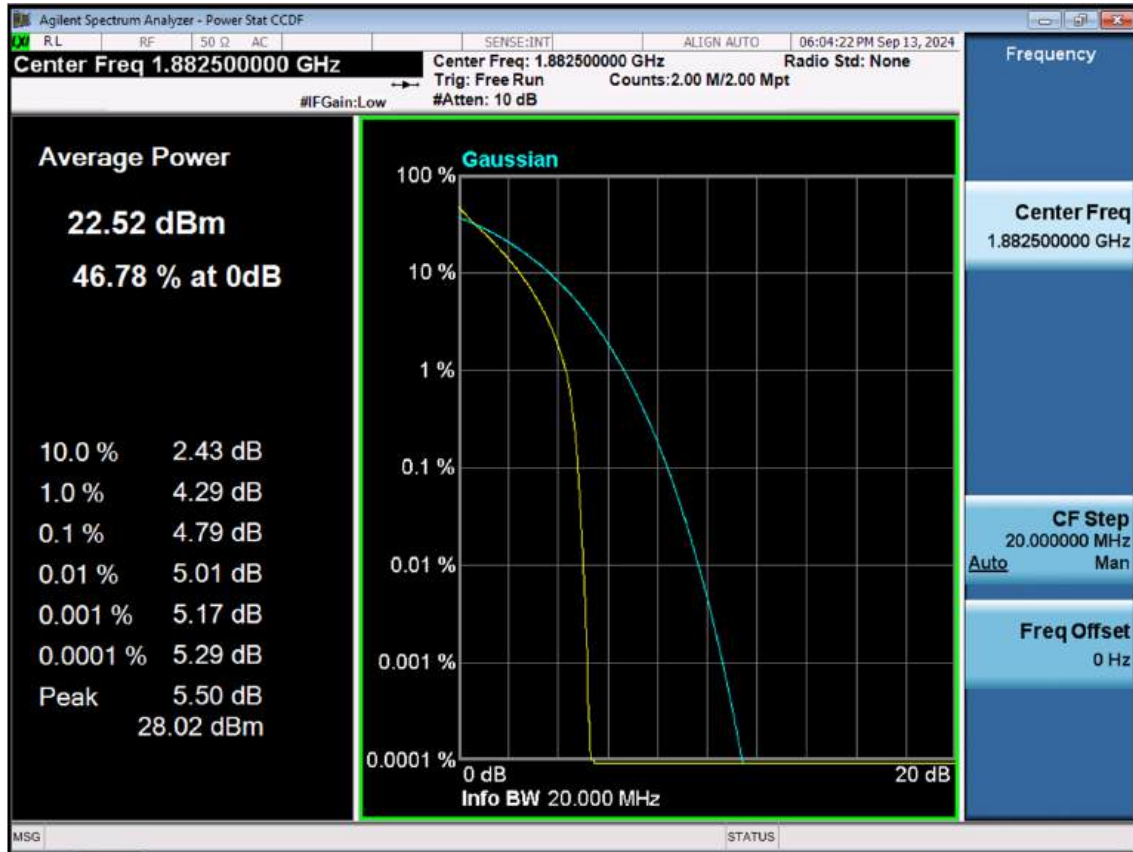
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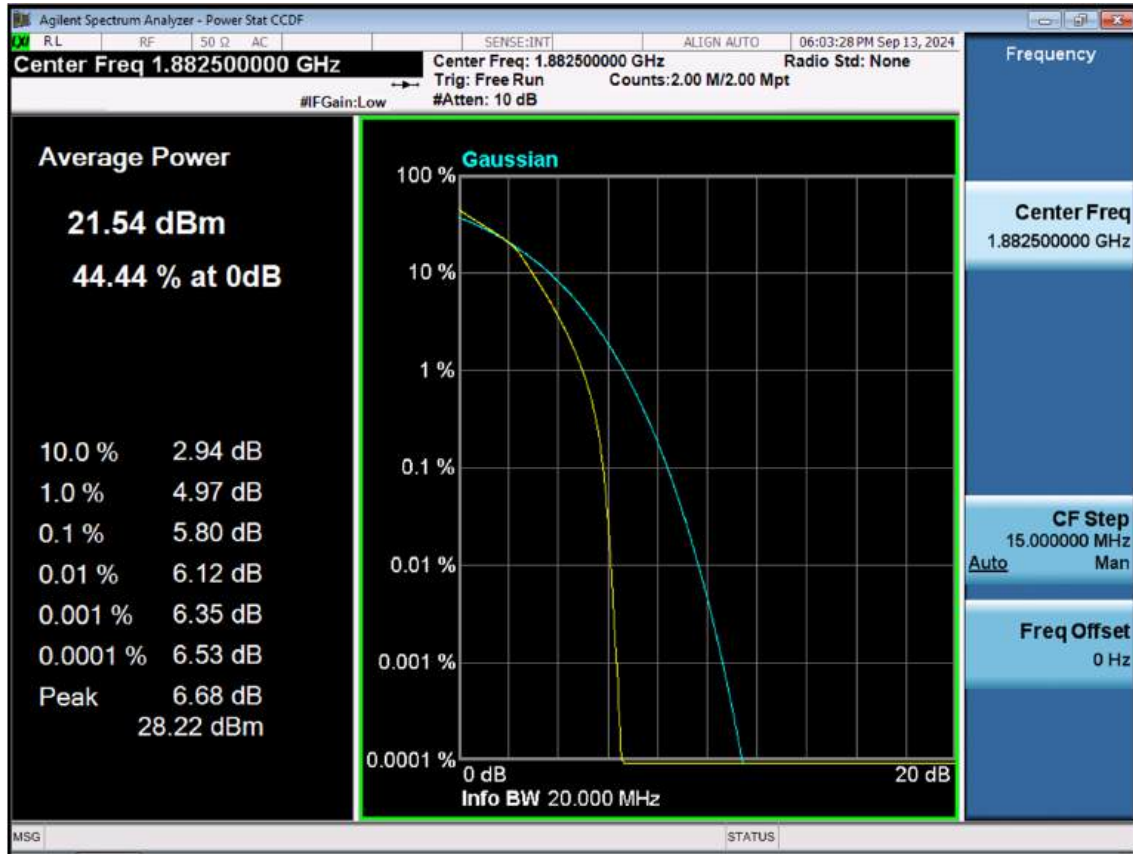
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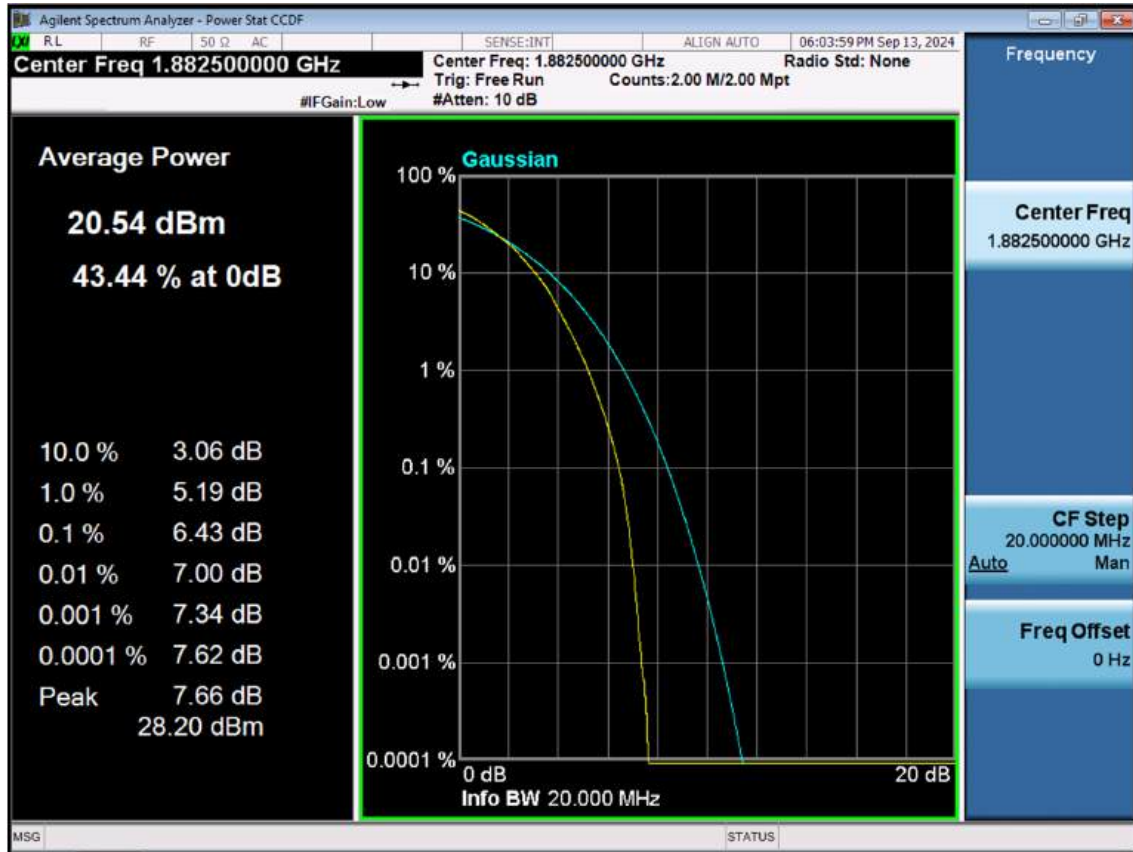
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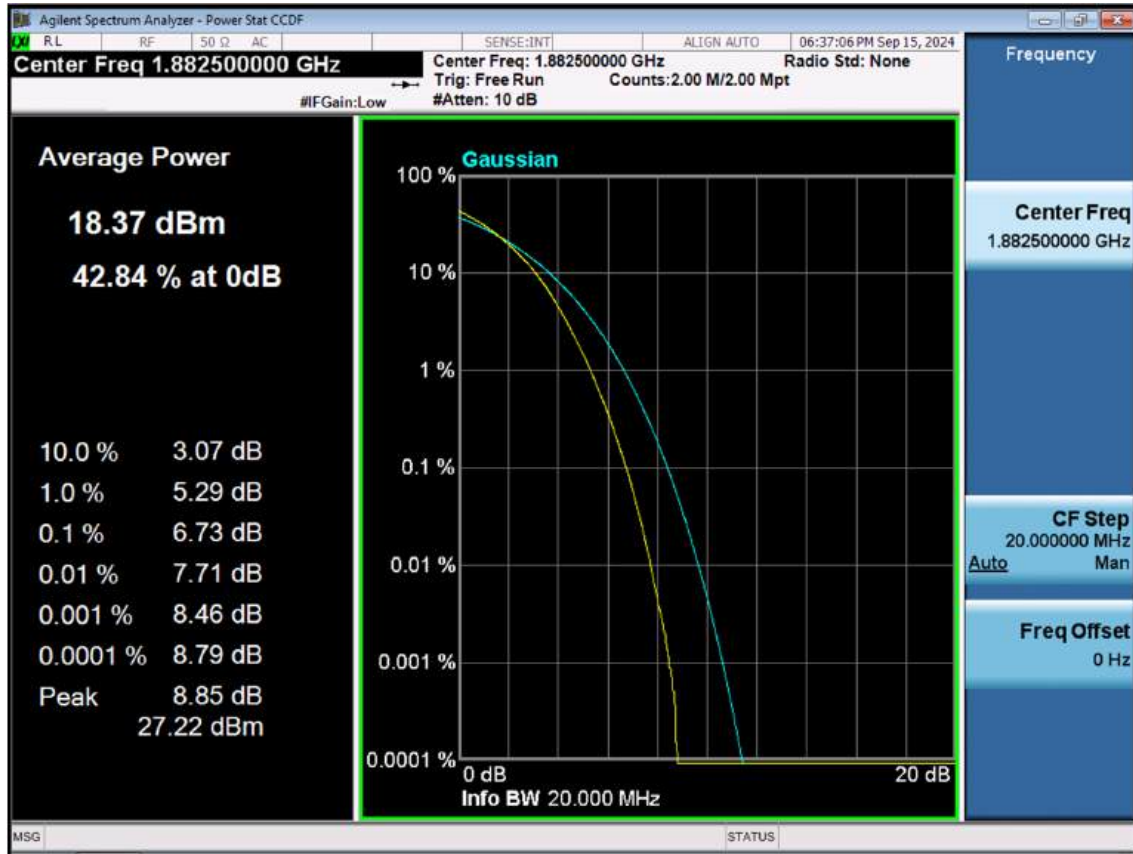
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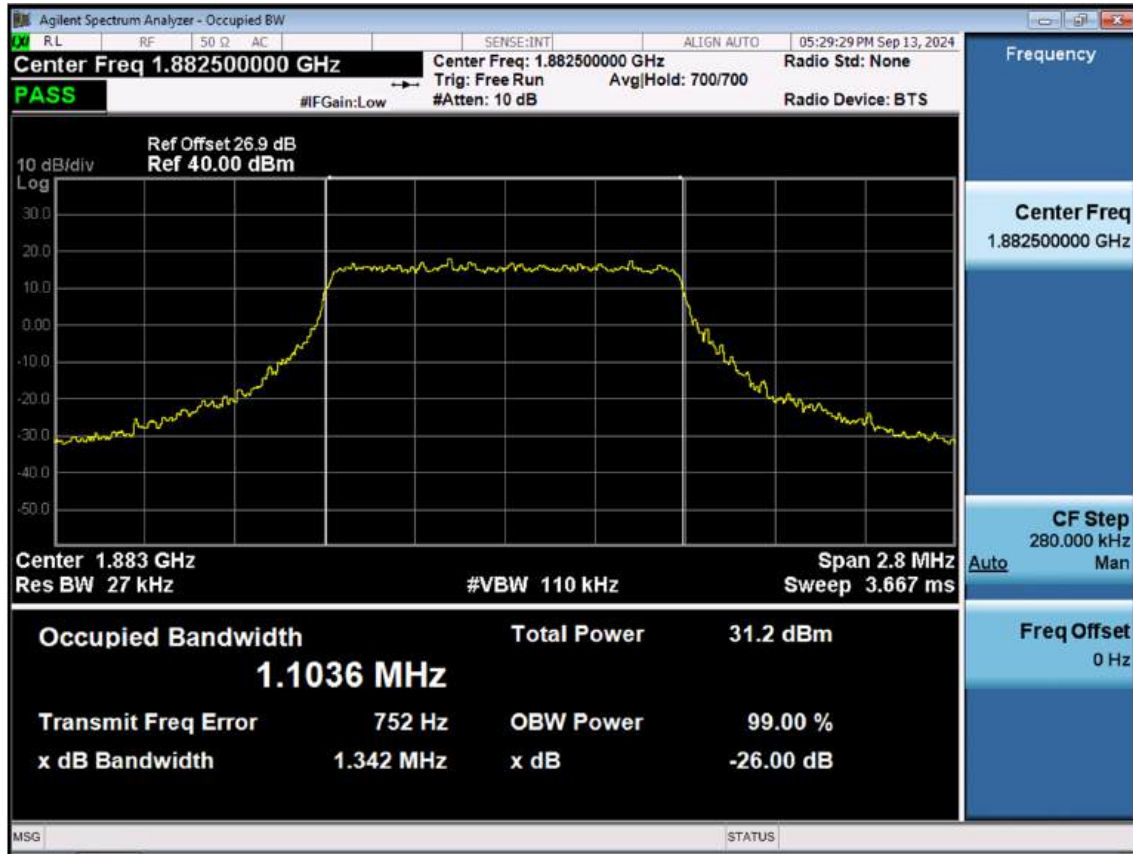
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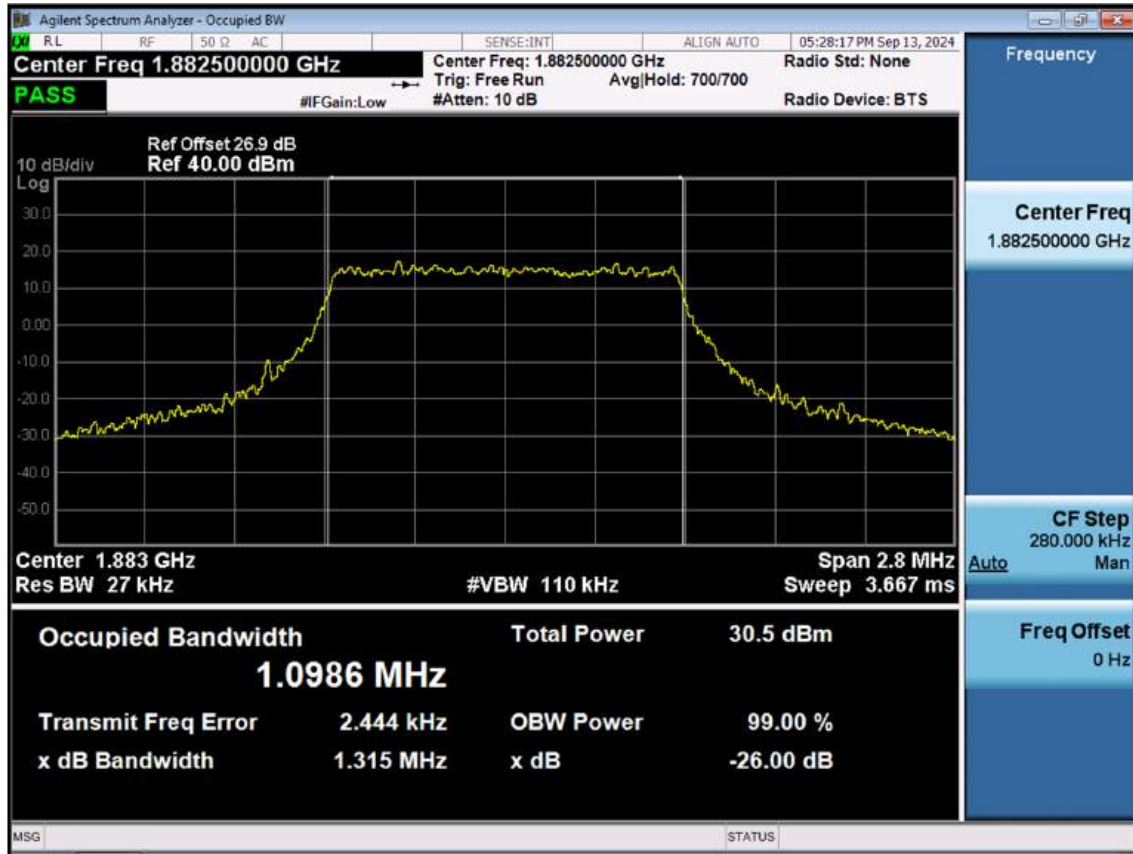
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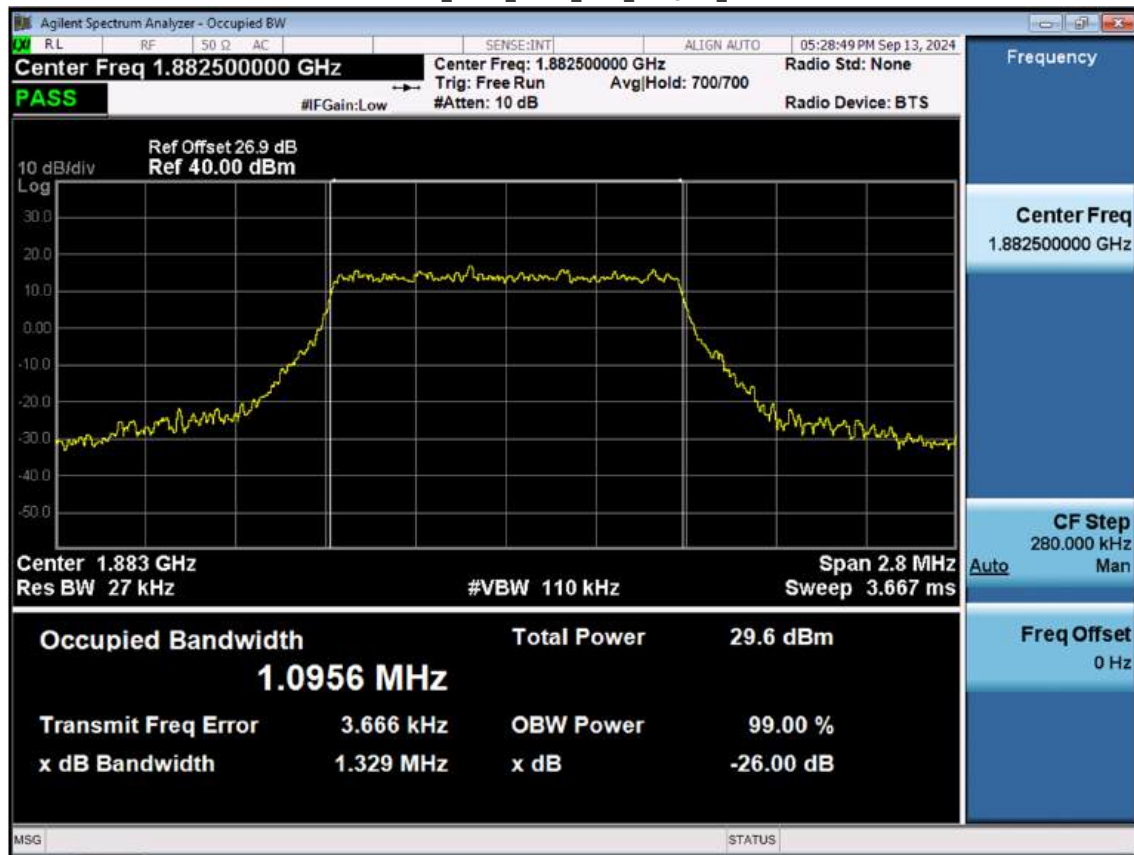
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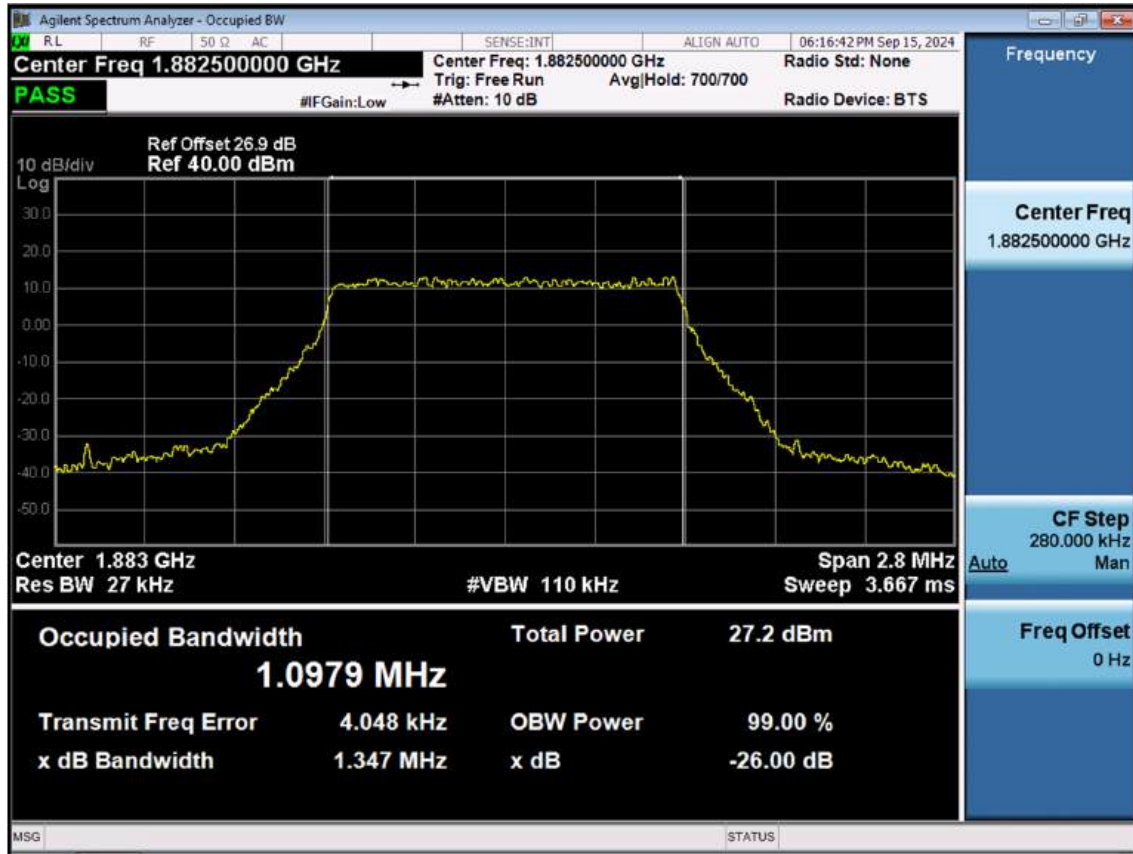
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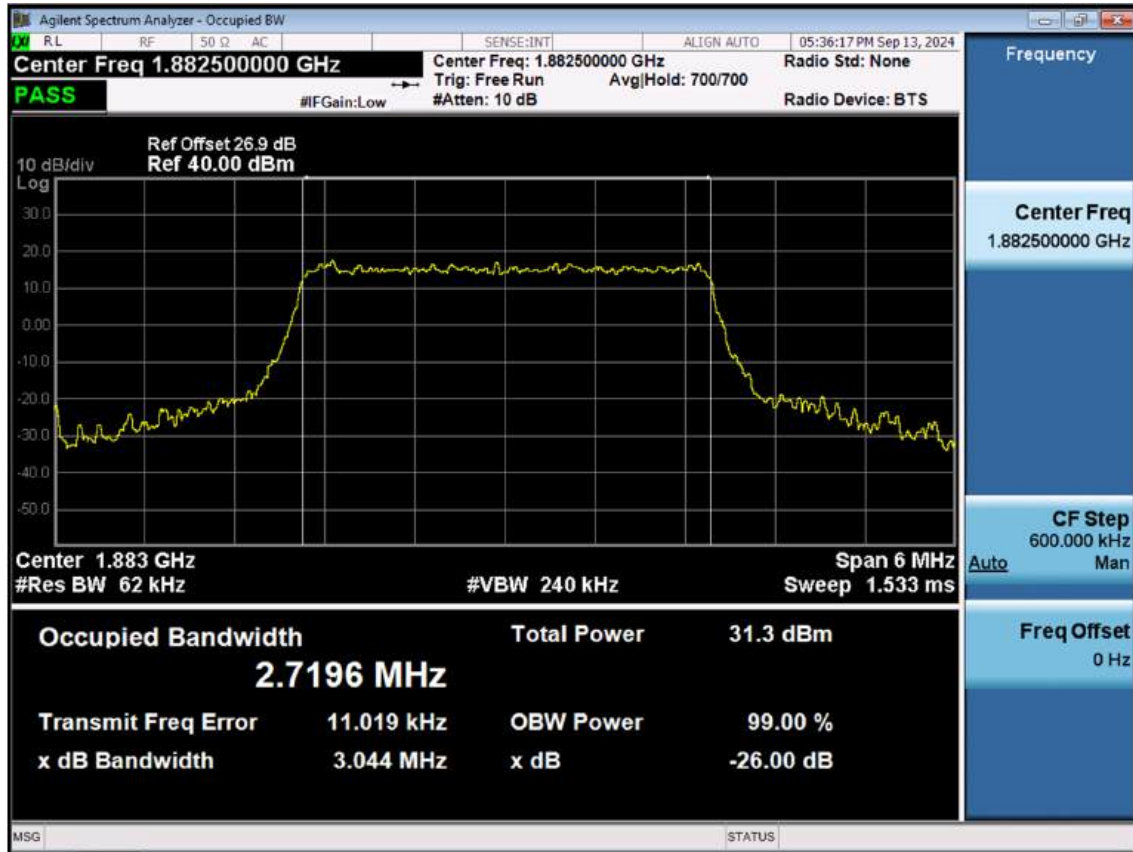
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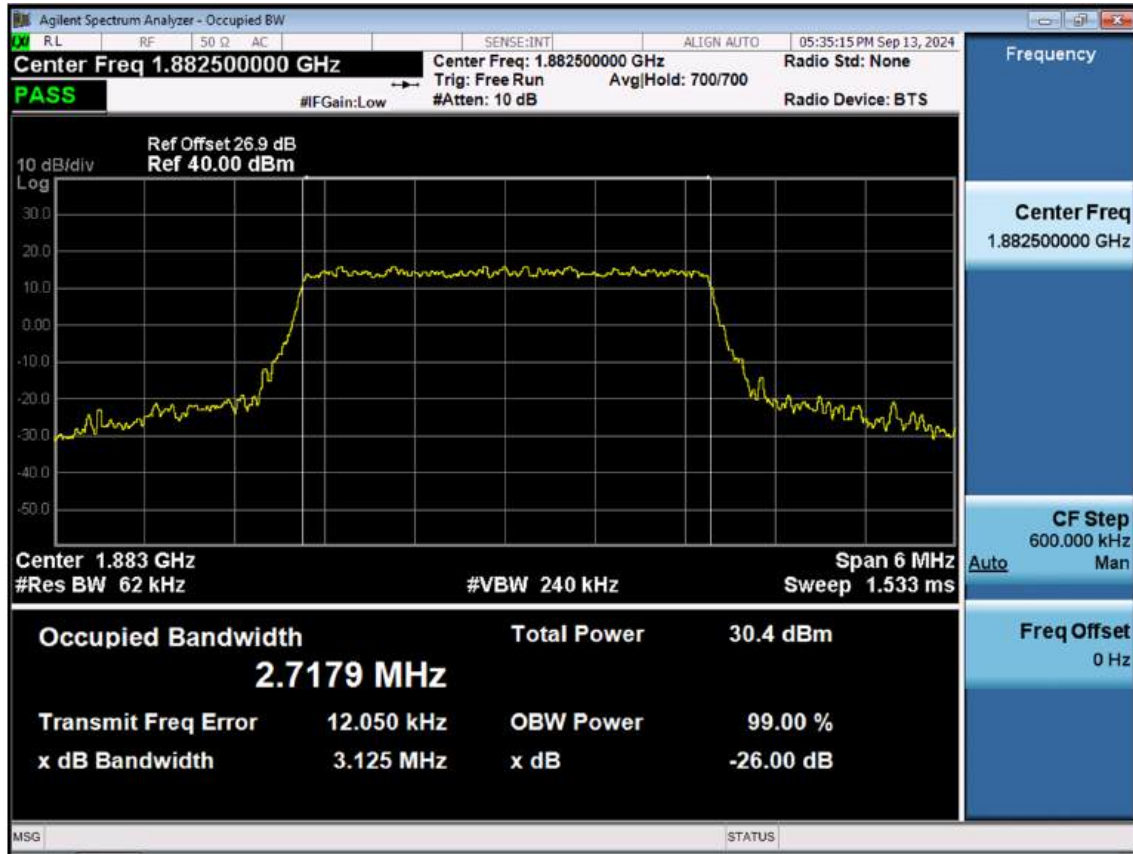
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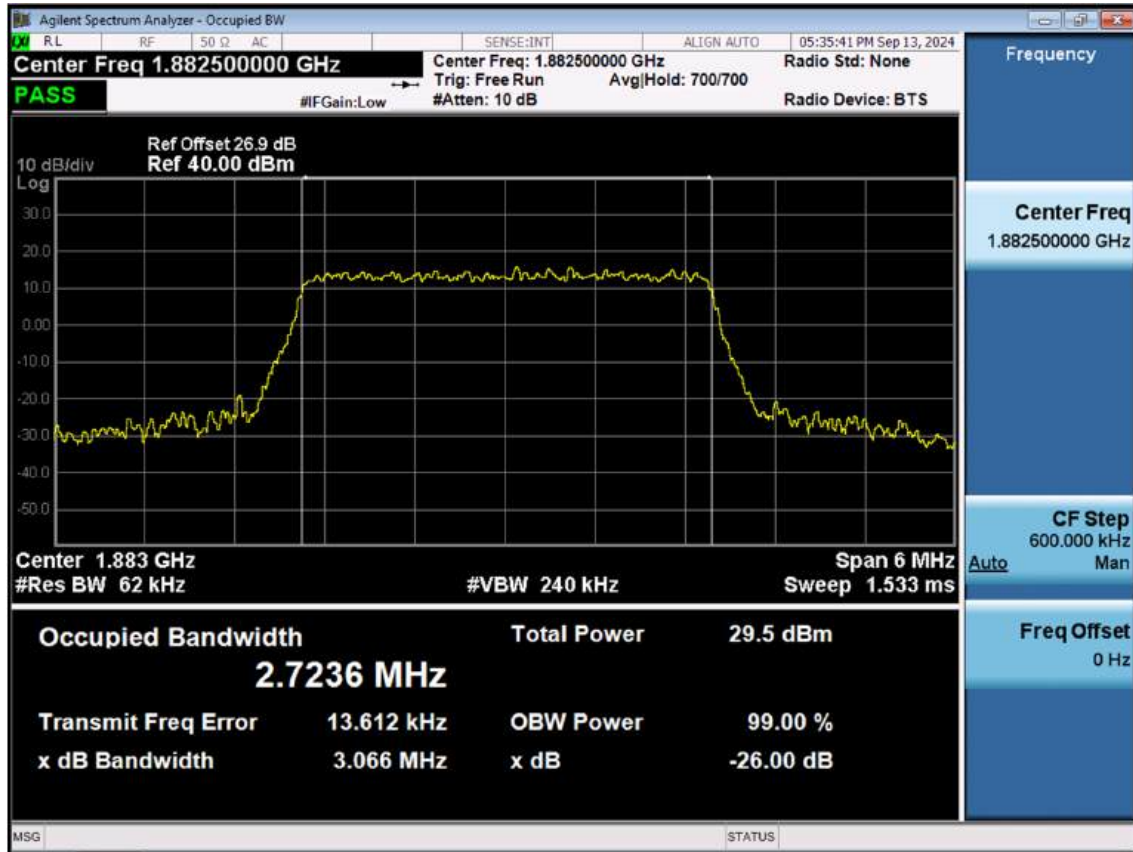
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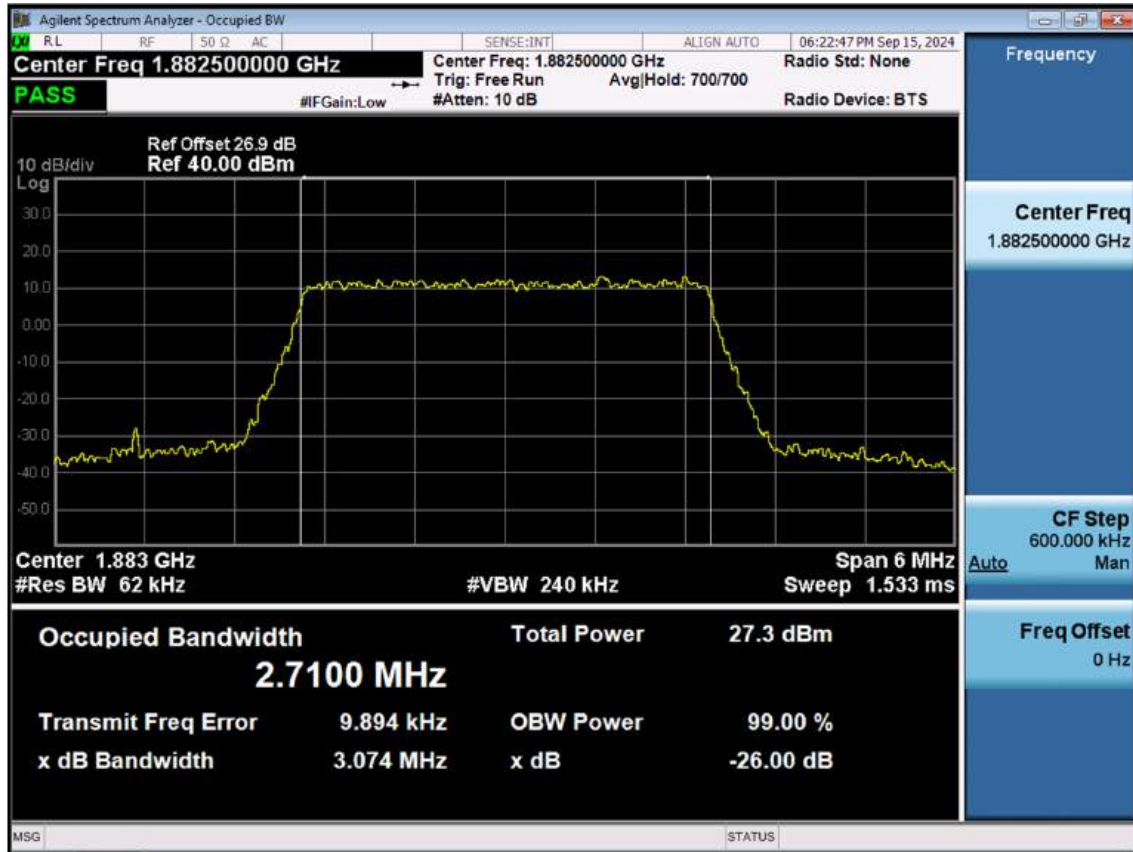
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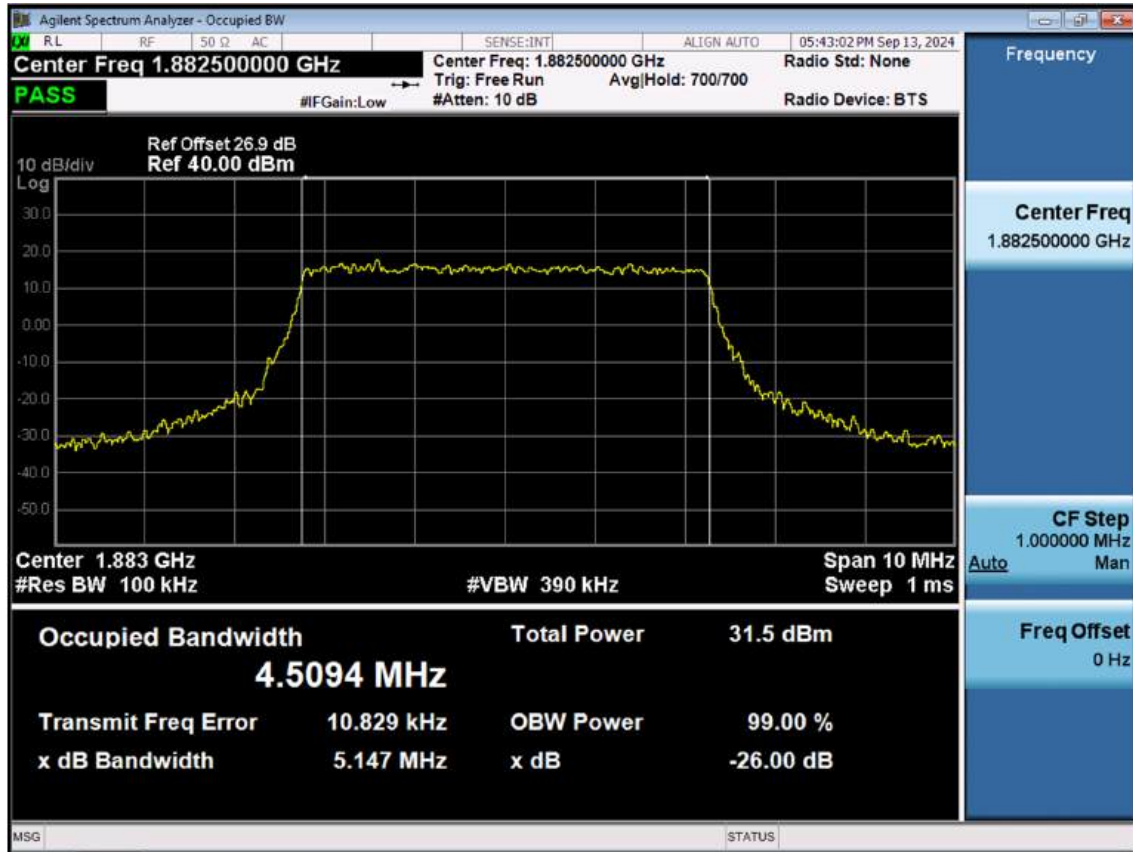
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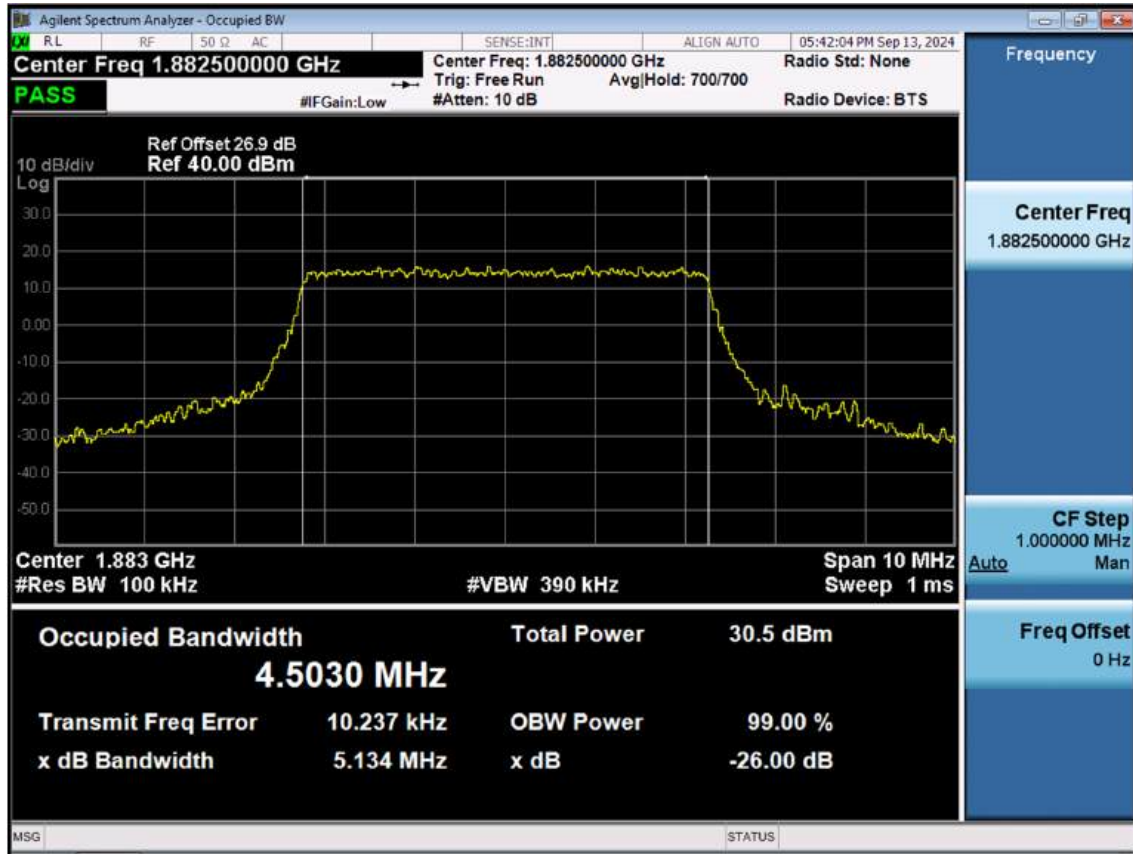
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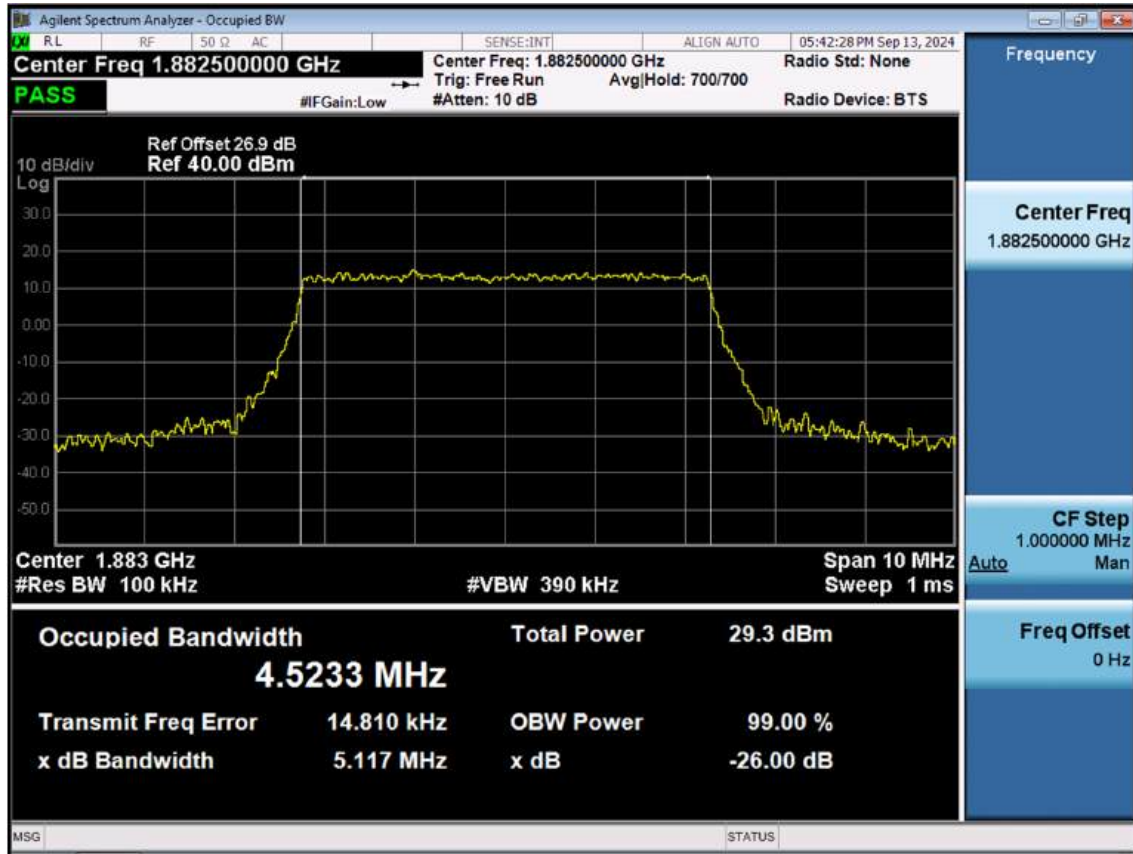
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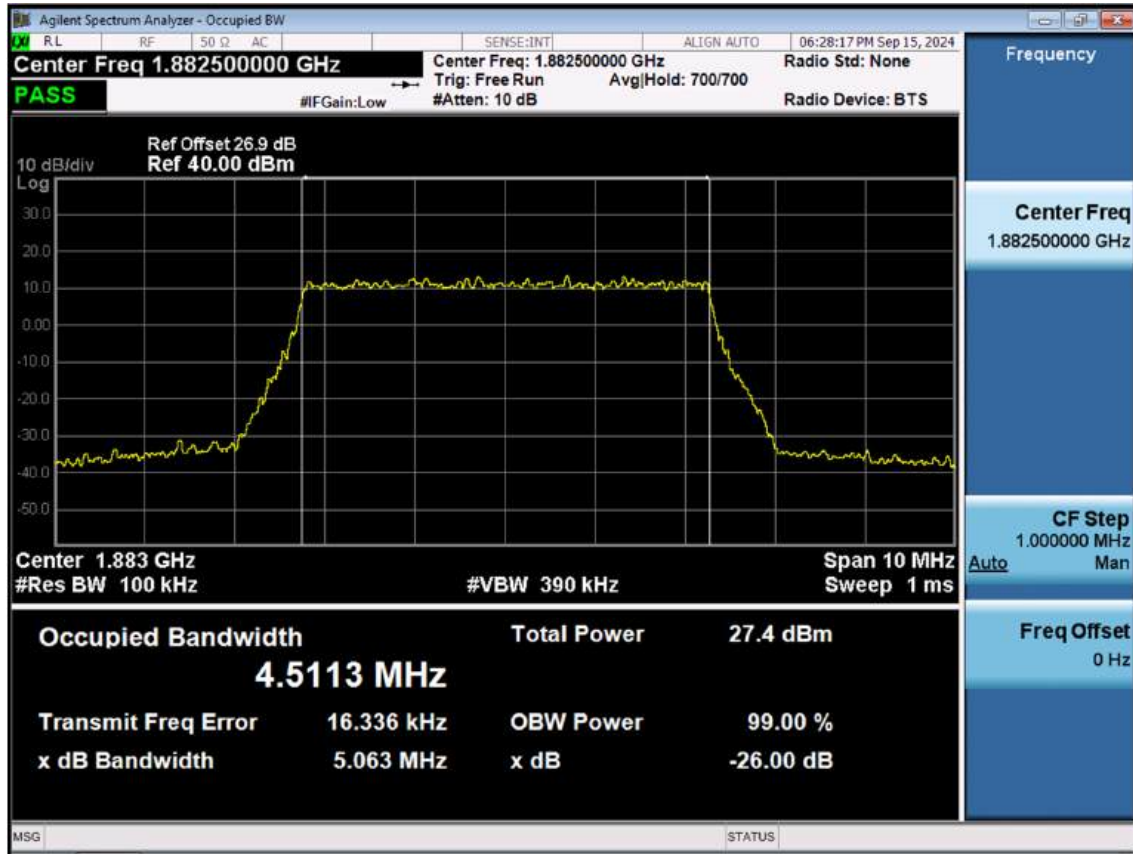
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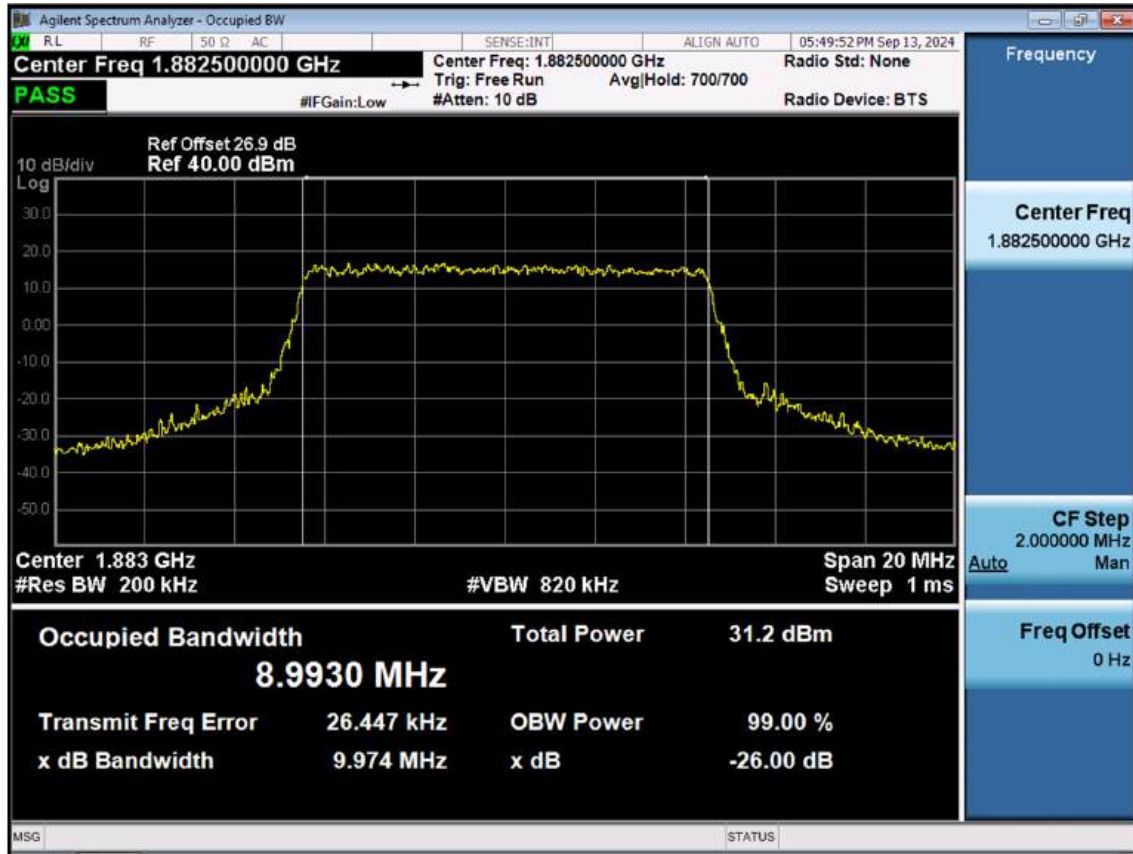
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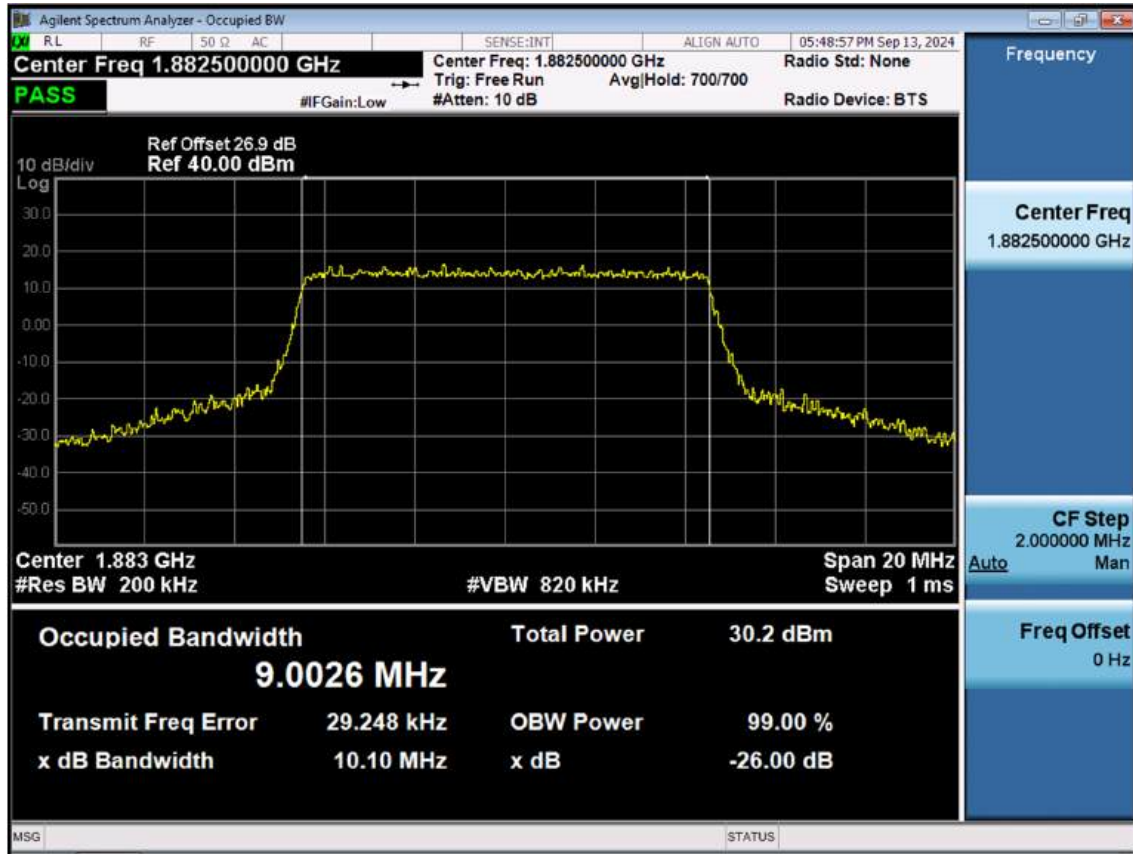
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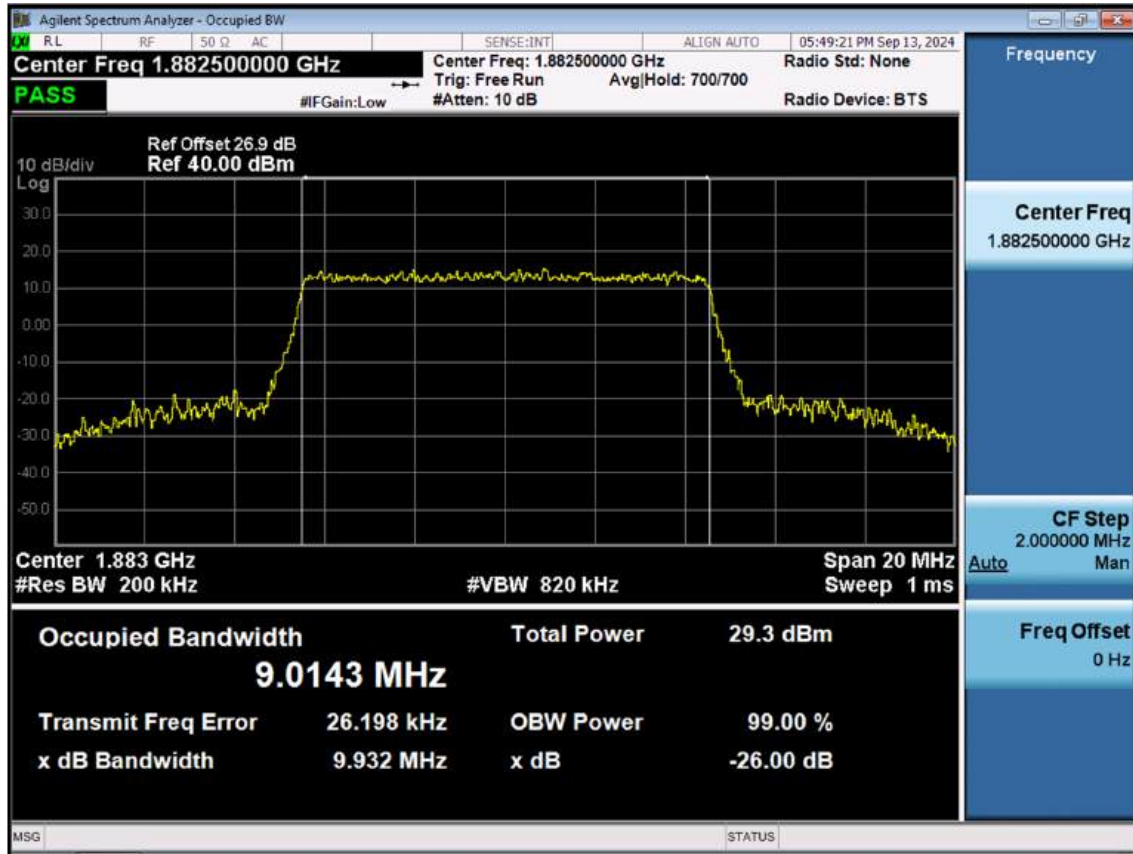
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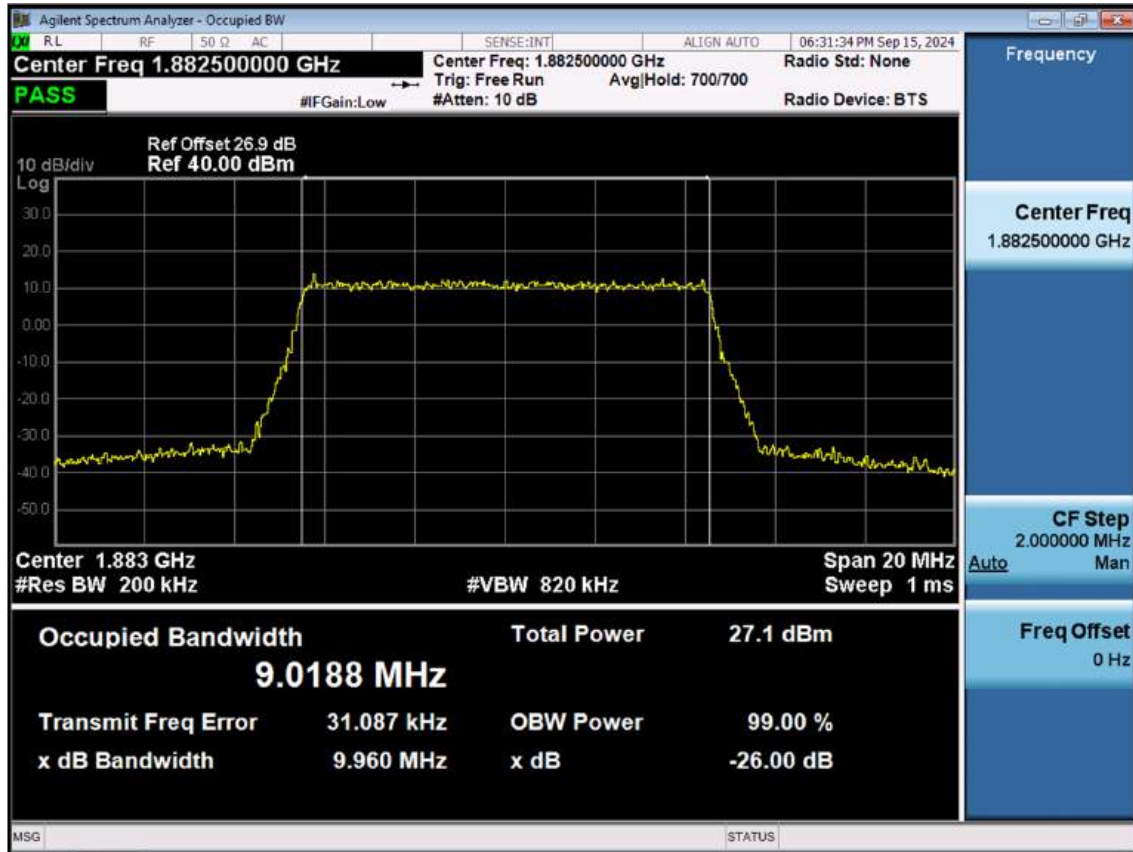
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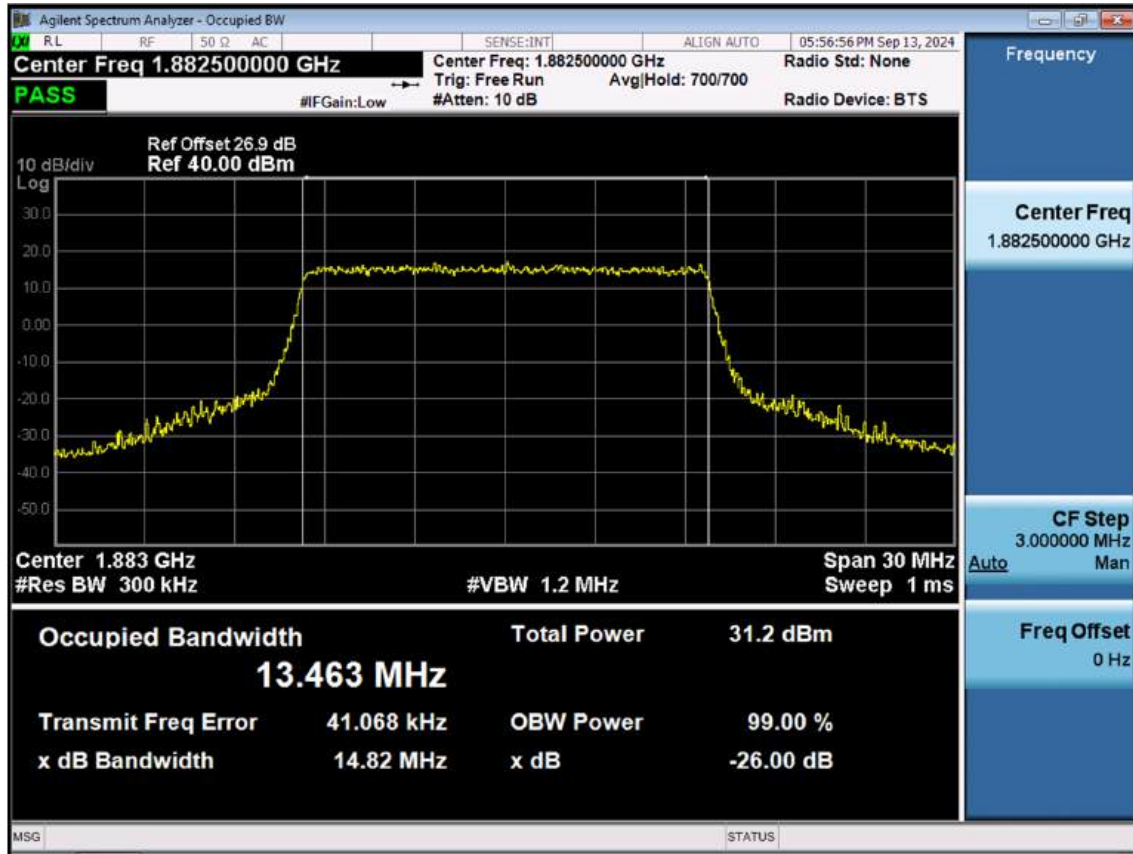
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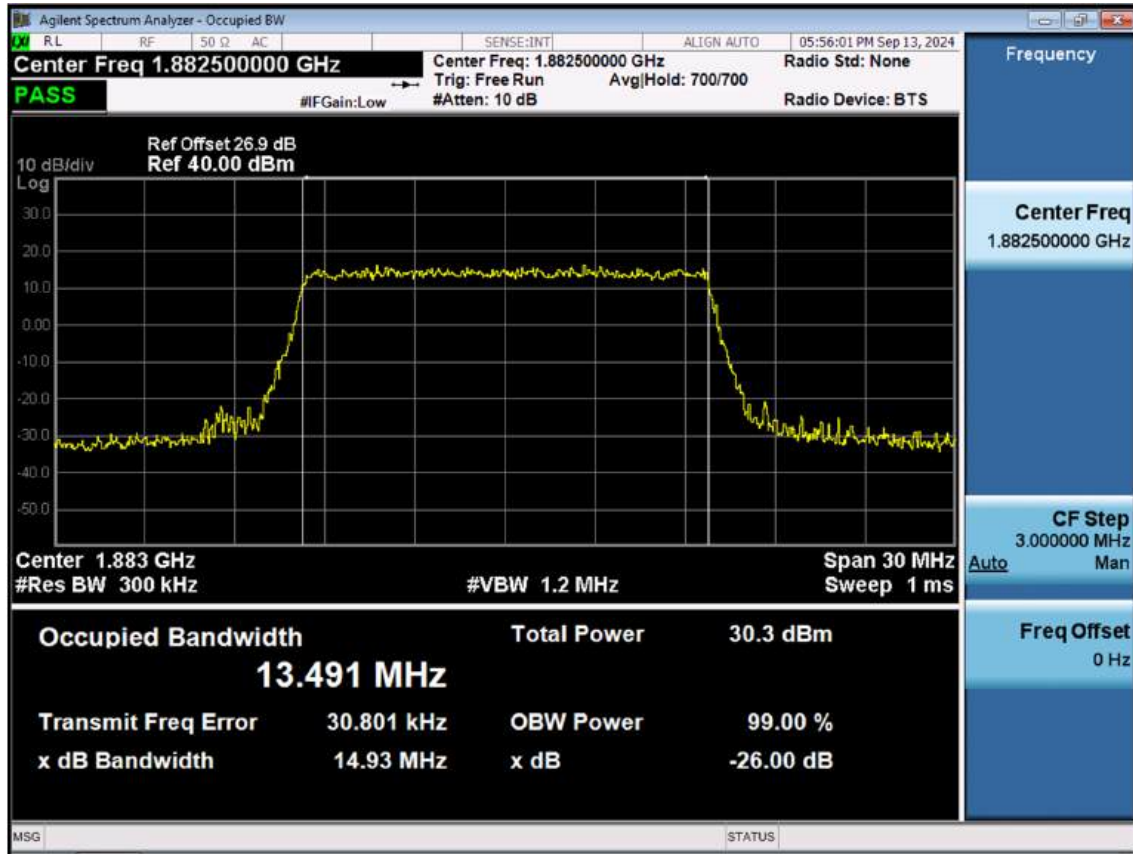
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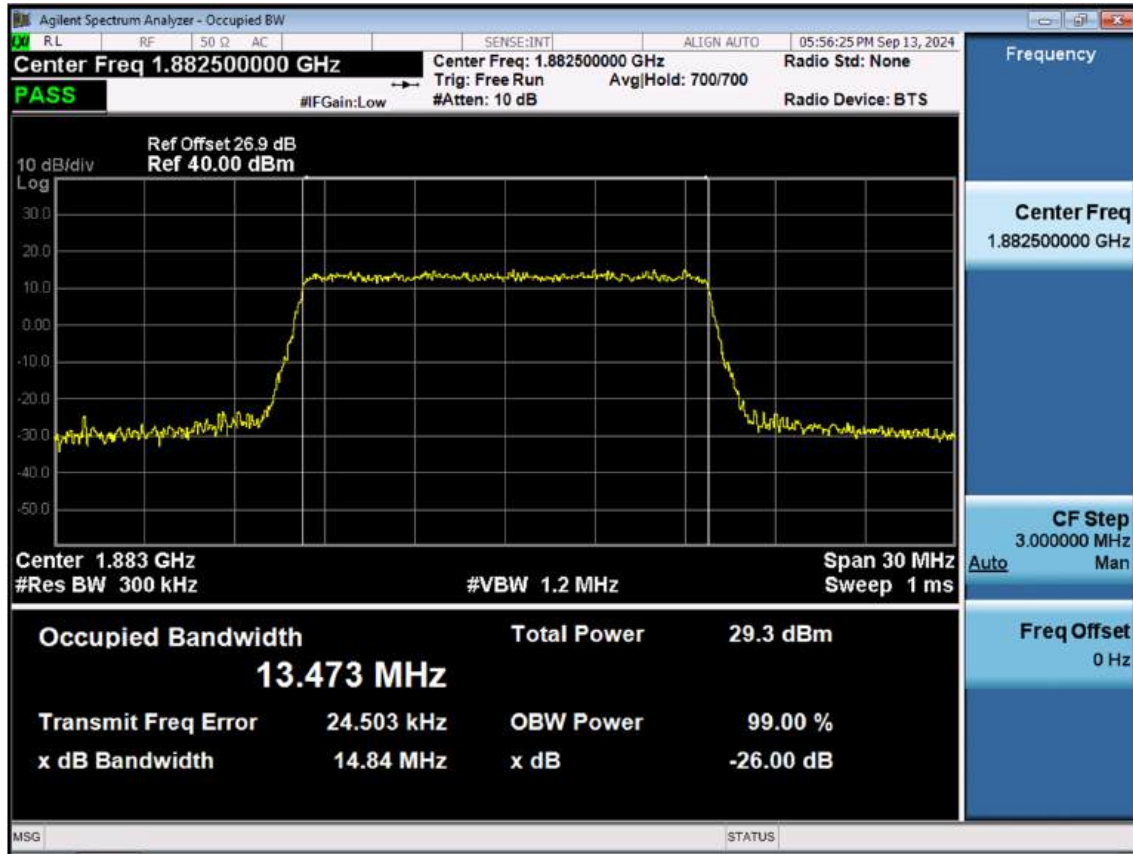
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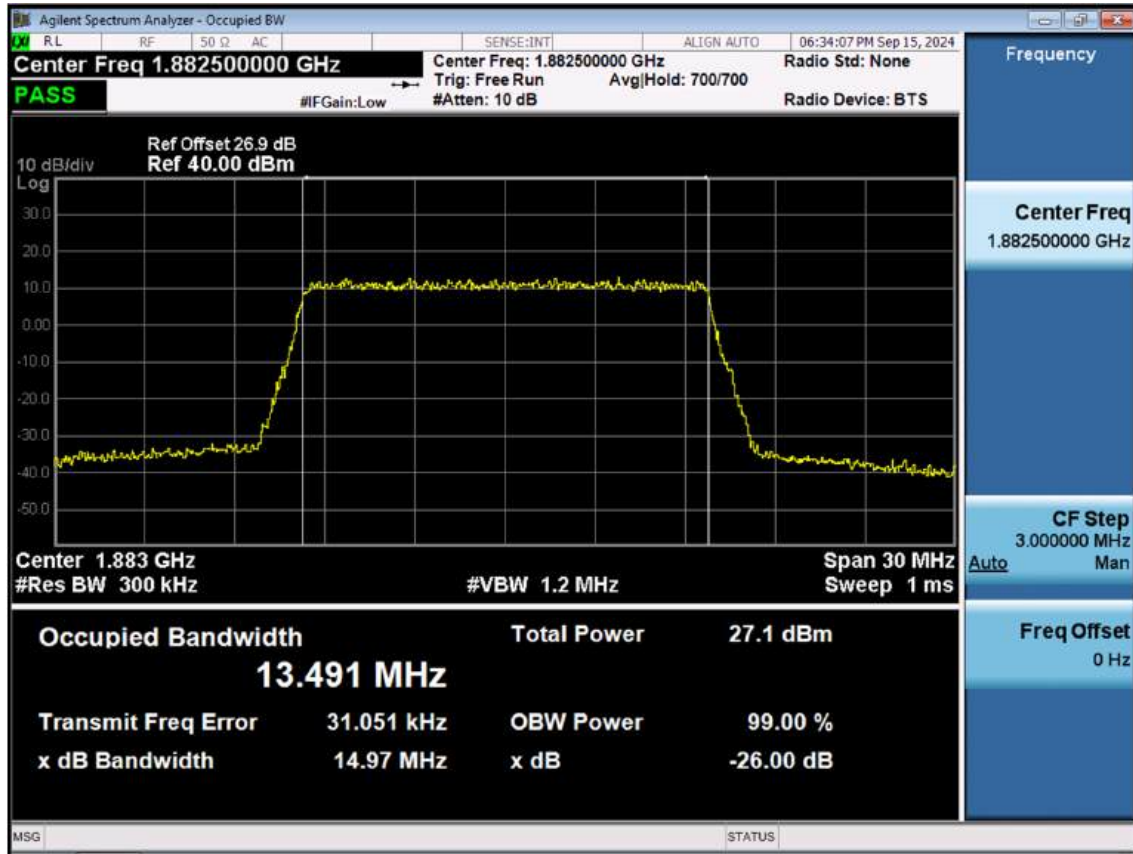
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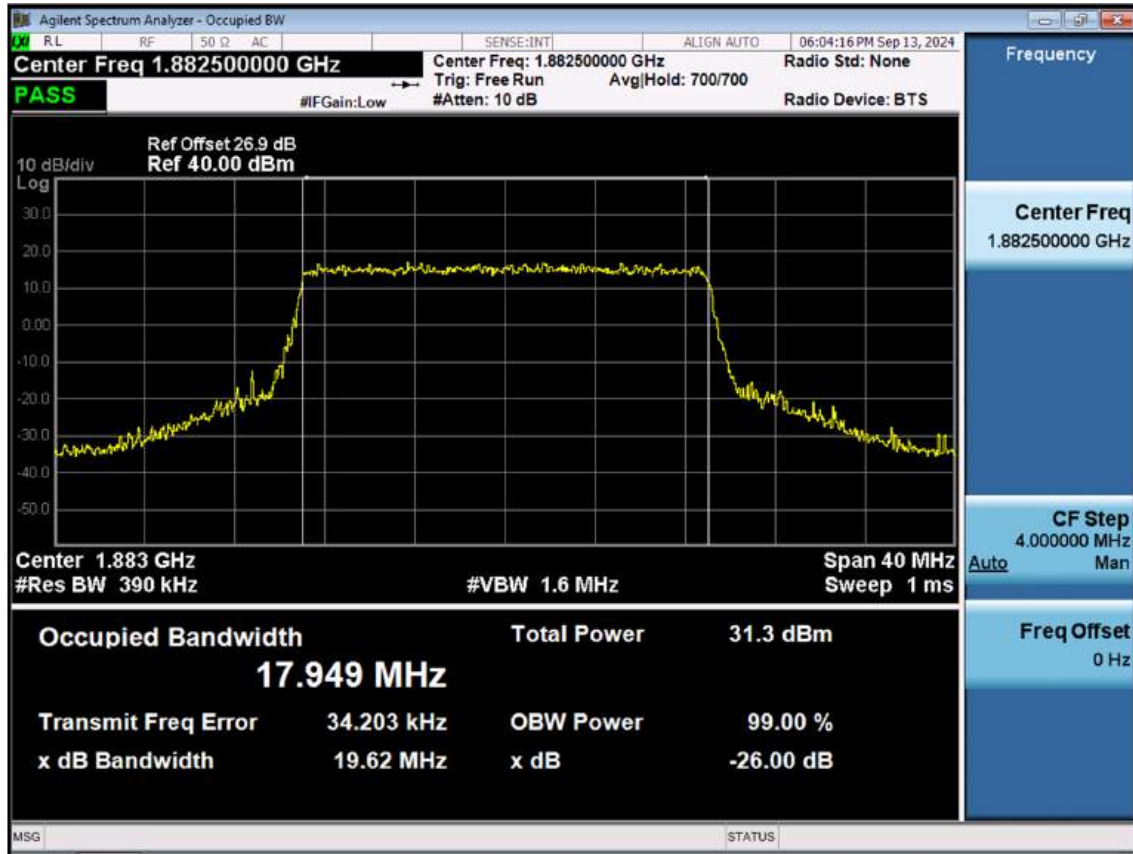
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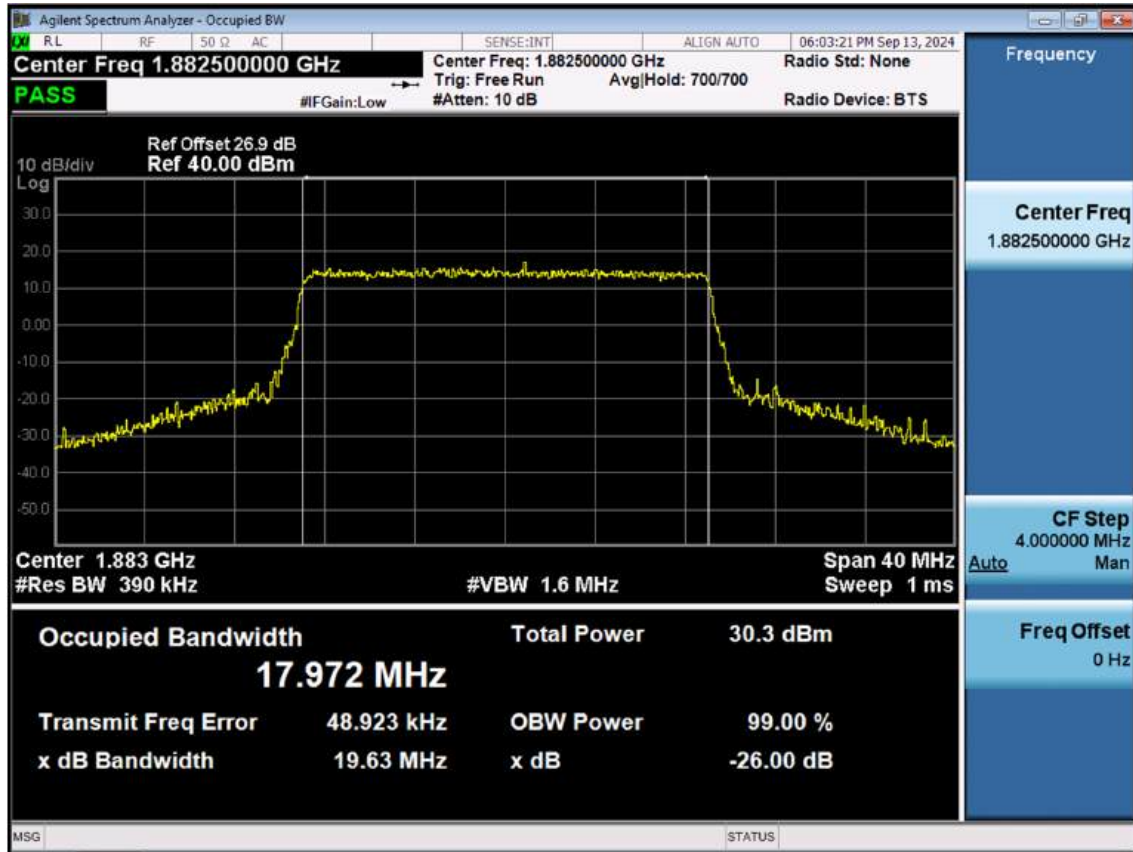
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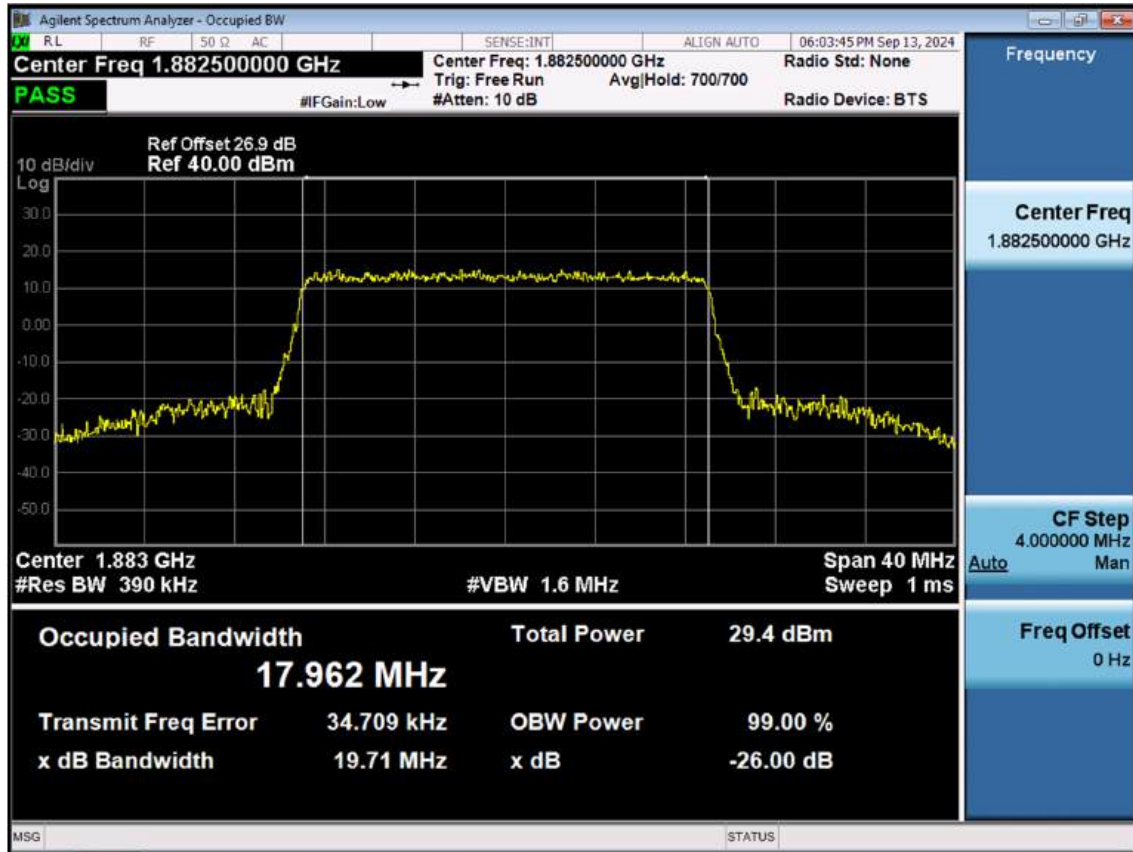
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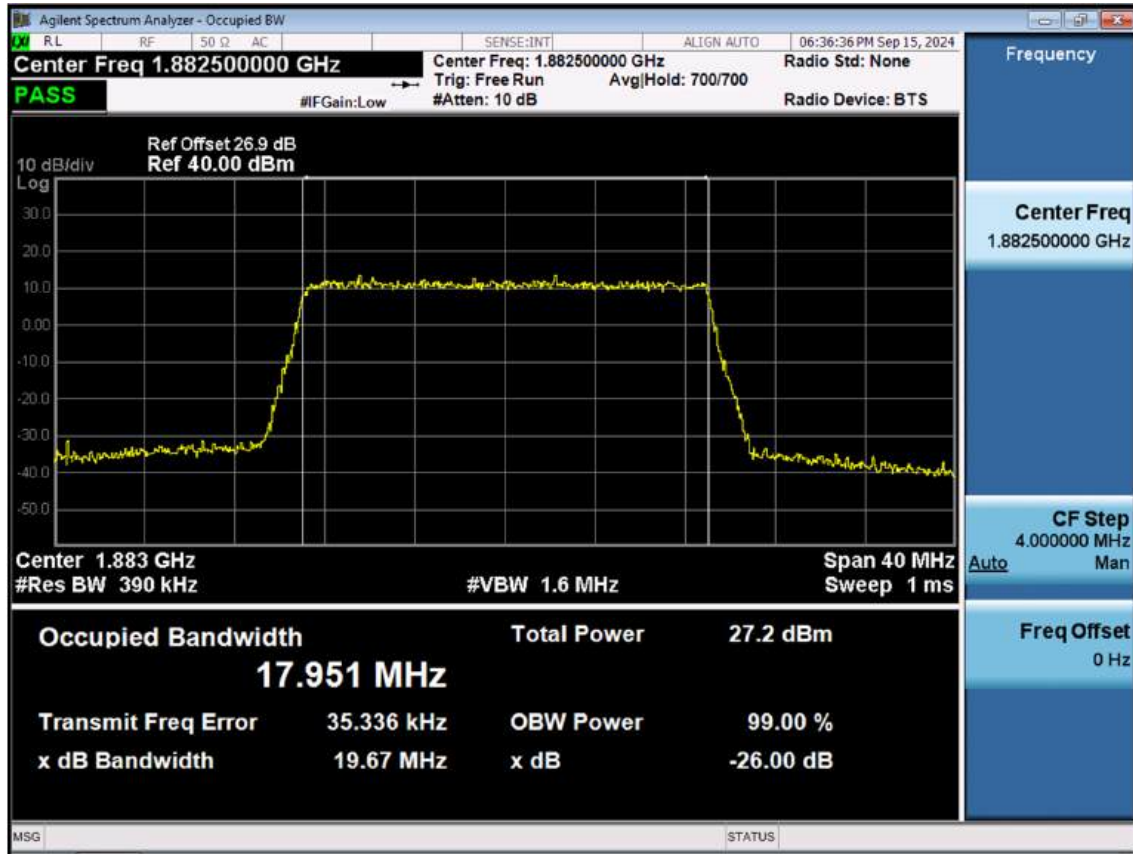
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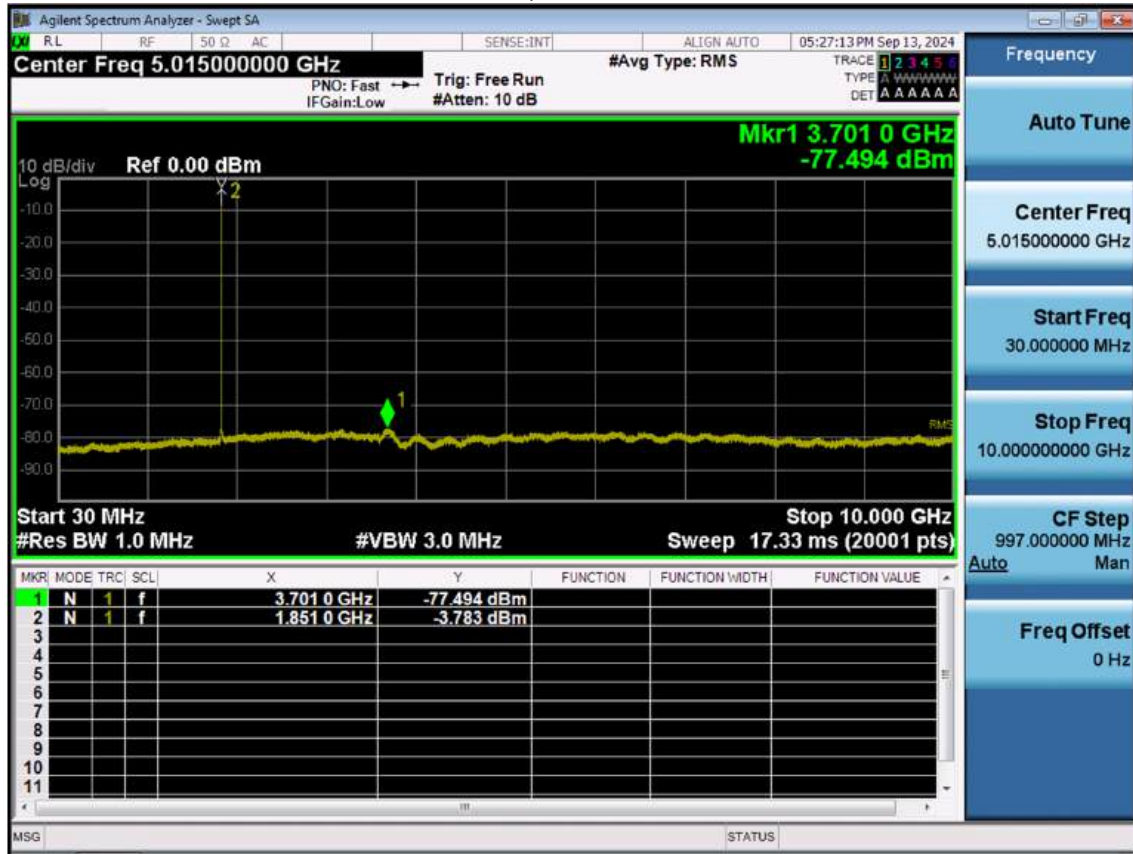
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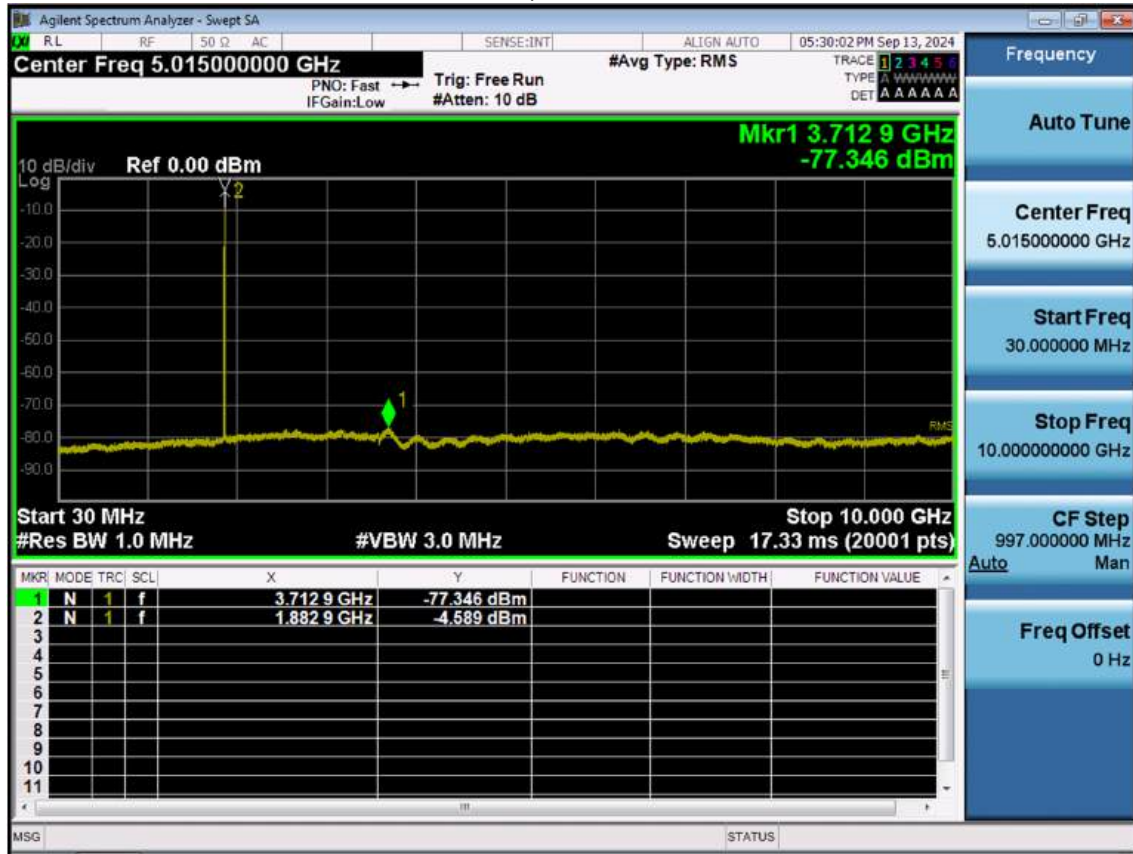
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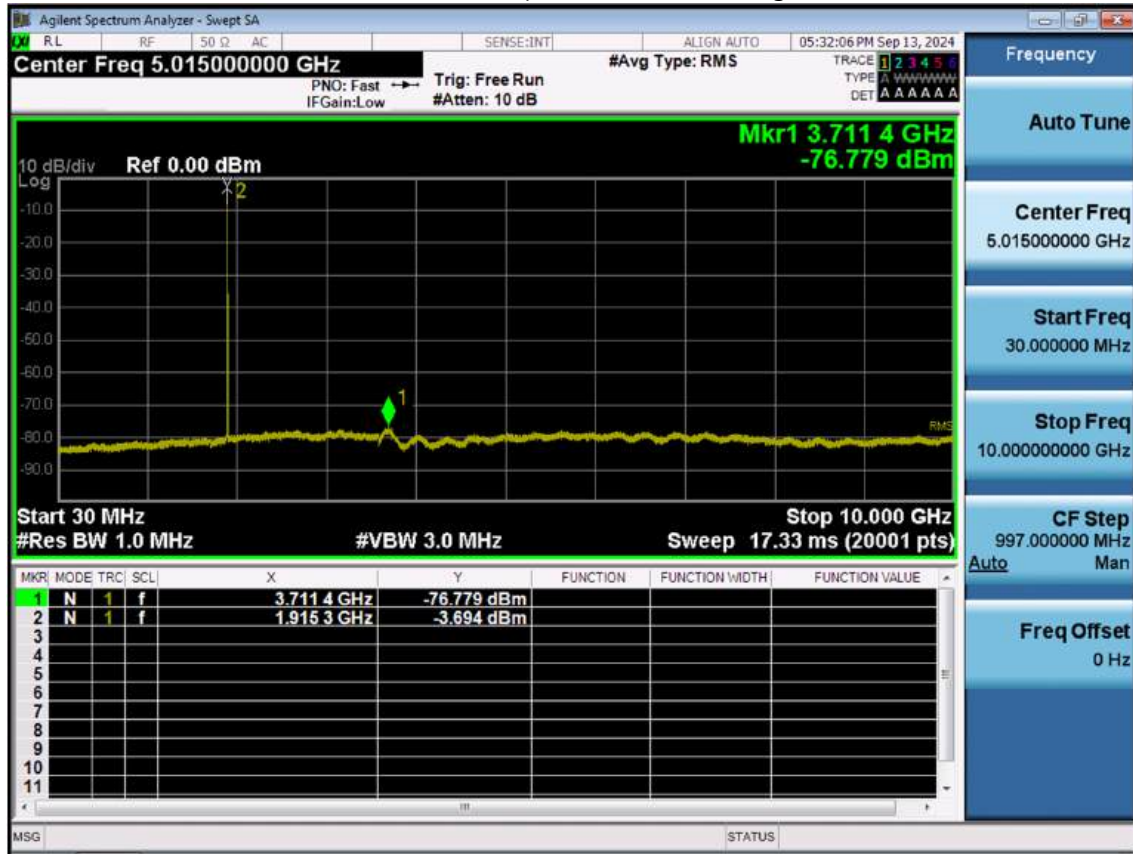
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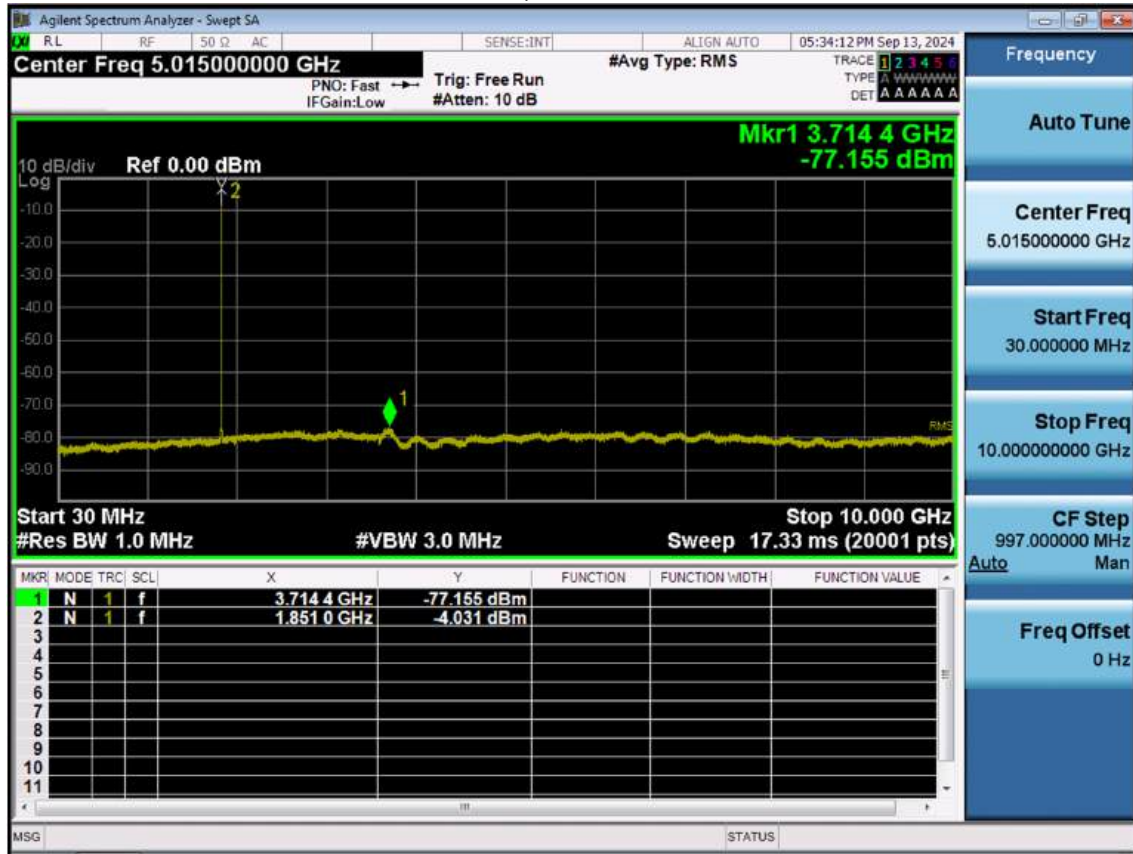
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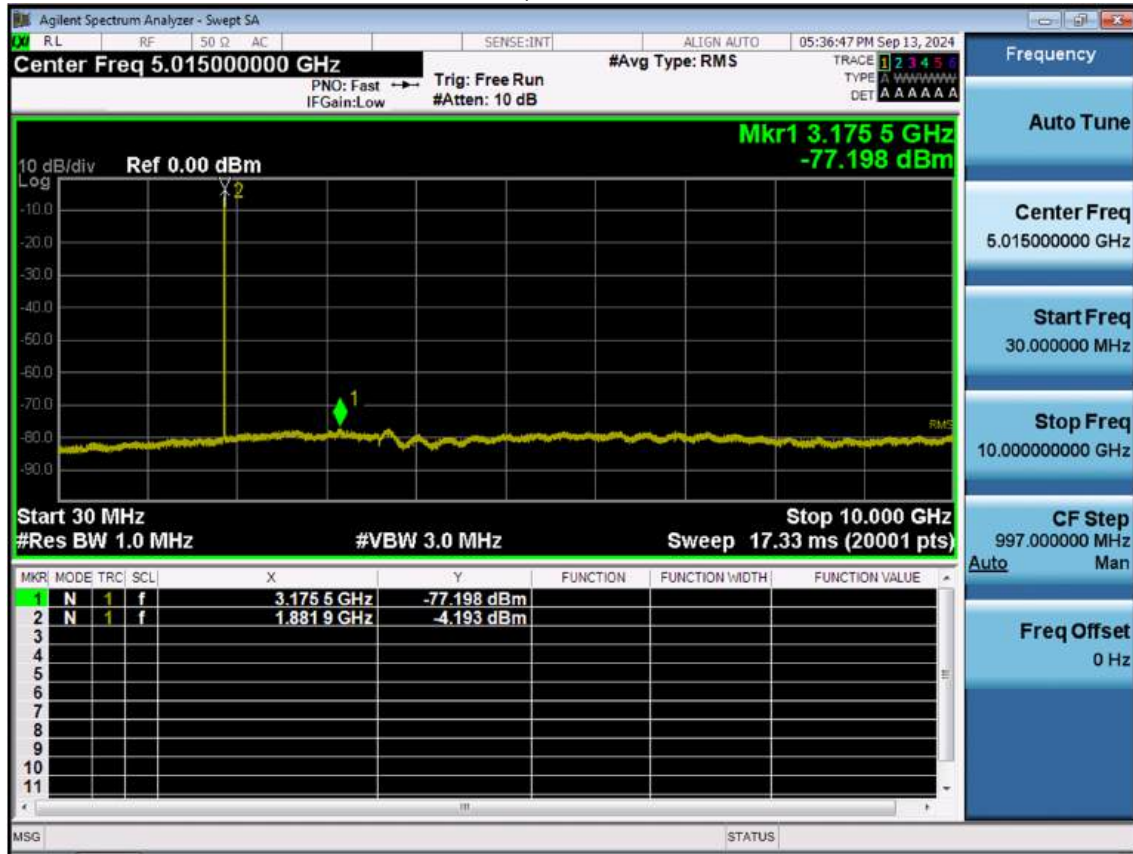
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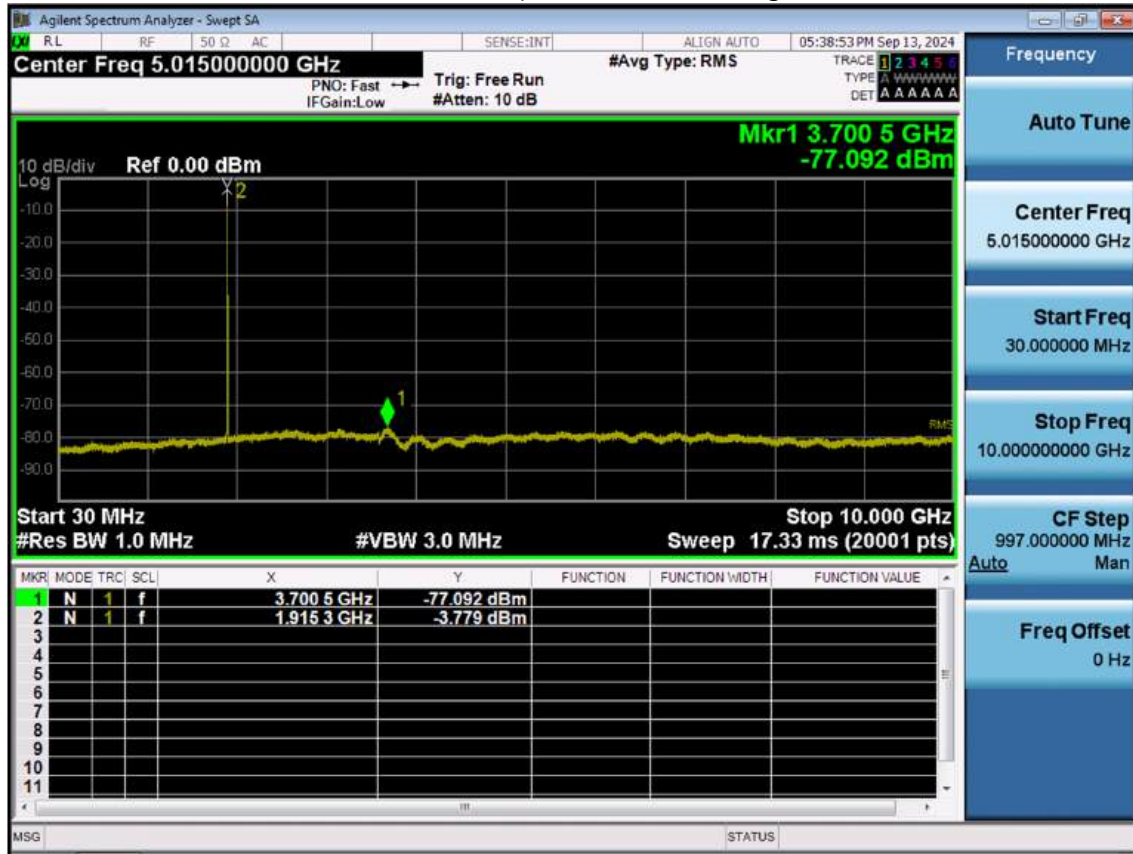
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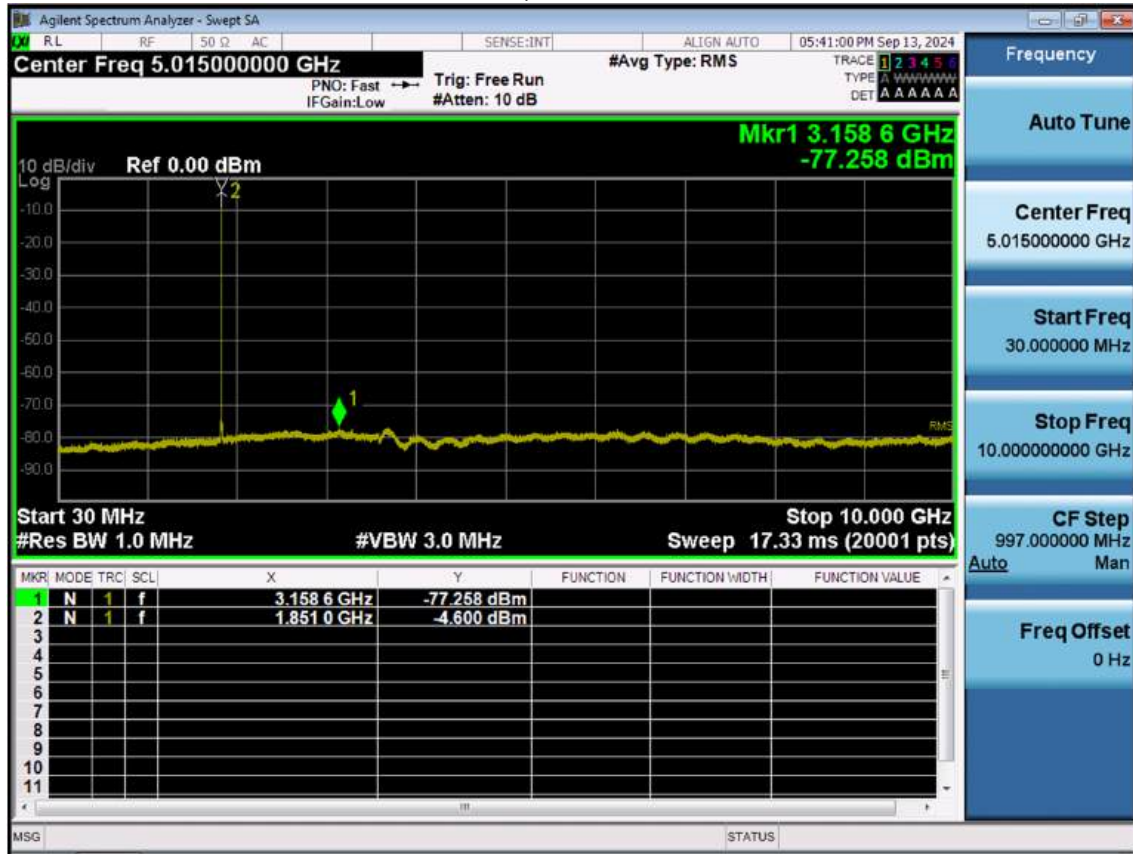
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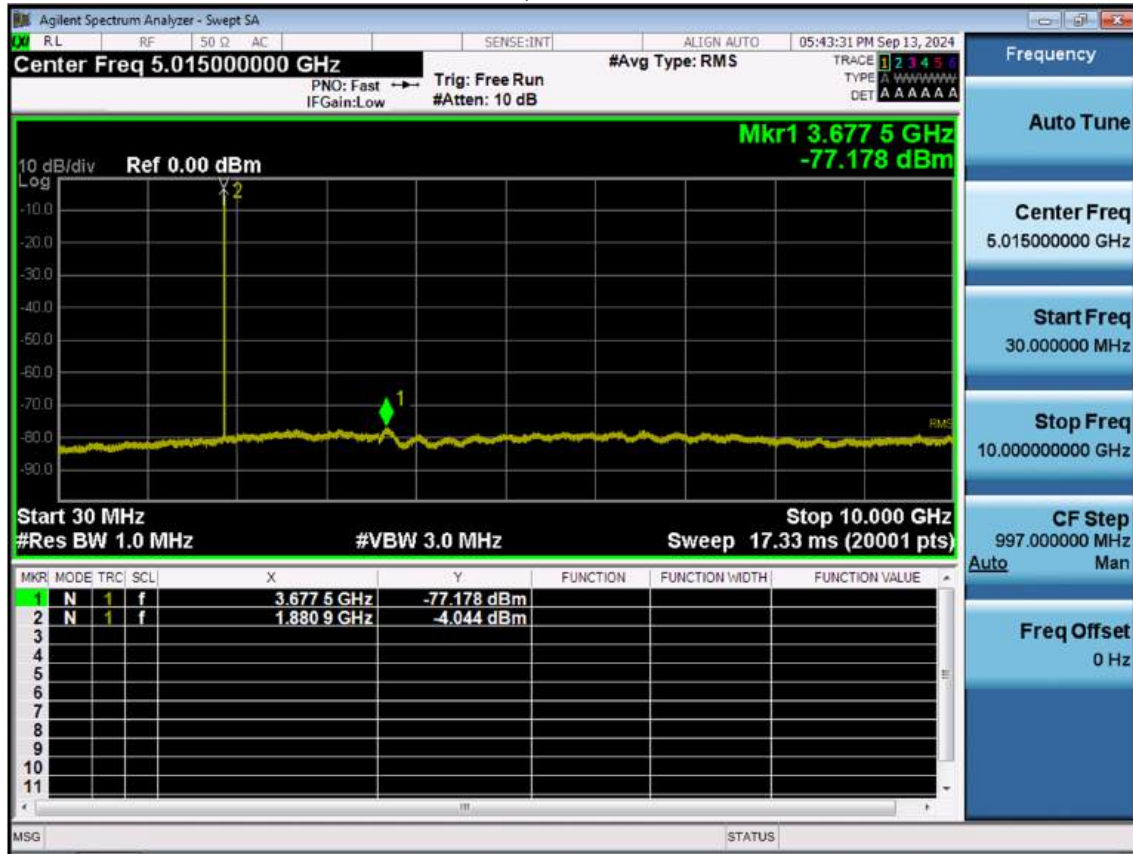
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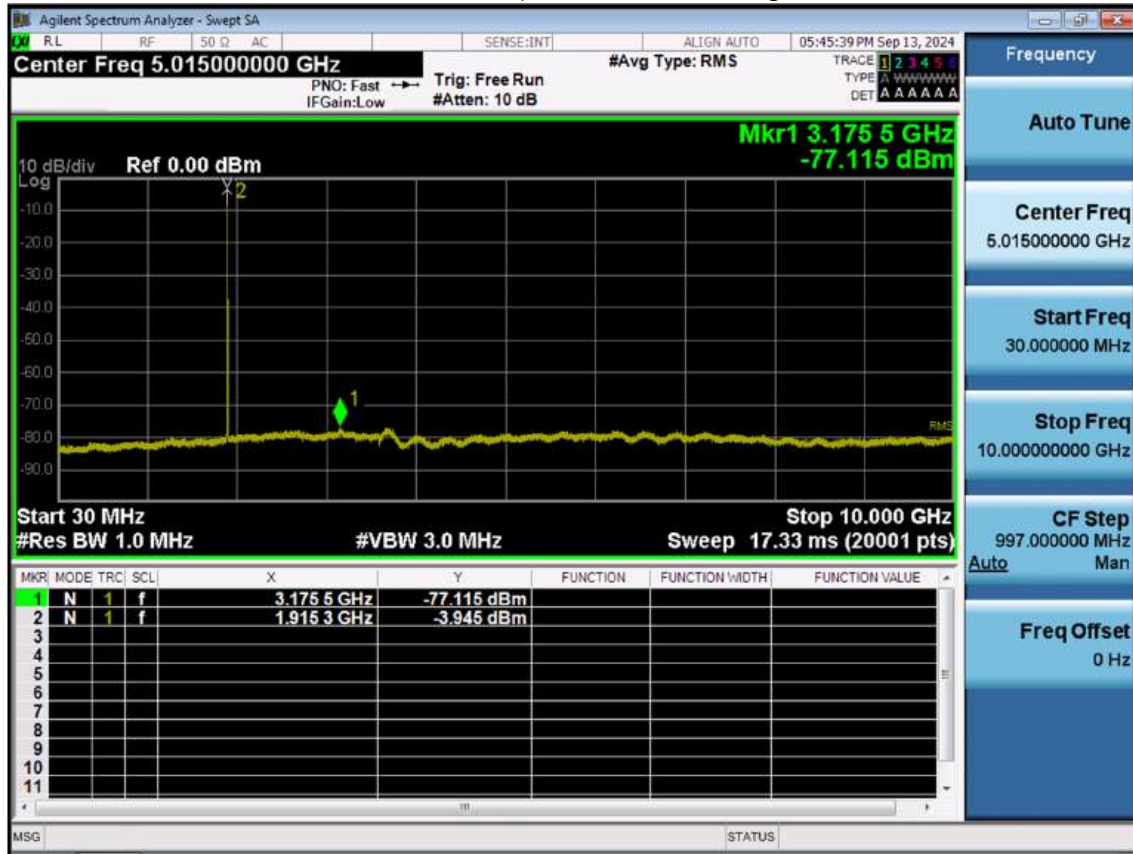
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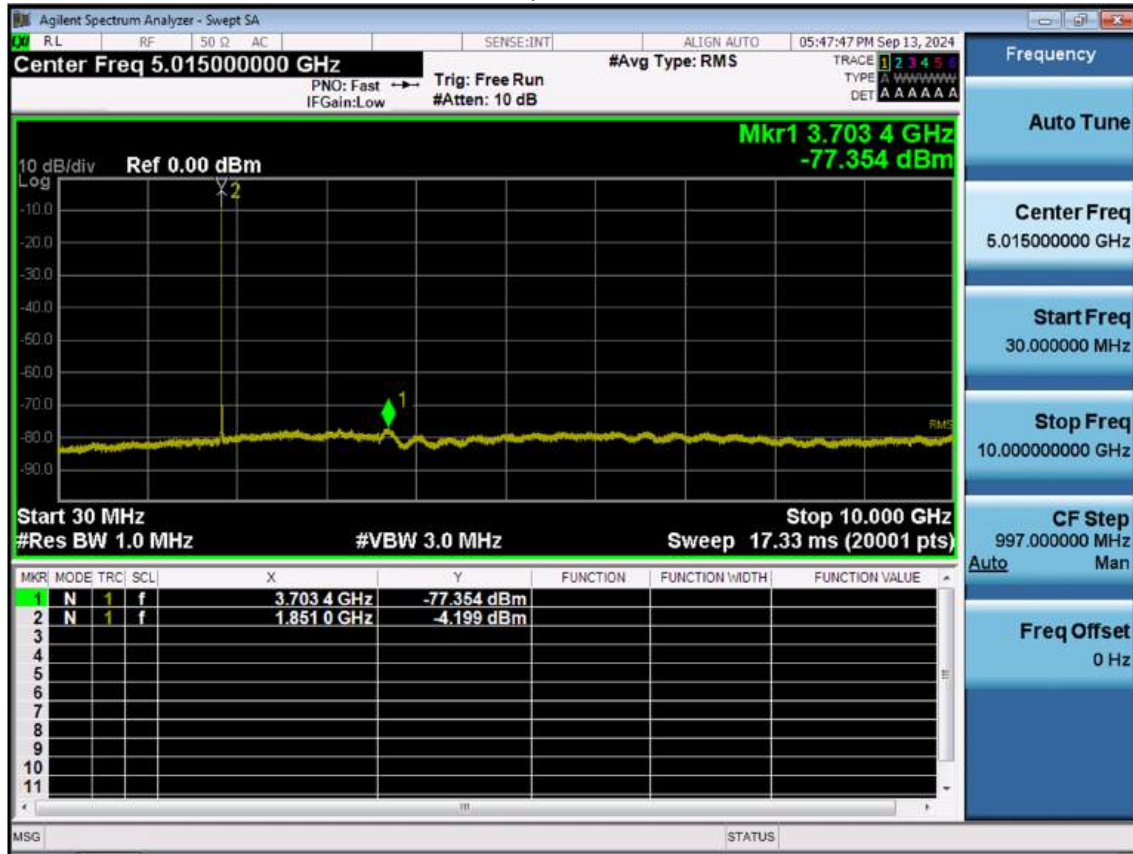
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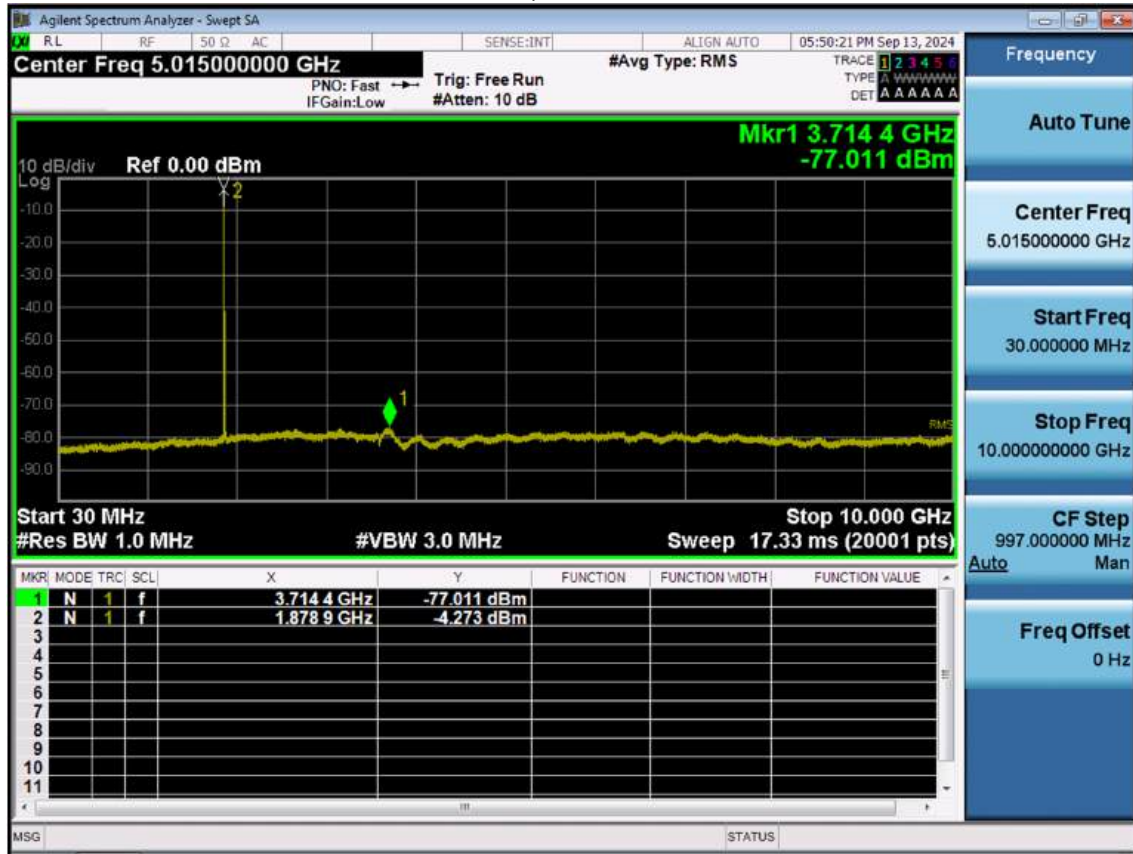
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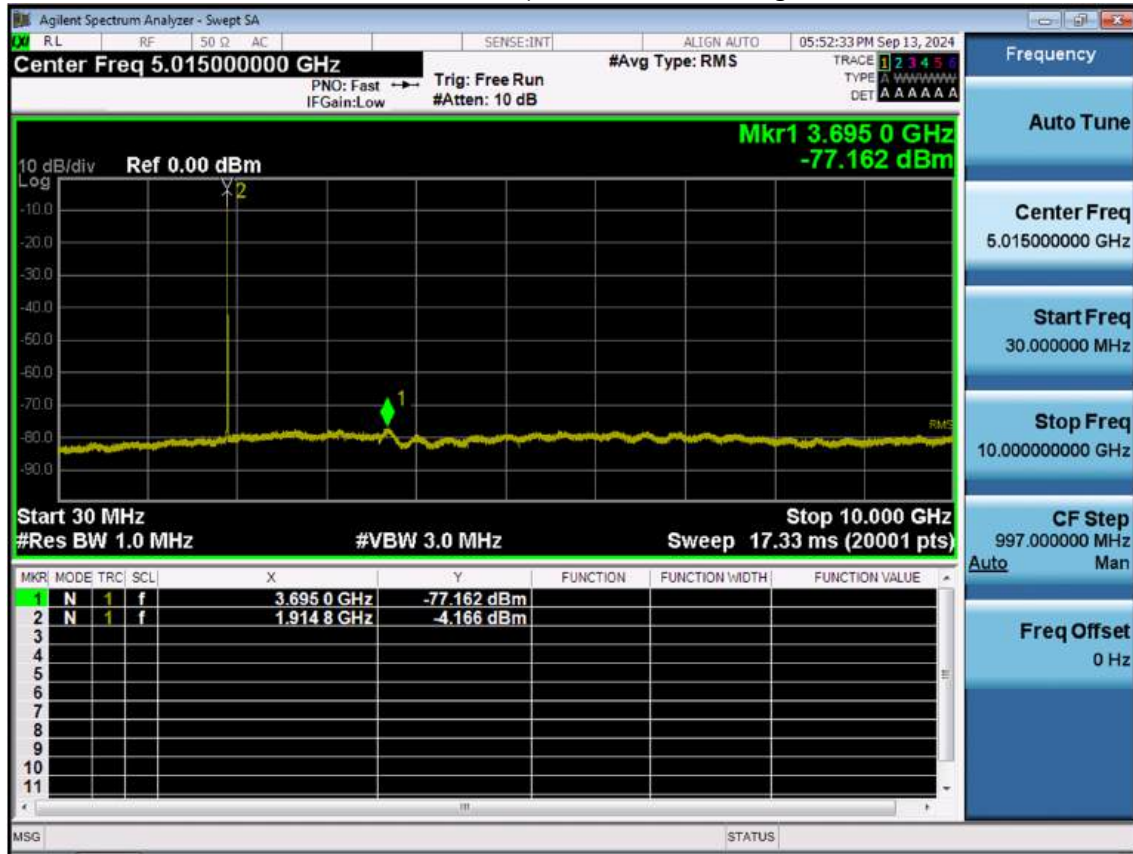
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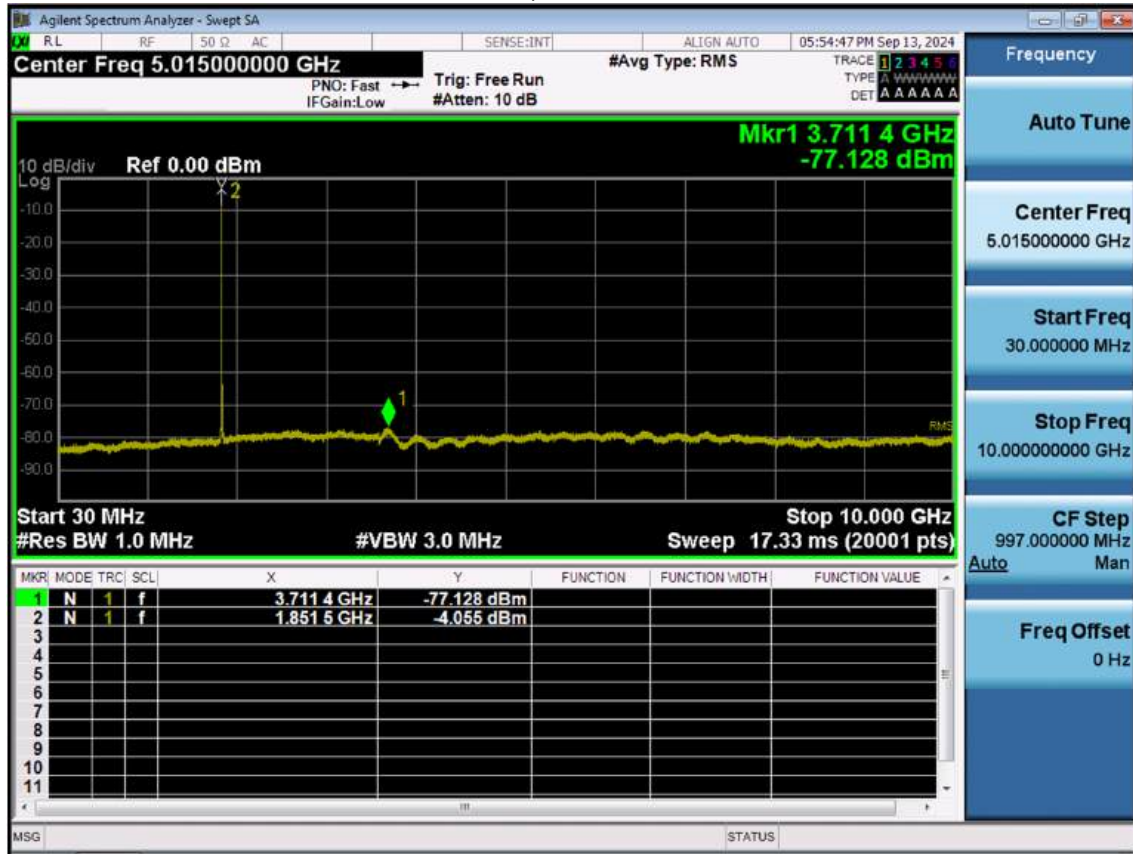
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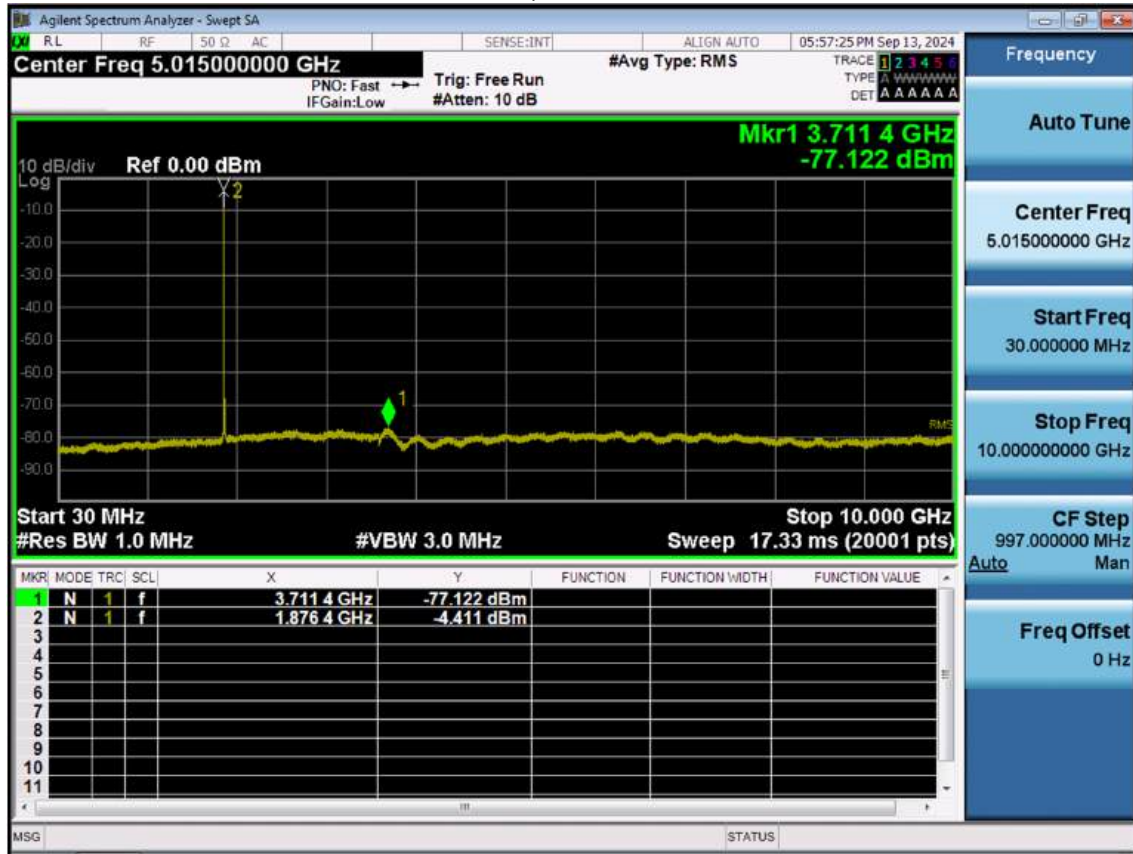
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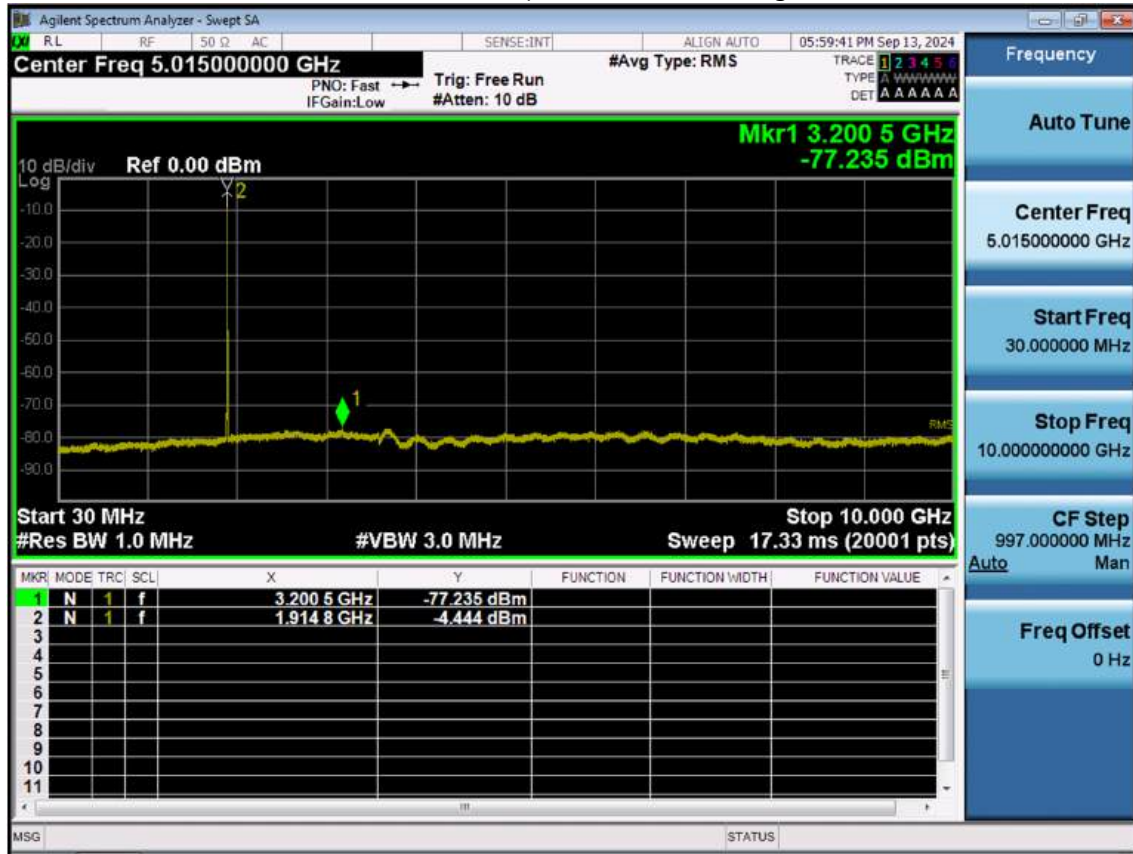
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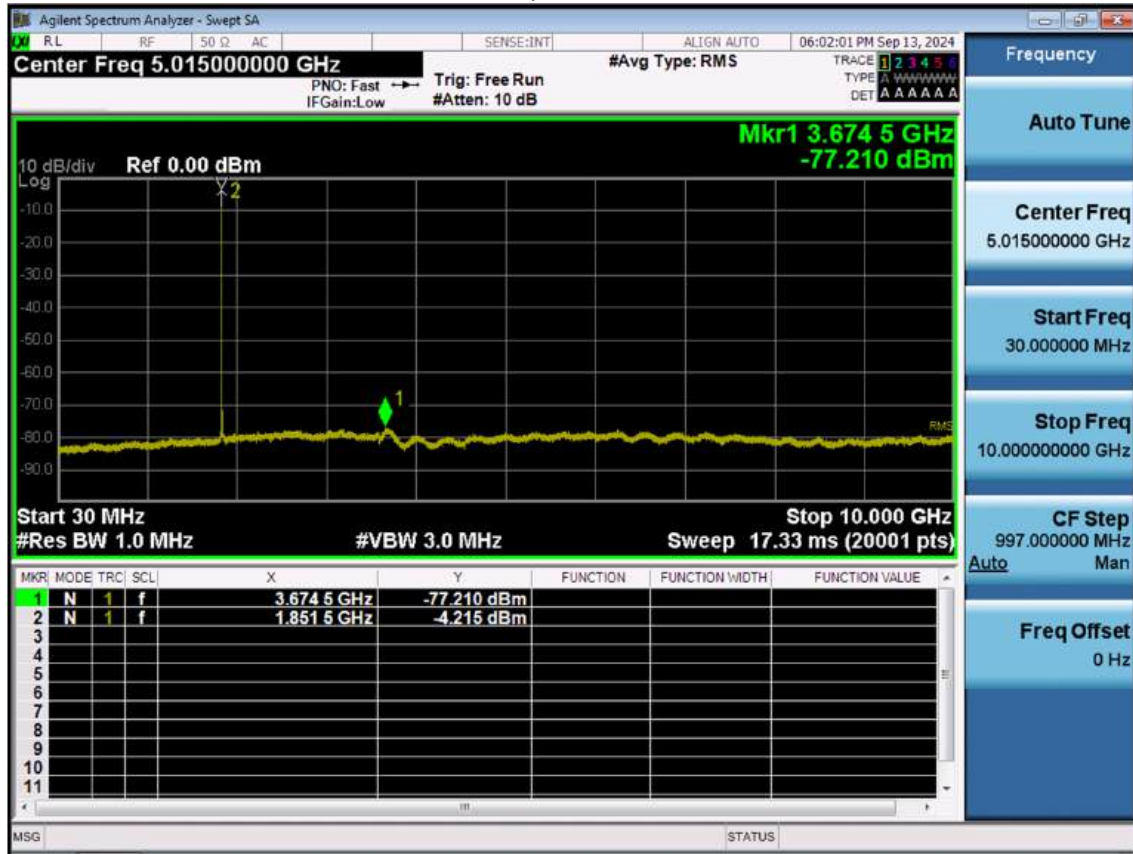
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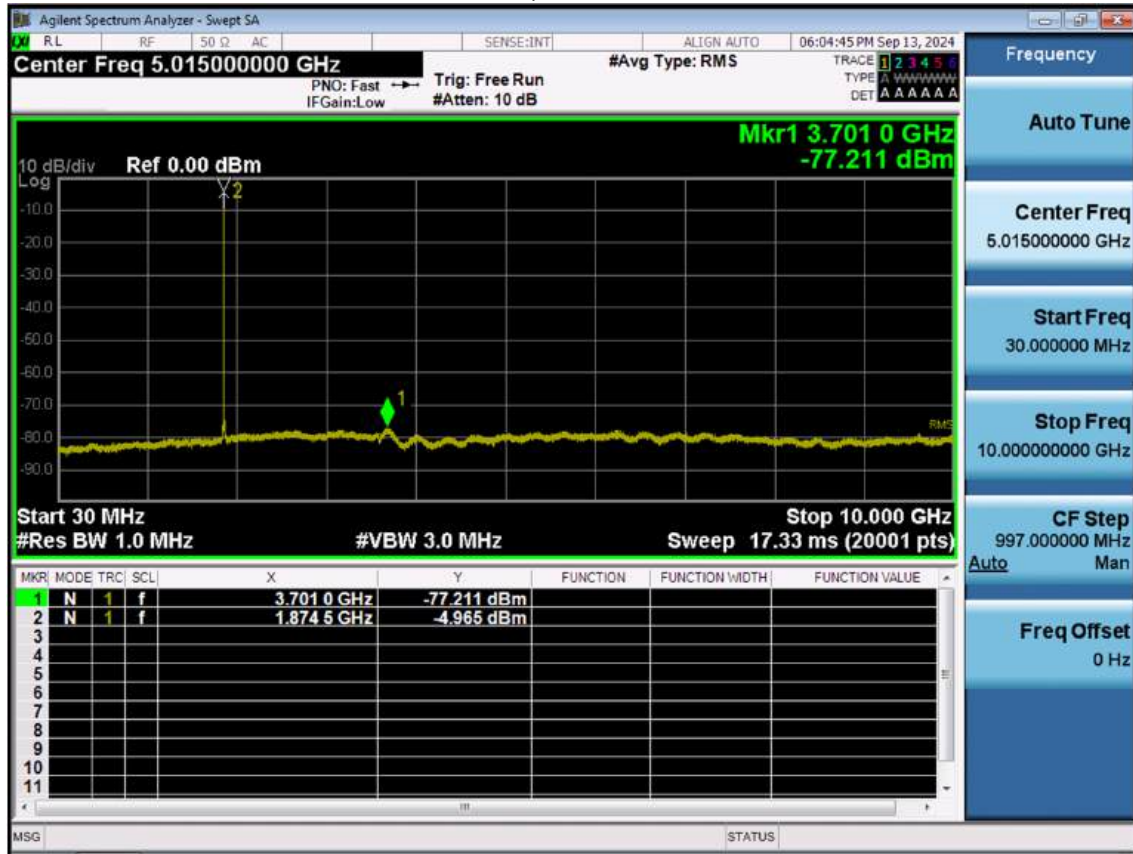
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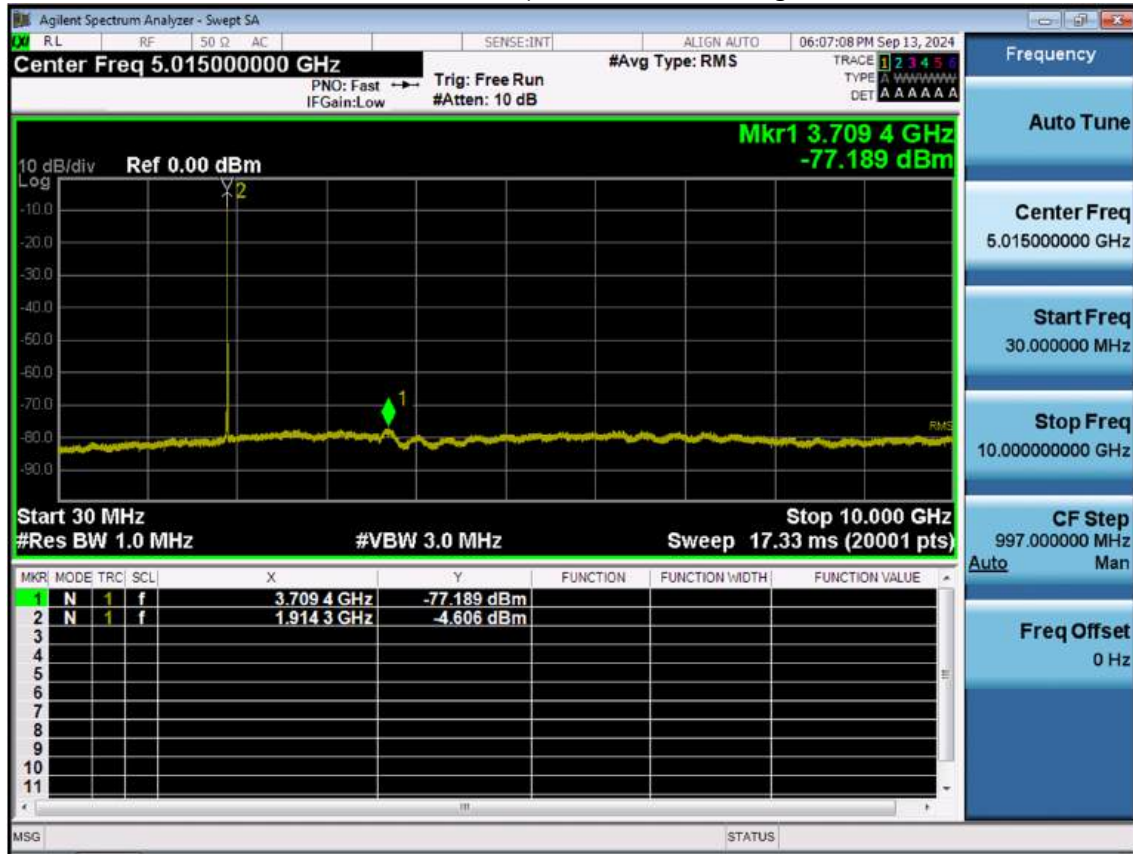
LTE B25_20 M_Conducted Spurious(30 M-10 G)_Low_QPSK_1RB



LTE B25_20 M_Conducted Spurious(30 M-10 G)_Mid_QPSK_1RB



LTE B25_20 M_Conducted Spurious(30 M-10 G)_High_QPSK_1RB



LTE B25_1.4M_Conducted Spurious(10 G-20 G)_Low_QPSK_1RB



LTE B25_1.4M_Conducted Spurious(10 G-20 G)_Mid_QPSK_1RB



LTE B25_1.4M_Conducted Spurious(10 G-20 G)_High_QPSK_1RB



LTE B25_3 M_Conducted Spurious(10 G-20 G)_Low_QPSK_1RB



LTE B25_3 M_Conducted Spurious(10 G-20 G)_Mid_QPSK_1RB



LTE B25_3 M_Conducted Spurious(10 G-20 G)_High_QPSK_1RB



LTE B25_5 M_Conducted Spurious(10 G-20 G)_Low_QPSK_1RB



LTE B25_5 M_Conducted Spurious(10 G-20 G)_Mid_QPSK_1RB



LTE B25_5 M_Conducted Spurious(10 G-20 G)_High_QPSK_1RB



LTE B25_10 M_Conducted Spurious(10 G-20 G)_Low_QPSK_1RB



LTE B25_10 M_Conducted Spurious(10 G-20 G)_Mid_QPSK_1RB



LTE B25_10 M_Conducted Spurious(10 G-20 G)_High_QPSK_1RB



LTE B25_15 M_Conducted Spurious(10 G-20 G)_Low_QPSK_1RB



LTE B25_15 M_Conducted Spurious(10 G-20 G)_Mid_QPSK_1RB



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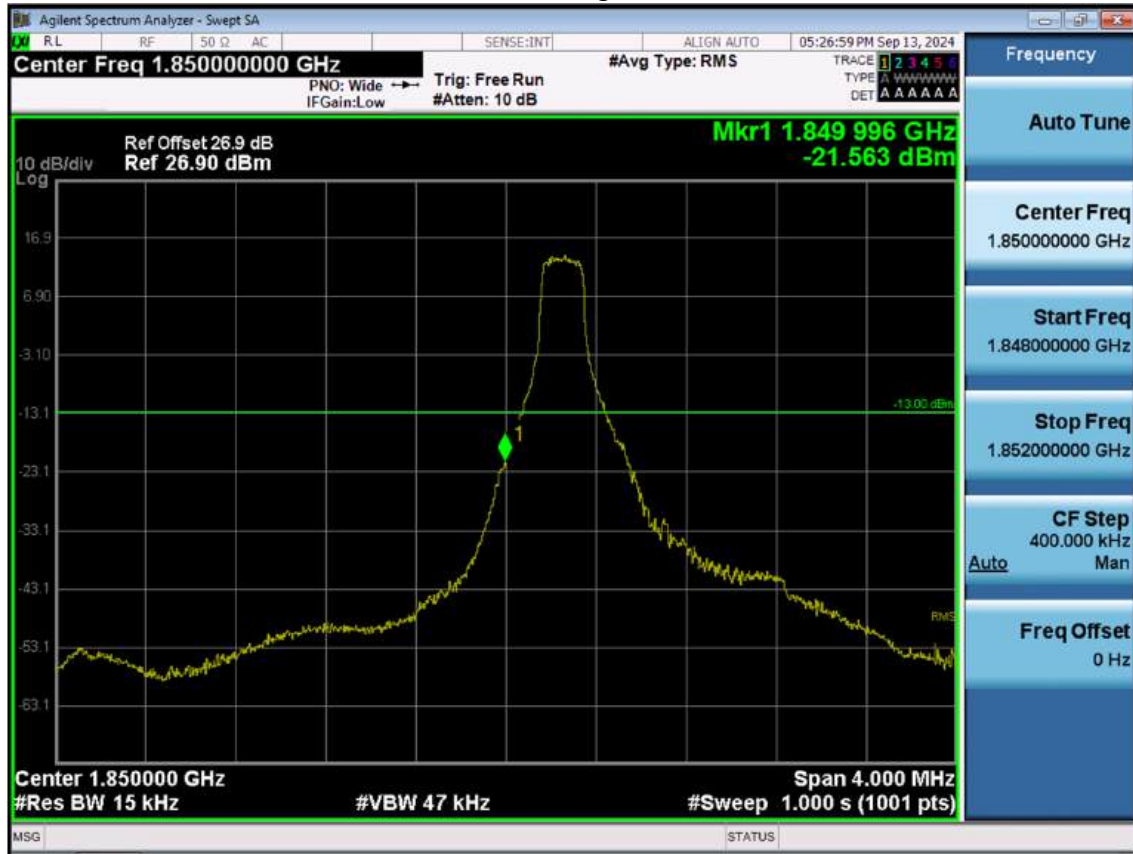
LTE B25_20 M_Conducted Spurious(10 G-20 G)_Mid_QPSK_1RB



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LTE B25_1.4M_Band Edge_Low_QPSK_1RB



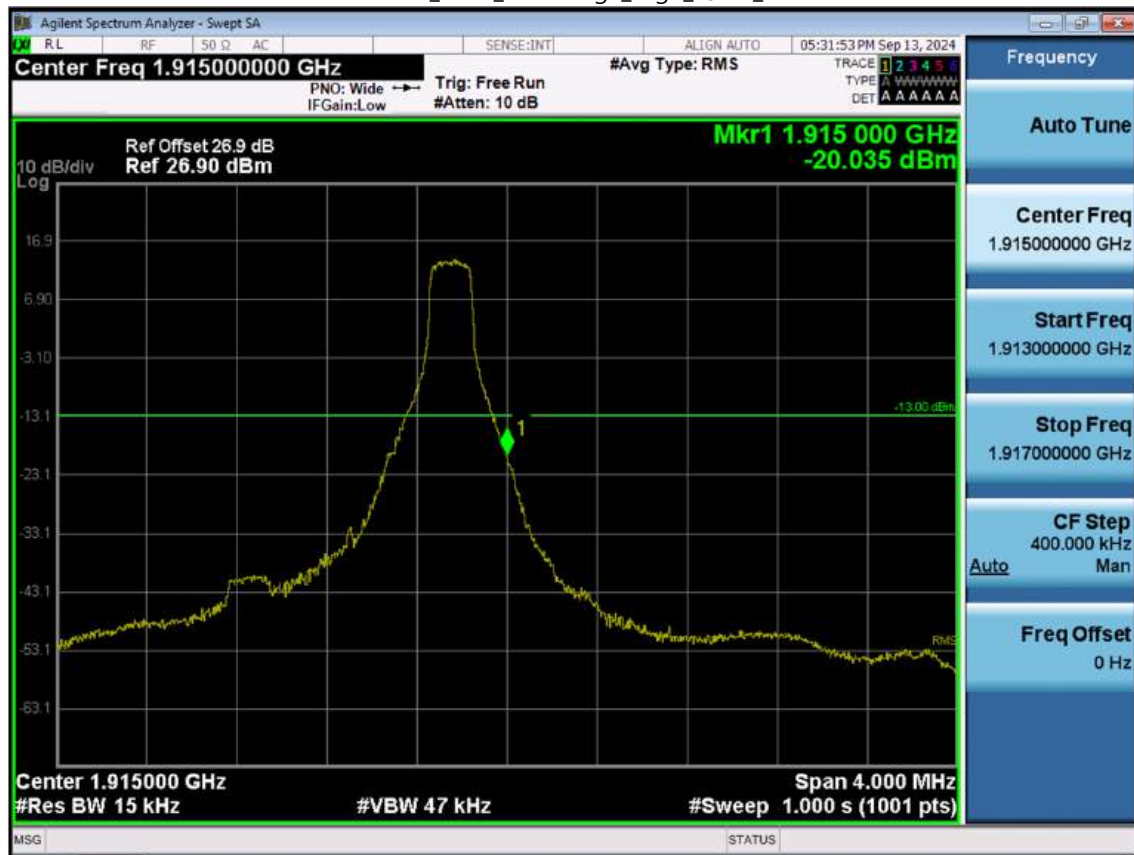
LTE B25_1.4M_Band Edge_Low_QPSK_FullRB



LTE B25_1.4M_Extended Band Edge_Low_QPSK_FullRB



LTE B25_1.4M_Band Edge_High_QPSK_1RB



LTE B25_1.4M_Band Edge_High_QPSK_FullRB



LTE B25_1.4M_Extended Band Edge_High_QPSK_FullRB



LTE B25_3 M_Band Edge_Low_QPSK_1RB



LTE B25_3 M_Band Edge_Low_QPSK_FullRB



LTE B25_3 M_Extended Band Edge_Low_QPSK_FullRB



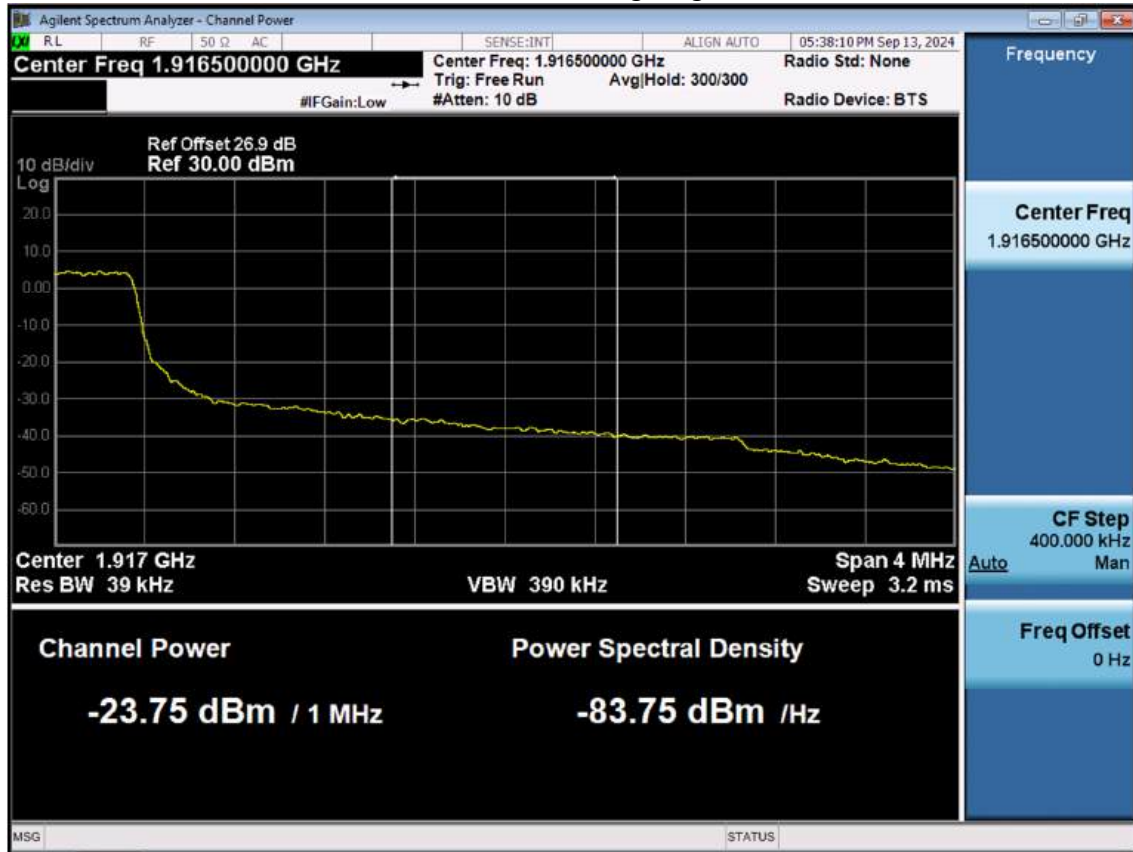
LTE B25_3 M_Band Edge_High_QPSK_1RB



LTE B25_3 M_Band Edge_High_QPSK_FullRB



LTE B25_3 M_Extended Band Edge_High_QPSK_FullIRB



LTE B25_5 M_Band Edge_Low_QPSK_1RB



LTE B25_5 M_Band Edge_Low_QPSK_FullRB



LTE B25_5 M_Extended Band Edge_Low_QPSK_FullRB



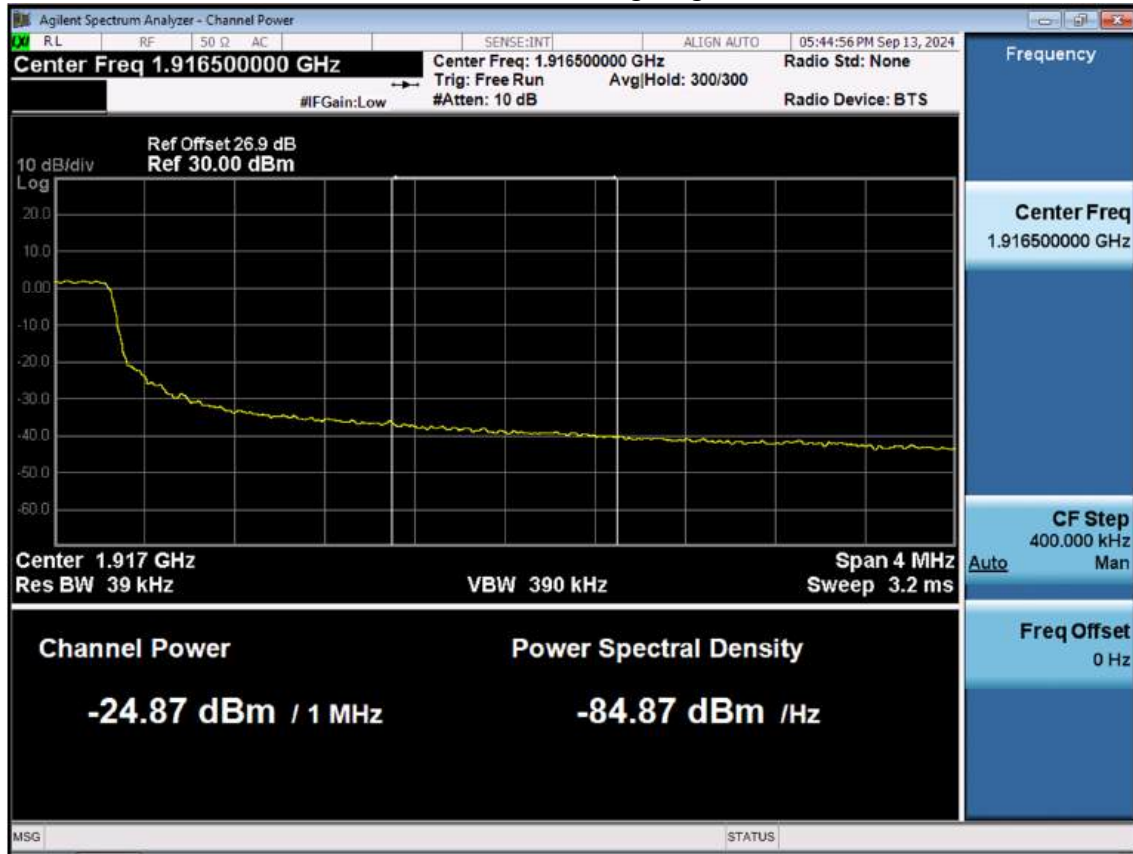
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LTE B25_5 M_Band Edge_High_QPSK_FullRB



LTE B25_5 M_Extended Band Edge_High_QPSK_FullIRB



LTE B25_10 M_Band Edge_Low_QPSK_1RB



LTE B25_10 M_Band Edge_Low_QPSK_FullRB



LTE B25_10 M_Extended Band Edge_Low_QPSK_FullRB

